
Name of Candidate: Mayuribala Mangrulkar

PhD Program: Materials Science and Engineering

Title of Thesis: Design and engineering of additives for improving the stability of hybrid perovskite solar cells

Supervisor: Professor Keith Stevenson

Name of the Reviewer: Ajay Kumar Jena

<table>
<thead>
<tr>
<th>I confirm the absence of any conflict of interest</th>
<th>Date: 20-09-2021</th>
</tr>
</thead>
<tbody>
<tr>
<td>(Alternatively, Reviewer can formulate a possible conflict)</td>
<td></td>
</tr>
</tbody>
</table>

The purpose of this report is to obtain an independent review from the members of PhD defense Jury before the thesis defense. The members of PhD defense Jury are asked to submit signed copy of the report at least 30 days prior the thesis defense. The Reviewers are asked to bring a copy of the completed report to the thesis defense and to discuss the contents of each report with each other before the thesis defense.

If the reviewers have any queries about the thesis which they wish to raise in advance, please contact the Chair of the Jury.

Reviewer's Report

Reviewers report should contain the following items:

- Brief evaluation of the thesis quality and overall structure of the dissertation.
- The relevance of the topic of dissertation work to its actual content
- The relevance of the methods used in the dissertation
- The scientific significance of the results obtained and their compliance with the international level and current state of the art
- The relevance of the obtained results to applications (if applicable)
- The quality of publications

The summary of issues to be addressed before/during the thesis defense
The work done by the student is satisfactory. The additive engineering approach has been a popular strategy to improve the performance and stability of PSCs. A variety of organic molecules and inorganic salts has been reported in the literature, which has been written well by classifying them into different families in the literature review section of the thesis. And, it is true that, although such a wide range of additives has been explored there is no general rule of selection. Every reported study, by large, tells the same story of improved film quality, defects-passivation, and improved PCE and stability. The present thesis aims to screen a few of these additives by photothermal stability tests, which are possibly not directly examined by others. However, to me, it looks like the thesis lacks some deeper insightful discussions related to the findings. I can understand that some points can be out of the scope of the work but a thorough interpretation of the obtained results, asking more interesting questions on the results can be a good exercise for the student. For example, as found by the student, PbI2-NMP complex helps in improving the stability/photostability of MAPI while excess PbI2 is detrimental for stability. This discussion just states this much I would expect a little deeper discussion by asking questions like why PbI2-NMP improves stability? Is this photoinsensitive, unlike PbI2?, Does the morphology, which is different for the cases, influence the stability? Is the excess PbI2 bad for stability in both dark and light? In light, it undergoes a photoreduction process (PbI2 to Pb), as found here also, which can shift the equilibrium between MAPI and PbI2+MAI in a way such that more of PbI2 is formed. On the other hand, in the dark, PbI2 nanocrystals that are already present in the film, and are in contact with MAPI crystals in atomic scale, may favor more of PbI2 formation, unlike the case where there is no PbI2. Such discussions can improve the content and would be good learning for the student. I have posted many such comments at the right places in the pdf file. I would recommend defending the thesis after the changes made according to these comments. In addition, in general, I feel

1. The title needs to be modified a little. It should be changed to a more appropriate one reflecting the main aim/objectives and findings of the work.

2. The writing needs to be improved in many places (some have been highlighted in the file, as examples). Grammatical errors and inappropriate Eng expressions should be corrected throughout the file.

**Provisional Recommendation**

☐ I recommend that the candidate should defend the thesis by means of a formal thesis defense

☑ I recommend that the candidate should defend the thesis by means of a formal thesis defense only after appropriate changes would be introduced in candidate’s thesis according to the recommendations of the present report

☐ The thesis is not acceptable and I recommend that the candidate be exempt from the formal thesis defense
DESIGN AND ENGINEERING OF ADDITIVES FOR IMPROVING THE STABILITY OF HYBRID PEROVSKITE SOLAR CELLS

Doctoral Thesis

BY

MAYURIBALA MANGRULKAR

DOCTORAL PROGRAM IN MATERIALS SCIENCE AND ENGINEERING

Supervisor

Prof. Keith J. Stevenson

Moscow – 2021

© Mayuribala Mangrulkar 2021
I hereby declare that the work presented in this thesis was carried out by myself at Skolkovo Institute of Science and Technology, Moscow, except where due acknowledgement is made and has not been submitted for any other degree.

Candidate- Mayuribala Mangrulkar

Supervisor – Prof. Keith J. Stevenson
Abstract

Complex lead halide based perovskite solar cells have caught the attention of the scientific community all across the globe. This is because research associated with perovskite solar cell showed a dramatic improvement in efficiency compared to conventional solar cells built with silicon. Additionally, benefits such as solution processing and ease of manufacturing make it a potential candidate to replace conventional photovoltaics materials. However, poor stability issues have been a significant drawback. Hence the objective of this work is to design and engineer additives for improving the stability of hybrid organic-inorganic perovskite solar cells based on methylammonium lead iodide based active layer. The poor stability of the perovskite layer often disintegrates perovskite into either PbI$_2$, metallic lead or some volatile species, creating defects at the surface, grain boundaries. Thus, this thesis is dedicated to investigating additives that can improve the intrinsic photostability of MAPbI$_3$. To achieve the aim, additives were first screened by a thin-film photostability test and then opted in complete solar cell devices to further investigate their operational stability under illumination. For this thesis, three of the best additives showing stabilization effect were studied in detail. Their mechanism of improving stability and influence on morphology, optoelectronics property were examined in conjunction with the operational stability of additive containing solar cells. The highest operational stability of solar cells achieved in this work was 4400 h due to HAI incorporation in MAPbI$_3$ film, followed by 1500 h due to NMP cosolvent present with excess PbI$_2$ in MAPbI$_3$. 
Thesis related publication


Author’s Contribution

**Publication 1.** “Influence of hydrazinium iodide on the intrinsic photostability of MAPbI$_3$ thin films and solar cells”. The author is mainly responsible for this work. The author prepared sampled, executed experiments (UV-Vis, XRD, FTIR, Device performance and device ageing tests). Further, the author finalized the results and wrote the manuscript.

**Publication 2.** “Influence of pyridine-based ligands on photostability of MAPbI$_3$ thin films”. The author is mainly responsible for this work. The author prepared sampled, executed experiments (UV-Vis, XRD, FTIR, Device performance-related measurements). Further, the author finalized the results and wrote the manuscript.

**Publication 3.** “Rationalizing the effect of overstoichiometric PbI$_2$ on the stability of perovskite solar cells in the context of precursor solution formulation”. The author is mainly responsible for this work. The author prepared sampled, executed experiments (UV-Vis, XRD, Device performance and device stability measurements). Further, the author finalized the results and wrote the manuscript.

**Publication 4.** “The progress of additive engineering for CH$_3$NH$_3$PbI$_3$ photo-active layer in the context of perovskite solar cells”. The author is mainly responsible for this work. The author performed and analysed the literature review. Further, the author wrote the manuscript.
Other Publications


Conferences


Acknowledgements

I am thankful to the Skolkovo Institute of Science and Technology for providing the research facilities required to conduct the experiments at the Centre of Energy Science and Technologies (CEST) and Advanced Imaging Core Facility (AICF), and our collaborators from the Institute for Problems of Chemical Physics of RAS (IPCP RAS), Chernogolovka, Moscow, Russia, Institute of Physics and Technology, Ural Federal University (UrFU), Yekaterinburg, Russia, M. N. Mikheev Institute of Metal Physics of Ural Branch of Russian Academy of Sciences (IMP UB RAS), Yekaterinburg, Russia.

I am blessed to have Prof. Keith J. Stevenson as my supervisor and would like to express special gratitude to Prof. Keith J. Stevenson for his supervision, support and guidance. Without Prof. Keith J. Stevenson’s support, this dissertation would not have been possible. Further, I would like to thank Prof. Pavel A. Troshin for his support for the work done during this PhD project. I am thankful to Prof. Andriy Zhugayevich and Prof. Alexei Buchachenko for being on the doctoral committee and evaluating my progress.

In addition, I would like to express my thanks to all the labmates and colleagues for their assistance. Regular discussions with them helped me to frame and execute my research plans. Further, I would like to extend my thankfulness to Dr Sergey Tsarev to train me to fabricate solar cells, Dr Azat. F. Akbulatov to teach me how to use additives.

I want to acknowledge and express my gratitude towards colleagues who performed some of the presented experiments in this thesis. AFM imaging and in-situ photodegradation measurements were carried out by Dr Sergey Yu Luchkin (CEST, Skoltech). EDX measurements were done by Dr Azat. F. Akbulatov (IPCP RAS). PL and Power dependent PL measurements were performed by Dr Alexandra G. Boldyreva (CEST, Skoltech). SEM and EDX measurements were carried by Dr Svetlana A. Lipovskikh (AICF, Skoltech).
XPS results were acquired by Prof. Ivan Zhidkov (UrFU) and Prof. Ernst Kurmaev (IMP UB RAS).

Finally, I would like to express my heartfelt appreciation to my friends and parents for their unwavering support throughout my life. Especially, my mother who supported me to pursue my dreams of higher education and always motivated me to step forward in the direction of achievement. Without her backing, I would not have been able to reach this milestone in my life.
# Table of Contents

Abstract ............................................................................................................................................... 3

Thesis related publication ................................................................................................................ 4

Author’s Contribution ......................................................................................................................... 5

Other Publications .............................................................................................................................. 6

Conferences ......................................................................................................................................... 7

Acknowledgements ............................................................................................................................. 8

Table of Contents ............................................................................................................................... 10

List of Symbols, Abbreviations ......................................................................................................... 15

List of Figures ....................................................................................................................................... 19

List of Tables ....................................................................................................................................... 22

1. Introduction & Background ........................................................................................................... 24

  1.1 Why “solar”?............................................................................................................................... 24

  1.2 Origin and history of solar cells ................................................................................................. 25

  1.3 “Perovskite” solar cells ............................................................................................................. 26

  1.4 Advantages of Perovskite solar cells ........................................................................................ 28
1.4.1 Excellent optical and electronic properties ........................................... 28

1.4.2 High open-circuit voltage ($V_{oc}$) and power conversion efficiency (PCE) ..... 29

1.4.3 Easy and low cost of manufacturing ....................................................... 29

1.5 Challenges: stability issues of complex lead halides ................................. 30

1.5.1 Extrinsic stability issues ........................................................................ 31

1.5.2 Intrinsic stability issue .......................................................................... 32

1.6 Aim .......................................................................................................... 33

2. Literature Review ....................................................................................... 34

2.1 Organic additives ..................................................................................... 34

2.1.1 N donor atom-based additives ............................................................. 34

2.1.2 O donor atom-based additives ............................................................. 47

2.1.3 S donor atom-based additives ............................................................. 70

2.1.4 Alkane additives .................................................................................. 75

2.1.5 Quantum dot-based additives .............................................................. 77

2.2 Inorganic additives .................................................................................. 80
2.2.1 Alkali metals additives................................................................. 80

2.2.2 Transition metals additives ......................................................... 83

2.2.3 Other metals additives............................................................... 85

2.2.4 Non-metal inorganic salts .......................................................... 87

2.3 Summary of literature review: ......................................................... 89

3. Experimental section....................................................................... 90

3.1 Methodology .................................................................................. 90

3.2 Materials ......................................................................................... 91

3.2.1 Preparation of Precursor Solutions: ............................................. 95

3.2.2 Thin Film Preparation: ............................................................... 95

3.2.3. Device Preparation: ................................................................. 96

3.3 Characterisation Techniques: ......................................................... 97

3.3.1 UV-visible spectroscopy ............................................................. 97

3.3.2 XRD measurements ................................................................. 97

3.3.3 FTIR spectroscopy ................................................................. 97
3.3.4 Photoluminescence ................................................................. 97
3.3.5 Atomic Force Microscopy ......................................................... 98
3.3.6 Scanning Electron Microscopy & Energy Dispersive Xray. .............. 98
3.3.7 X-ray photoelectron spectroscopy ............................................. 98
3.3.8 J-V characterisation ................................................................... 99

4. Results and Discussion ................................................................. 100
4.1 Impact of solution formulation on the excess of PbI₂ additive in MAPbI₃ thin films and solar cells .................................................................................................................. 100
  4.1.1 Photostability of thin-films ......................................................... 101
  4.1.2 Proposed mechanism of improved stability with MAPbI₃+PbI₂·NMP .... 104
  4.1.3 Device performance and Device stability ...................................... 106
4.2 Enhanced intrinsic photostability of MAPbI₃ thin films and solar cells with hydrazinium iodide ......................................................................................................................... 108
  4.2.1 Photostability of thin-films with HAI additive .............................. 108
  4.2.2 Proposed mechanism of improved stability with HAI salt .......... 110
4.2.3 Device performance and Device stability ........................................... 114

4.3 Photostability of MAPbI₃ thin films with pyridine-based ligands ................. 117

4.3.1 Photostability of thin-films with pyridine-based ligands ....................... 117

4.3.2 Proposed mechanism of improved stability of MAPbI₃ film with \( \Upsilon \)-bipyridyl (N2) ................................................................................................. 122

4.3.3 Device performance with additive \( \Upsilon \)-bipyridyl (N2) ......................... 125

5. Conclusions and Prospects ........................................................................ 128

6. BIBLIOGRAPHY .......................................................................................... 131

Appendix 0: Literature Review Analysis ......................................................... 155

Appendix 1: UV-Vis Evolution of Investigated Additives ............................... 160

Appendix 2: Supplementary Material ............................................................. 163
List of Symbols, Abbreviations

Ag – Silver

Al – Aluminium

AM 1.5G – Air Mass 1.5 Global

a-Si – Amorphous Silicon

BHJ – Bulk Heterojunction

CdTe – Cadmium Telluride

CIGS - Copper Indium Gallium Selenide

CSSCs – Crystalline Silicon Solar Cells

c-Si – Crystalline Silicon

DMF – Dimethylformamide

DMSO – Dimethylsulfoxide

DSSCs – Dye-Sensitized Solar Cells

EDX – Energy-Dispersive X-ray

EQE – External Quantum Efficiency

ETL – Electron Transport Layer

ETM – Electron Transport Material

FA – Formamidinium
FAI – Formamidinium Iodide

FF – Fill Factor (%)

FWHM – Full Width at Half Maximum

GaAs – Gallium Arsenide

HOMO – Highest Occupied Molecular Orbital

HTL – Hole Transport Layer

HTM – Hole Transport Material

ITO – Indium Tin Oxide

$J_{SC}$ – Short Circuit Current Density

LBIC – Light beam induced current

LiTFSI - Lithium bis(trifluoromethylsulfonyl)imide

MA – Methylammonium

MAI – Methylammonium Iodide

MAPbI$_3$ - Methylammonium Lead Iodide

MoO$_x$ – Molybdenum oxide

$N_2$ - Nitrogen

NiO$_x$ – Nickel Oxide

NMP- N-Methyl-2-pyrrolidone
NREL – National Renewable Energy Laboratory

PbI₂ – Lead Iodide

PCBA - Phenyl-C61-butyric acid

PC₆₁BM - Phenyl-C61-butyric acid methyl ester

PC₇₁BM - Phenyl-C71-butyric acid methyl ester

PCE – Power Conversion Efficiency

PEDOT:PSS – Poly(3,4-ethylenedioxythiophene) polystyrene sulfonate

PL – Photoluminescence

PSCs – Perovskite Solar Cells

p-Si - Polycrystalline Silicon

PTAA – Poly[bis(4-phenyl)(2,4,6-trimethylphenyl)amine]

PTA - Poly[bis(4-phenyl)(4-trimethylphenyl)amine]

PV – Photovoltaic

OPVs – Organic Photovoltaics

QDs – Quantum Dots

SEM – Scanning Electron Microscopy

Spiro-OMeTAD – 2,2',7,7'-Tetrakis[N,N-di(4-methoxyphenyl)amino]-9,9'

Spirobifluorene
TF - Tolerance Factor

ToF-SIMS - Time of Flight Secondary Ion Mass Spectrometry

V₂O₅ - Vanadium Oxide

VOC – Open Circuit Voltage

XPS – X-ray Photoelectron Spectroscopy

XRD – X-ray Diffraction
List of Figures

Figure 1 Expected energy consumption 1 ................................................................. 24

Figure 2: (a) global energy potential (b) availability of energy resources. 2 ................. 25

Figure 3: Evolution of photovoltaic technology. 6 ...................................................... 26

Figure 4 (a) crystal structure of perovskite materials, (b) suitable A cations for perovskite solar cells. 8 ................................................................. 27

Figure 5 Comparison of photoelectrical properties of PSC with different PV technology 12,13 ........................................................................................................ 28

Figure 6 (a) Dependence of PCE on IV parameters 14. (b) Open-circuit voltage (Voc) versus optical band gap (Eg) of different PV technology 15. (c) PCE evolution of PSCs 16 ....... 29

Figure 7 Comparison of material production capacity of various PV technologies 18 .... 30

Figure 8: Methodology of the experiment. (a) solution preparation (b) Spin coating process for device optimization (c) conditions for stability tests (d) completed device upon stability tests. ........................................................................................................ 90

Figure 9 Investigated additives and their chemical structures ......................................... 92

Figure 10 Absorbance spectra of fresh and photoaged MAPbI₃ films with 0% and 15% excess PbI₂ (a) from pure DMF (b) from DMF/NMP cosolvents. 168 ......................... 102

Figure 11 XRD pattern of fresh and photoaged MAPbI₃ films with 0% and 15% PbI₂ (a) from pure DMF (b) from DMF/NMP mixture. 168 ......................................................... 103
Figure 12 AFM images of MAPbI$_3$ thin films acquired as a result of in situ photo-degradation. (laser beam of 405 nm wavelength, with the light intensity of 10 kW m$^{-2}$ was used). (a) fresh, 0% excess PbI$_2$, from pure DMF. (b) fresh, 10% excess PbI$_2$ from pure DMF. (c) fresh, 0% excess PbI$_2$ from DMF/NMP mixture. (d) fresh, 10% excess PbI$_2$ from DMF/NMP mixture. (e) aged, 0% excess PbI$_2$, from pure DMF. (f) aged, 10% excess PbI$_2$ from pure DMF. (g) aged, 0% excess PbI$_2$ from DMF/NMP mixture. (h) fresh, 10% excess PbI$_2$ from DMF/NMP mixture.\textsuperscript{168}.................................................................................................................. 105

Figure 13 Device stability of solar cells made of MAPbI$_3$ with 0%, and 15% excess PbI$_2$, coated from pure DMF and DMF/NMP mixture.\textsuperscript{168} ........................................................................................................ 107

Figure 14 Evolution of the UV-Vis spectra of MAPbI$_3$ films (a) reference film with 0% HAI, (b) MAPbI$_3$+HAI film ........................................................................................................... 109

Figure 15 XRD patterns of fresh and aged MAPbI$_3$ and MAPbI$_3$+HAI films. * represents perovskite peaks.................................................................................................................. 110

Figure 16 SEM images of (a) pristine MAPbI$_3$ film (b) MAPbI$_3$ + HAI film........... 112

Figure 17 FTIR spectra of pristine and MAPbI$_3$+HAI films before and after photoaging test.\textsuperscript{179} .......................................................................................................................... 113

Figure 18 Normalised IV parameters with HAI additive............................................. 116

Figure 19 (a) UV-vis results (b) PL emission peaks of pristine MAPbI$_3$ and MAPbI$_3$ with additives (N1-N6). ........................................................................................................... 118

Figure 20 Evolution of UV-vis and XRD patterns of MAPbI$_3$+N1 (a,b), MAPbI$_3$+N2 (c,d), MAPbI$_3$+N3 (e,f), MAPbI$_3$+N4 (g,h), MAPbI$_3$+N5 (i,j), MAPbI$_3$+N6 (k,l) and pristine MAPbI$_3$ (m,n) respectively. * presents perovskite, · presents PbI$_2$ and +presents Pb........ 121
Figure 21 AFM images (a) fresh pristine MAPbI$_3$ film. (b) fresh MAPbI$_3$+N$_2$. (c) photoaged pristine MAPbI$_3$ film (d) photoaged MAPbI$_3$+N$_2$.\textsuperscript{43} ................................................. 123

Figure 22 FTIR spectra fresh MAPbI$_3$ and MAPbI$_3$+ N$_2$ film.................................................... 124

Figure 23 (a) device architecture (b) Impact of the addition of N$_2$ onto photovoltaic parameters. ........................................................................................................................................................................... 126

Figure 24 J-V curves of pristine vs 2.5% (best PCE) of N$_2$ in MAPbI$_3$................................. 127
List of Tables

Table 1 Additives based on nitrogen donor atom containing amines or nitrile\textsuperscript{57} .................. 38

Table 2 A summary of additives containing Amides/carbonyls/sulphonyl functional group in MAPbI\textsubscript{3} active layer.\textsuperscript{57} ...................................................................................................................................................... 50

Table 3 A summary of acid additives for MAPbI\textsubscript{3} active layer.\textsuperscript{57} ........................................ 55

Table 4 Acetate based additives in MAPbI\textsubscript{3} active layer.\textsuperscript{57} ........................................ 59

Table 5 Ester and Ether based additives for MAPbI\textsubscript{3} and their role.\textsuperscript{57} .............................. 63

Table 6 Alcohol based additives and their role in MAPbI\textsubscript{3} perovskite framework.\textsuperscript{57} ...... 66

Table 7 Other oxygen atom-based additives with multifunctional group.\textsuperscript{57} ............................ 69

Table 8 S atom based additive in MAPbI\textsubscript{3}.\textsuperscript{57} .................................................................................................................. 73

Table 9 Alkane based additives and their role within MAPbI\textsubscript{3} framework.\textsuperscript{57} .................. 76

Table 10 Quantum dots based additives for MAPbI\textsubscript{3}.\textsuperscript{57} ....................................................... 78

Table 11 Alkali metal additives and their role in MAPbI\textsubscript{3} perovskite.\textsuperscript{57} ................................. 82

Table 12 Transition metal additives and their role in MAPbI\textsubscript{3} perovskite.\textsuperscript{57} ....................... 84

Table 13 Other metal additive for MAPbI\textsubscript{3}.\textsuperscript{57} ........................................................................................................ 86

Table 14 Non-metal additives and their role in MAPbI\textsubscript{3} active layer.\textsuperscript{57} ................................. 88

Table 15 Investigated additives with their respective functional group ............................................. 93

Table 16 HAI concentration vs IV parameters.\textsuperscript{179} ......................................................................... 114
Table 17 Comparision of UV-vis, PL and XRD observations for the fresh MAPbI$_3$ +additive (N1-N6) films$^{43}$ ........................................................................................................... 119
1. Introduction & Background

1.1 Why “solar”? 

The traditional source of energy includes oil, coal and gas. However, these conventional energy resources are limited on earth. Due to the limitation of availability, we cannot rely on conventional energy resources for satisfying the increased demand for consumption. A study done by the US energy department has predicted that by 2050 the demand in energy requirement will sour to double compared to what was observed in the last decade (Figure 1)\(^1\). The approximate consumption of energy for the entire world population is around 16 TW per year\(^2\). Clearly, with this speed, the human race will soon run out of conventional energy sources like fossil fuel.

On the contrary, solar energy is abundantly available in nature, so solar energy is considered an alternative renewable energy resource\(^3\). To add on, greenhouse gas emissions can also be minimized by utilizing solar energy, resulting in lower pollution. Thus, solar energy provides clean and green energy. If the low cost of manufacturing is achieved, then solar energy can replace conventional energy resources\(^4\).

![Figure 1 Expected energy consumption](image)
1.2 Origin and history of solar cells

Solar cells convert sunlight into electrical energy. Thus solar cells are a great tool to utilize solar energy. The milestones in the development of photovoltaic technology are dated back to the 18th century. The very first photovoltaic effect was demonstrated by Edmond Becquerel in 1839. Later in 1883, the first solar cell using Selenium wafer was demonstrated by Charles Fritts. Although the efficiency of that solar cell was very low, around ~1%, the solar cell concept was demonstrated well. However, commercial solar cells were first developed by Bell labs in 1954. They used Silicon to produce solar cells, which gave efficiency around 4-5%\textsuperscript{5}. Unfortunately, those solar cells were not a very successful commercial product due to the high cost. Besides, their application became limited to powering satellites and some other space applications. Since then, researchers have been attempting to develop a low-cost solution for PV technology. These resulted in three generations of solar cells (Figure 3)\textsuperscript{6}. The first-generation solar cells mainly comprised of Silicon wafers. The development of Silicon-based solar cells led to very high efficiency, but a significant disadvantage was the very high cost, as discussed. The second-
generation solar cell offered low cost but with compromise in the efficiency. Hence the third generation was developed with the aim that it can be cost-effective as well as efficient, which is still in the research and development phase. The hybrid organic/inorganic perovskite solar cells are an advanced concept in the third generation, followed by DSSC and organic solar cells.

![Figure 3: Evolution of photovoltaic technology.](image)

1.3 “Perovskite” solar cells

“Perovskite” is the name of the mineral CaTiO₃ discovered in the Ural Mountains of Russia and named after Russian mineralogist Lev Perovski. Nevertheless, this term is being used for all compounds with the general formula ABX₃ with the same crystal structure as CaTiO₃ or derived from this structure. Perovskite materials consist of two cations. The cation A is 12 fold coordinated by the anions X and the cation B 6-fold where X can either be oxygen or a halide. In terms of perovskite solar cells, A site can be MA⁺/[CH₃NH₃]⁺, FA⁺/[H₂NCHNH₂]⁺, Rb⁺, Cs⁺, B site can be Pb²⁺, Sn²⁺, Ge²⁺ and X site can be halogens I⁻.
, Cl\(^-\), Br\(^-\). These choices are of the cation and anion relies on Goldschmidt tolerance factor \(t\), which predicts a stable crystal structure of perovskite. According to the Goldschmidt tolerance factor, the relationship between the ionic radius of the \(A\)-site cation \(r_A\), \(B\)-site cation \(r_B\) and \(X\)-site anion \(r_X\) is given as shown in equation 1

\[
t = \frac{r_A + r_B}{\sqrt{2(r_A + r_B)}}
\]  

(1)

Figure 4 (a) crystal structure of perovskite materials, (b) suitable \(A\) cations for perovskite solar cells.\(^8\)

For many different inorganic or hybrid perovskite light-absorbing layers suitable for photovoltaic application, the tolerance factor lies between 0.8 to 1. Specifically, for methylammonium lead iodide (MAPbI\(_3\)), the tolerance factor is \(~0.95\). This is why MAPbI\(_3\) is the most prominently studied hybrid organic-inorganic perovskite among perovskite solar cells\(^5,9\) and also the main perovskite material to work on for this thesis.
1.4 Advantages of Perovskite solar cells

1.4.1 Excellent optical and electronic properties

The light-absorbing perovskite materials offer many significant advantages. One of them is excellent optoelectronic properties that make them suitable for photovoltaic application. Perovskites are direct bandgap semiconductors that are ambipolar in nature. Perovskite light absorber materials have suitable bandgap (~1.5 eV), decent charge carrier mobilities of 2-66 cm² V⁻¹ s⁻¹, long diffusion lengths of charge carriers >1 um, and low exciton binding energy: 2–50 meV, which helps to achieve better charge transport properties compared to their competitive technologies. Also, perovskite light absorber material can be used in the low light region due to its high absorption coefficients. Further, low trap states and non-radiative recombination and high quantum yield make it an exciting candidate for PV technologies¹⁰,¹¹. A comparison of the photoelectrical properties of perovskite material with other PV technology is shown in Figure 5.

<table>
<thead>
<tr>
<th>Photovoltaic technology</th>
<th>PCE, %</th>
<th>Absorbance coefficient (cm⁻¹)</th>
<th>Diffusion lengths (μm)</th>
<th>Carrier mobility (cm² Vs⁻¹)</th>
<th>Carrier life time</th>
<th>Band gap (eV)</th>
<th>External radiative efficiency,%</th>
</tr>
</thead>
<tbody>
<tr>
<td>C-Si</td>
<td>27.6</td>
<td>10²</td>
<td>100-300</td>
<td>10⁻¹³ - 10¹⁰</td>
<td>4 ms</td>
<td>1.1</td>
<td>1.3</td>
</tr>
<tr>
<td>GaAs (thin film)</td>
<td>29.1</td>
<td>10⁴</td>
<td>1-5</td>
<td>&gt; 10³</td>
<td>50 ns</td>
<td>1.4</td>
<td>25</td>
</tr>
<tr>
<td>CIGS</td>
<td>23.4</td>
<td>10³ - 10⁴</td>
<td>0.3-0.9</td>
<td>10⁻¹⁰ - 10⁻¹</td>
<td>250 ns</td>
<td>1.1</td>
<td>10⁻¹</td>
</tr>
<tr>
<td>CdTe</td>
<td>22.1</td>
<td>10¹</td>
<td>0.4-1.6</td>
<td>10</td>
<td>20 ns</td>
<td>1.5</td>
<td>10⁻³</td>
</tr>
<tr>
<td>Dye sensitised (DSSC)</td>
<td>13.0</td>
<td>10³ - 10⁴</td>
<td>0.005-0.2</td>
<td>10⁻² - 10⁻¹</td>
<td>1 ns</td>
<td>1.6</td>
<td>10⁻⁴</td>
</tr>
<tr>
<td>Organic (OPV)</td>
<td>18.2</td>
<td>10³ - 10⁵</td>
<td>0.005-0.01</td>
<td>10⁻⁵ – 10⁻⁴</td>
<td>10-100 μs</td>
<td>1.6</td>
<td>10⁻⁷</td>
</tr>
<tr>
<td>Quantum dot</td>
<td>18.1</td>
<td>10² - 10³</td>
<td>0.08-0.2</td>
<td>10⁻⁴ – 10⁻²</td>
<td>30 μs</td>
<td>1.3</td>
<td>10⁻⁴</td>
</tr>
<tr>
<td>Perovskite</td>
<td>25.2</td>
<td>10³ - 10⁵</td>
<td>0.1-1.9</td>
<td>2·66</td>
<td>270 ns</td>
<td>~1.5</td>
<td>10⁻²</td>
</tr>
</tbody>
</table>

Figure 5 Comparison of photoelectrical properties of PSC with different PV technology¹²,¹³.
1.4.2. High open-circuit voltage ($V_{oc}$) and power conversion efficiency (PCE)

Another vital advantage of the perovskite absorber layer is a high open-circuit voltage produced under the full solar spectrum. Open circuit voltage represents the maximum possible voltage across a solar cell under the sunlight when no current is flowing. As depicted in figure 6a, higher $V_{oc}$ results in higher power conversion efficiencies $^{14}$. In practical terms, this $V_{oc}$ depends on effective bandgap potential ($E_g/q - V_{oc}$). Due to lower recombination rates of charge carriers in perovskite, effective bandgap potential is very low, as shown in Figure 6b. Thus, perovskite materials have a low loss of potential that further helps attain higher PCE values $^{9,15}$. As a result, perovskite solar cells have reached a very high efficiency beyond 25.2 %, comparable to commercially available Si PV technology (Figure 6c) $^{16}$.

![Figure 6](image.png)

Figure 6 (a) Dependence of PCE on IV parameters $^{14}$. (b) Open-circuit voltage (Voc) versus optical band gap ($E_g$) of different PV technology $^{15}$. (c) PCE evolution of PSCs $^{16}$.

1.4.3. Easy and low cost of manufacturing

The main advantage above all the advantages is the ease and low cost of manufacturing perovskite solar cells. Perovskite solar cells can be easily fabricated using solution processing techniques such as spin coating, drop-casting, slot die coating, doctor blading etc $^5$. On the other hand, commercial Si PV is expensive because of the high cost of manufacturing. The manufacturing of Silicon-based solar cells requires purifying raw silicon feedstock at very high temperature (~2000 °C ) and prepare ingots, which are later
sliced into wafers. Those wafers are then processed to form panels. All this process is energy-intensive. Further, installing those panels adds up the extra cost too. Thus, overall, in terms of payback, the energy and money spent to use solar panels are higher compared to traditional fossil fuel resources \(^{17}\). Because of this energy-intensive purifying and extraction process of Si technology, the quantity of Silicon required to produce one year of production is almost double that of perovskite light absorber materials (Figure 7) \(^{18}\). Thus, combining all these features makes perovskite-based solar cells a potential candidate to replace currently used Si PV technology.

![Figure 7 Comparison of material production capacity of various PV technologies](image)

1.5 Challenges: stability issues of complex lead halides

Since perovskite solar cells showed rapid progress of improvement in the efficiencies within a decade, it has emerged as future generation PV technology. However, long term operational stability has been a significant factor that acts as a blockade for the commercialization of PSCs. Silicon-based PV modules are considered to be stable for 25 years. On the contrary, perovskite solar cells are reported to be stable only for a few hundred hours to a maximum of one year \(^{5}\). Thus faces serious stability issues compared to
already available PV technology in the market. These stability issues can be further classified as extrinsic stability challenges and inherent stability challenges.

1.5.1 Extrinsic stability issues

The perovskite-based active layer is susceptible to external factors such as water, air and moisture. Out of many perovskite structures, MAPbI₃ perovskite-based active layer is widely explored to understand the degradation mechanism due to various extrinsic and intrinsic factors. Reports have shown that upon exposure to these external factors, PSCs degrades and loses their operational stability.

It was found that in the presence of water, MAPbI₃ crystal structure forms hydrates/complex with H₂O (equation 2) and deforms the perovskite structure destroying optoelectronic properties, resulting in loss of photovoltaic performance ¹⁹,²⁰.

\[ 4\text{CH}_3\text{NH}_3\text{PbI}_3 + \text{H}_2\text{O} \leftrightarrow 4\text{CH}_3\text{NH}_3\text{PbI}_3\cdot \text{H}_2\text{O} \leftrightarrow (\text{CH}_3\text{NH}_3)_4\text{PbI}_6 \cdot 2\text{H}_2\text{O} + 3\text{PbI}_2 + 2\text{H}_2\text{O} \]  (2)

Further, when MAPbI₃ is exposed to moisture under illumination, methyl-ammonium cation gets despoiled and results in PbI₂, I₂ and water (equation 3-6) ⁵. Thus, destabilize the solar cells.

\[ \text{CH}_3\text{NH}_3\text{PbI}_3 (s) \rightarrow \text{CH}_3\text{NH}_3\text{I} (aq) + \text{PbI}_2 (s) \]  (3)

\[ \text{CH}_3\text{NH}_3\text{I} (aq) \rightarrow \text{CH}_3\text{NH}_2 (aq) + \text{HI} (aq) \]  (4)

\[ 4\text{HI} (aq) + \text{O}_2 (g) \rightarrow 2\text{I}_2 (s) + 2\text{H}_2\text{O} \]  (5)

\[ 2\text{HI} (aq) \rightarrow \text{H}_2 (g) + \text{I}_2 (g) \]  (6)

Whereas the exposure of CH₃NH₃PbI₃ photo-active layers to light and dry oxygen results in superoxide (O₂⁻) species. This reactive O₂⁻ species can deprotonate the
methylammonium cation (CH$_3$NH$_3^+$), leading to the formation of PbI$_2$, water, methylamine and iodine $^{21-23}$, as shown in equation 7.

$$4\text{CH}_3\text{NH}_3\text{PbI}_3 + \text{O}_2 \rightarrow 4\text{CH}_3\text{NH}_2\text{I} + 2\text{I}_2 + 2\text{H}_2\text{O} + 4\text{PbI}_2$$  \hspace{1cm} (7)

Though, the impact of these external factors can still be minimized by encapsulating the active layer. However, it may result in loss of performance or increment in cost.

**1.5.2 Intrinsic stability issue**

Ironically, MAPbI$_3$ is intrinsically unstable as well. It means that in the presence of light and heat, MAPbI$_3$ tends to decompose. Sadly, these conditions are unavoidable for the operation of a solar cell. When the temperature is above 85°C, MAPbI$_3$ forms ammonia or some other volatile species and PbI$_2$ (equation 8) $^{20,24}$.

$$\text{CH}_3\text{NH}_3\text{PbI}_3 \rightarrow \text{PbI}_2 + \text{CH}_3\text{I} + \text{NH}_3$$  \hspace{1cm} (8)

Whereas, in the presence of light and temperature, the degradation pathways are reported as equation 9-10.

$$\text{CH}_3\text{NH}_3\text{PbI}_3 \rightarrow [(\text{PbI}_2)] + \text{volatile species (rising from CH}_3\text{NH}_3\text{I)}$$  \hspace{1cm} (9)

$$\text{PbI}_2 \rightarrow \text{Pb}^{2+} + 2\text{I}^- \rightarrow \text{Pb}^+ + \text{I}^0 + \text{I}^- \rightarrow (1/2)\text{Pb}^0 + (1/2)\text{PbI}_2 + (1/2)\text{I}_2$$  \hspace{1cm} (10)

In the presence of light and heat, PbI$_2$ is further decomposed and results in the formation of metallic lead and ionic iodine, as mentioned above $^{19,25}$.

Thus, this Pb$^0$ and iodine create defect sites resulting in instability of perovskite solar cell devices. These defect sites are often reported to be within the grains, at grain boundaries or at the surface of the CH$_3$NH$_3$PbI$_3$ perovskite layer. Moreover, these trap states can also alter the energy level alignment and destroy charge transfer properties in CH$_3$NH$_3$PbI$_3$ solar
cell devices. Besides, non-radiative recombination becomes more prominent in such a scenario, a clear indication of deterioration of device performance. Therefore, it is crucial/important to chemically passivate these defect sites to achieve longer stability of the CH$_3$NH$_3$PbI$_3$ layer $^{22}$. To do so, additive engineering is often adopted.

1.6 Aim

Thus this research project aims to improve the intrinsic stability challenge of MAPbI$_3$ perovskite-based light-absorbing layer using additive engineering. For this purpose, the impact of additive incorporation in perovskite film and its influence on photothermal stability has been intensively investigated. Further, the impact of additive incorporation on the morphological, optical, and electrical properties of perovskite films and solar cell devices has been studied. In the same context, device performance and intrinsic device stability under illumination have been further tested. Later, the mechanism of stability is proposed with respect to the structure and composition of additives in the perovskite film. Thus, this thesis is dedicated to additive engineering for CH$_3$NH$_3$PbI$_3$ photo-active layer for photovoltaic application.
2. Literature Review

So far, there is no proper rule of selection to choose additive for the MAPbI$_3$ light-absorbing layer. Majorly the additives have opted from already available literature or experimental data related to dye-sensitized solar cells (DSSC). For which additives are often categorized based on N donor, O donor and S donor atoms. Since these electron donor atoms can bind /coordinate with Pb$^{2+}$ species, it can result in adduct formation, passivate the grain boundaries, and improve efficiency and stability. Further, based on the electron-donating atoms, additives are subcategorized as amines, nitriles belonging to the N donor atom, amides, acids, acetates, alcohol, ester, ether belonging to the oxygen donor atom and sulphides, thiocyanates belonging to the S donor atom. Following the same idea, here, additives are classified as organic and inorganic additives with further classifications as mentioned above. Thus obtained analysis of the available literature is then published in a reputed journal which can be accessed at https://doi.org/10.3390/cryst11070814

2.1 Organic additives

2.1.1 N donor atom-based additives

2.1.1.1 Amine additives

Scientists commonly refer to amine-based additives. Following the recommendation, the non-stoichiometric use of methylammonium iodide as an amine additive was investigated in the early phases of developing perovskite solar cells. It was established that adding excess MAI reduces trap density, increases PL lifetime, and further increases PCE regardless of fabrication methods. Likewise, some other organic amine derivatives such as benzylammonium iodide (BAI) and Phenethylamine iodide (PEAI) have also been investigated as additives and found to improve light harvesting properties and exciton lifetime with reduced charge recombination. Besides, attaching hydrophobic cations within amine additives, such as hexylamine hydrochloride (1-HH), 1,6-diaminohexane dihydrochloride (1,6-DD) and phenylhydrazinium iodide (PHAI), may even work as a
protection for the MAPbI\textsubscript{3} film against moisture, improving the stability in ambient condition\textsuperscript{32,33}. Later, it was found that if instead of iodide, chloride-based counterpart (such as MACl instead of MAI) was used as an additive, perovskite films became more crystalline, with increased grain size and homogenous, smooth morphology, which further resulted in grain boundary passivation, resulting in better performance. Unfortunately, the addition of MACl was reported to form mixed halide perovskite CH\textsubscript{3}NH\textsubscript{3}PbI\textsubscript{3-x}Cl\textsubscript{x}\textsuperscript{34-36}. Although there were opposite reports about mixed halide formation. It was shown that when other halide ions, i.e. X=Br/Cl, are used with a minimum concentration in MAPbI\textsubscript{3} precursor, it does not affect MAPbI\textsubscript{3} characteristics, and the final perovskite remains crystalline MAPbI\textsubscript{3} phase-only instead of mixed halide perovskite. This is because a low concentration of halide ions can quickly evaporate as the films are annealed during the fabrication process. Some of the examples of such additives are Amphiphilic hexadecyl trimethyl ammonium bromide (CTMAB), ethyl ammonium chloride (EACl), 1,3-diaminoguanidine monohydrochloride (DAGCl), methoxyammonium chloride (MeOCl), 2, 2, 2-trifluoroethylamine hydrochloride (TFEACl), benzenamine hydrochloride (BACl), 3-chloropropylamine Hydrochloride (3-CPACl), diethylamine hydrochloride (DEACl)\textsuperscript{37-41}.

Furthermore, nitrogen-containing heterocyclic amines play a great role in improving stability\textsuperscript{42}. For instance, the introduction of 4, 4'-bipyridine in MAPbI\textsubscript{3} demonstrated complex formation with PbI\textsubscript{2}, thus improved intrinsic stability against illumination\textsuperscript{43}. Additionally, it has been shown that the presence of N atoms prevents the loss of volatile species from the perovskite film and acts in a similar way as polymeric passivation coating. Further, such a passivation effect was visible morphologically (in the SEM cross-section images and energy dispersive X-ray analysis) when PVC was added in MAPbI\textsubscript{3}\textsuperscript{44}. Later, scientists designed pyridine derivatives with units containing different multifunctional groups. One such additive is (C\textsubscript{60}-PyP), which contains C\textsubscript{60} units that are hydrophobic in nature and pyridine units which chelates Pb\textsuperscript{2+} by donating lone electron pair on the N atom.
It is known that uncoordinated Pb$^{2+}$ ions are considered trap states at grain boundaries and can block charge extraction \(^{45}\). Thus, grain boundaries are passivated by assisting coordination interactions with the Pb$^{2+}$ ion of MAPbI$_3$ and PyP unit that further improved short circuit current density $J_{sc}$ and eliminated ion migration. While the hydrophobic C$_{60}$ unit does not let moisture directly affect the film \(^{45}\). Similar results were noticeable when pyridine-2-carboxylic lead salt (PbPyA$_2$) and polyvinylpyrrolidone (PVP) additives were employed in MAPbI$_3$ precursor \(^{34,46}\). To add on, solvent additives with heterocyclic nitrogen-containing units also demonstrated similar results. In an investigation, Zhang and co-workers demonstrated that NMP as a solvent additive (when added in DMF) resulted in high quality of perovskite film due to Lewis acid-base reaction with Pb atom. The study revealed that intermediates obtained with different PbI$_2$/NMP ratios are of the same kind, because of which the solar cell performance and stability do not depend on the NMP ratio in the precursor \(^{47}\). Following the idea of Lewis acid-base interaction, KIM and co-workers explored pyrrolidone-based solvent additives and compared them with commonly used DMF based precursor \(^{48}\). For pyrrolidone-based solvent additives, different N-substituents: N-methyl-2-pyrrolidone (NMP), N-ethyl-2-pyrrolidone (NEP), N-cyclohexyl-2-pyrrolidone (CHP), and N-octyl-2-pyrrolidone (NOP) was employed. During the in situ crystal growth, it was observed that solvent additive containing pyrrolidone structure with higher boiling point results in lower vapour pressure over pristine DMF based precursor. Thus, it resulted in a further improvement in the morphology of perovskite film since the N substituent becomes bulkier with a higher boiling point (The boiling points of NMP, NEP, and CHP and NOP are 154°C, 202°C, 204 °C, 286 °C, 303 °C). Furthermore, it was discovered that the strength of coordination of solvent component influenced intermediate formation with PbI$_2$, which, in turn, was influenced by the boiling point of the solvent. This was based on the evidence when the intermediate phase was found to be vanished with CHP solvent additive, whereas pure DMF solvent without pyrrolidone-based solvent additives showed DMF: PbI$_2$ solvate formation. Therefore, it was suggested that the bulkier additive solvent suppress DMF: PbI$_2$ solvate formation which shows lack of stability when
used without any cosolvent. Some other derivative such as DMI, 1-(4-ethenylbenzyl)-3-(3,3,4,4,5,5,6,6,7,7,8,8,8-tridecafluoroocetylimidazolium iodide (ETI), 1-methyl-3-propylimidazolium bromide (MPIB), 1-butyl-3-tetrafluoroborate (BMIMBF4) are other examples that result in improved PCE and ambient stability due to hydrophobicity of N atoms with ring like structure.

2.1.1.2 Cyano/nitrile additives

Subsequently, it was observed that the cyano group-containing N atom could be equally effective to passivate grain boundaries. Triazine-graphdiyne (Tra-GD) is a graphene-like material that consists of pyridine-like nitrogen in the highly conjugated framework. It was suggested that balanced charge distribution in the C=N bond in the triazine ring promotes stronger interaction with Pb2+, resulting in very tight contact between these two materials. This in turn, did not allow the ion migration on the surface and successfully passivated grain boundaries. Similarly, graphitic carbon nitride addition also resulted in good morphology due to highly compact bonding between Pb2+ and N of C=N that further endorsed to achieve power conversion efficiencies (PCEs) up to 21.1% (aperture 0.16 cm²) and 19.5% (aperture 1.0 cm²), featuring an open-circuit voltage of 1.16 V (corresponding to a slight voltage loss of 0.39 V) and improved operational device stability (~90% initial efficiency retained after constant one sun illumination for 500 h). Further, Zhou and co-workers demonstrated that by employing 1,8-Diazaabicyclo[5.4.0]undec-7-ene (DBU), the formation of I− can also be suppressed due to adduct formation with PbI2. Besides, another solvent additive, acetonitrile (ACN), also showed improvement in morphology due to adduct formation with PbI2 when added in DMF based precursor. This further proved to increase PCE from 15.04% to 19.7%, which remained stable without encapsulation for 160 h, with the PCE remaining ~60% of the initial value when exposed to the white light. An overview of the influence of amines and nitrile additives on stability is shown in Figure A0.1, Appendix 0. Further, Table 1 below shows the effect of N donor atom-based additives on the PCE, stability and stability condition of MAPbI3 PSC.
Table 1 Additives based on nitrogen donor atom containing amines or nitrile

<table>
<thead>
<tr>
<th>Additive in active layer</th>
<th>Architecture</th>
<th>PCE, % (Pristine)</th>
<th>Stability (Pristine)</th>
<th>PCE, % (with additive)</th>
<th>amount of additive</th>
<th>Stability with additive</th>
<th>Stability conditions</th>
<th>Role of additive</th>
<th>Ref</th>
</tr>
</thead>
<tbody>
<tr>
<td>Excess MAI</td>
<td>FTO/ SnO₂/CH₃NH₃PbI₃/PCBM/Ag</td>
<td>15.14</td>
<td>N/A</td>
<td>17.24</td>
<td>Molar ratio (PbI₂: MAI) = 1:1.05</td>
<td>N/A</td>
<td>N/A</td>
<td>Hot casting, improved crystallinity, decrease in defect density, increased PL lifetime.</td>
<td>27</td>
</tr>
<tr>
<td>Excess MAI</td>
<td>ITO/PCBM/CH₃NH₃PbI₃/HTL/Au</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>MAI: PbI₂ molar ratio = 3:1</td>
<td>N/A</td>
<td>N/A</td>
<td>Vacuum deposition, increase PL lifetime, reduced trap states.</td>
<td>28</td>
</tr>
<tr>
<td>Excess MAI</td>
<td>FTO/ TiO₂/ CH₃NH₃PbI₃/Spiro-OmATAD/Au</td>
<td>11.13</td>
<td>N/A</td>
<td>13.37</td>
<td>0.2 mM</td>
<td>N/A</td>
<td>N/A</td>
<td>Sequential deposition, Good quality perovskite film and increment in recombination rate</td>
<td>29</td>
</tr>
<tr>
<td>benzylammonium iodide (BAI)</td>
<td>FTO/TiO₂/CH₃NH₃PbI₃/HTL/metal</td>
<td>6.83</td>
<td>N/A</td>
<td>9.05</td>
<td>molar ratio BAI/MAI = 0.2</td>
<td>N/A</td>
<td>N/A</td>
<td>better light harvesting property and low charge recombination</td>
<td>30</td>
</tr>
<tr>
<td>Phenethylamine iodide (PEAI)</td>
<td>FTO/ c-TiO₂/ m-TiO₂ / mp-ZrO₂ / CH₃NH₃PbI₃ / Carbon</td>
<td>6.3</td>
<td>Retained ~77% PCE after 80 days</td>
<td>8.60</td>
<td>molar ratio of PEAI:MAI = 1:20</td>
<td>Retained 90% PCE after 80 days</td>
<td>air, light-100mw/cm²,</td>
<td>better contact with TiO₂, longer exciton lifetime Good quality of perovskite film</td>
<td>31</td>
</tr>
<tr>
<td>Hexylamine Hydrochloride (1-HH)</td>
<td>Glass/ITO/PEDOT:PSS/CH₃NH₃PbI₃/PCBM/BCP/Ag</td>
<td>14.37</td>
<td>Retained 43% PCE from initial after 16 days</td>
<td>15.70</td>
<td>0.05 wt%</td>
<td>Retained ~85% PCE from initial after 16 days</td>
<td>Un-encapsulated, ambient, RT, air, RH=10-20%</td>
<td>Increases grain size and passivate defects. NH₃⁺ group could form N-H…I hydrogen bond with the I- of the [PbI₆]⁴⁻ passivating “A” vacancy; hydrophobic hexane alkyl chain protects against moisture</td>
<td></td>
</tr>
<tr>
<td>1,6-Diaminohexane Dihydrochloride (1,6-DD)</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>phenylhydrazinium iodide (PHAI)</td>
<td>FTO/PEDOT:PSS/CH₃NH₃PbI₃/PCBM/Rhodamine/Ag</td>
<td>14.63</td>
<td>a) Retained ~53 % PCE after 60 days b) died in 20 days</td>
<td>17.2</td>
<td>10 mg/mL</td>
<td>a) Retained ~90 % PCE after 60 days b) Retained ~85 % PCE after 20 days</td>
<td>a) unencapsulated, N₂, dark, RH=20% , T=26 °C b) (unencapsulated), ambient room environment (dark) at 30 ± 5% RH and 24 ± 2 °C</td>
<td>PbI₂ and PHAI complex/intermediate formation results in passivation against vacancy defects. Hydrophobic phenyl rings act as barrier against moisture</td>
<td></td>
</tr>
<tr>
<td>Amphiphilic hexadecyl trimethyl ammonium bromide (CTMAB)</td>
<td>Glass/FTO/TiO₂/CH₃NH₃PbI₃/Spiro/Au</td>
<td>17.05</td>
<td>Retained 70 % PCE after 40 days</td>
<td>18.03</td>
<td>10mg CTMAB in 1 ml DMSO. Used 20 µL of this</td>
<td>Retained 95 % PCE after 40 days</td>
<td>Non-encapsulated, RH~40%, T=25°C, dark</td>
<td>Improved crystallinity and morphology</td>
<td></td>
</tr>
<tr>
<td>Additive</td>
<td>Device Structure</td>
<td>Retained PCE after 1000 h</td>
<td>Retained PCE after 1000 h</td>
<td>Encapsulated</td>
<td>Non-encapsulated</td>
<td>Improvement in</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>----------------------------------------</td>
<td>-------------------------------------------------------</td>
<td>---------------------------</td>
<td>----------------------------</td>
<td>--------------</td>
<td>------------------</td>
<td>----------------</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Ethylammonium chloride (EACl)</td>
<td>Glass/FTO/c-TiO₂/meso-TiO₂/ CH₃NH₃PbI₃/HTL/Au</td>
<td>17.35</td>
<td>Retained ~30% of the original PCE</td>
<td>20.3</td>
<td>2.5% molar %</td>
<td>morphology, grain boundary passivation</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>1,3-Diaminoguanidine monohydrochloride (DAGCl)</td>
<td>Glass/ITO/PolyTPD/CH₃NH₃PbI₃/PC₆1BM/ZrAca c/Ag</td>
<td>19.1</td>
<td>Retained 70% PCE after 20 days</td>
<td>20.3</td>
<td>0.6%, wt% of MAI</td>
<td>Increased grain size, reduced trap density, DAG cation can bond with I via hydrogen</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Methoxyammonium chloride (MeOCl)</td>
<td>FTO/compact-TiO₂ layer/mesoporous-TiO₂ layer/CH₃NH₃PbI₃/spiro-MeOTAD/Ag</td>
<td>17.15</td>
<td>N/A</td>
<td>19.71</td>
<td>PbI/MeOCl molar ratio = 1:0.10</td>
<td>Grain size and crystallinity</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>2, 2, 2- trifluoroethylamine hydrochloride (TFEACl)</td>
<td>Glass/ITO/PEDOT:PSS/CH₃NH₃PbI₃/PCBM/Al</td>
<td>N/A</td>
<td>N/A</td>
<td>4.98</td>
<td>molar ratio of additive :MAI : Pbl₂ = 6:4:1:1</td>
<td>Compact smooth high quality film</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Benzenamine hydrochloride (BACl)</td>
<td></td>
<td></td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>3-Chloropropylamine hydrochloride (3-CPACl)</td>
<td></td>
<td></td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Diethylamine hydrochloride (DEACl)</td>
<td></td>
<td></td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Material</td>
<td>Device Structure</td>
<td>Time to Failure</td>
<td>Conditions</td>
<td>Stability</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>----------</td>
<td>-----------------</td>
<td>----------------</td>
<td>------------</td>
<td>-----------</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>4-ethylamine Phenylphosphate disodium salt (EAPP)</td>
<td>FTO/C-TiO$_2$/mp-TiO$_2$/CH$_3$NH$_3$PbI$_3$/Spiro/Ag</td>
<td>18.83 h</td>
<td>(a) Dead in 6 h (b) Remained 60% from initial PCE after 100 h</td>
<td>1 mol% (a) Remained 90% from initial PCE after 12 h (b) Remained ~99% from initial PCE after 100 h</td>
<td>(a) ATM condition, RH=80%, un-encapsulated. (b) inert, N$_2$ un-encapsulated. phenylethylamine group protects against moisture and improves ambient stability, phosphate sodium prevents the formation of (CH$_3$NH$_3$)$_4$PbI$_6$. H$_2$O.</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>4,4'-bipyridine</td>
<td>Glass/CH$_3$NH$_3$PbI$_3$</td>
<td>N/A</td>
<td>Died in ~900 h</td>
<td>N/A</td>
<td>5 wt % Remained active for 1400 h</td>
<td>inert, un-encapsulated. 70-80 mW/cm$^2$ 50-60 °C Forms complex with PbI$_2$ thus slows down the formation of metallic lead and inhibits carrier recombination, reduced defects</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>poly 4-vinylpyridine (PVP)</td>
<td>FTO/TiO$_2$/CH$_3$NH$_3$PbI$_3$/Spiro/Au</td>
<td>6.09 days</td>
<td>Remained 1.55% PCE as of final PCE (absolute value) after 3 weeks</td>
<td>13.07</td>
<td>0.4 wt% Remained 6.6% PCE as of final PCE (absolute value) after 3 weeks. Air, 50% RH, non-encapsulated. Inert, un-encapsulated.</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Polyvinylcarbazole (PVC)</td>
<td>ITO/PTAA/CH$_3$NH$_3$PbI$_3$/PCBM/Al</td>
<td>17.4 days</td>
<td>Died in 1500 h</td>
<td>18.7</td>
<td>1 mass% Retained ~70% of the initial efficiency after light soaking for 1500 h, light power of 50±3 mW/cm$^2$, the temperature of 65±2 °C in inert nitrogen. Defect passivation due to interaction with lone pair of electrons from N atom with Pb$^{2+}$</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>pyridine-functionalized fullerene derivative (C60-PyP)</td>
<td>ITO/TiO$_2$/CH$_3$NH$_3$PbI$_3$/Spiro-OMeTAD/Au</td>
<td>17.61 days</td>
<td>Retained 70% PCE after 30 days</td>
<td>19.82</td>
<td>0.13 wt % Retained 90% PCE after 30 days</td>
<td>25 °C, RH=30%, dark, non-Encapsulatio n, mppt-n/a, uv-filter-n/a. Enlarged grain size, improved crystallization, interaction b/w N atom of the pyridine moiety within C60-PyP</td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>
and Pb$^{2+}$ ion within MAPbI$_3$ leads to the passivation of trap states of perovskite layer, hydrophobic nature of C60-PyP molecule increases ambient stability.

| pyridine-2-carboxylic lead salt (PbPyA2) | ITO/P3CT-N / CH$_3$NH$_3$PbI$_3$/ (PCBM)/C$_{60}$/ (BCP)/Ag | 18.86 | (a) Retained 20% of PCE after 480 h (b) retained 20% of PCE after 540 h (c) retained 30% of PCE from initial after 480h | 19.96 | 4mg mL$^{-1}$ | (a) Retained 80% PCE after 480 h (b) retained 93% of initial PCE after 540 h (c) retained 90% PCE from initial after 480h | (a)90 °C,RH 40–60%, dark, not encapsulated. (b)MPP-tracking, non-encapsulated, white light-100mW/cm$^2$, inert, 25C. (c) Air, non-encapsulated, dark, RH 40–60% |

| polyvinylpyrrolidone (PVP) | Ito/SnO$_2$/ CH$_3$NH$_3$PbI$_3$/Spiro/Au | 15.33 | Retained 76% from initial PCE after 400 h | 15.19 | 1 mg mL$^{-1}$ | Retained 80% of the initial PCE after 60 days | Encapsulated, Ambient, RH-10%, RT, Lewis base, the pyridine part (side chain) of the PVP polymer, can passivate the surface defects caused by misaligned lead ions and can fill the iodine |

**Controlled crystallization, passivation of grain boundaries, the interaction of pyridine and carboxylate to cations increases hydrophobicity**
<table>
<thead>
<tr>
<th>Material</th>
<th>Device Structure</th>
<th>Initial PCE Retained</th>
<th>Type of Stabilization</th>
<th>Conditions</th>
<th>Deposition Method</th>
<th>Notes</th>
</tr>
</thead>
<tbody>
<tr>
<td>NMP</td>
<td>FTO/CrTiO$_2$/mp-TiO$_2$/CH$_3$NH$_3$PbI$_3$/Spiro/Au</td>
<td>15.5</td>
<td>a)Retained only ~10% PCE from initial after 30 days b) Retained ~55% PCE from initial after 30 days</td>
<td>ambient, air, dark</td>
<td>NMP ratio</td>
<td>N-donor and S-donor to coordinate with PbI$_2$ and slow down the formation of PbI$_2$ improved morphology, larger crystal size</td>
</tr>
<tr>
<td>NMP</td>
<td>NMP/FTO/ZnO-MgO-EA+ /mesoporous-TiO$_2$ /CH$_3$NH$_3$PbI$_3$/spiro-OMeTAD / Au</td>
<td>18.0</td>
<td>PbI$_2$/NMP molar ratios of 1:2</td>
<td>N/A</td>
<td>N/A</td>
<td>The same kind of intermediate, regardless of NMP ratio, results in excellent morphology</td>
</tr>
<tr>
<td>NMP</td>
<td>Glass/ITO/PEDOT:PSS/CH$_3$NH$_3$PbI$_3$/PC$_6$1BM/Al</td>
<td>1.50</td>
<td>60 μl in 1 ml precursor</td>
<td>N/A</td>
<td>N/A</td>
<td>Lewis acid base interaction</td>
</tr>
<tr>
<td>NEP</td>
<td></td>
<td></td>
<td></td>
<td>10.04</td>
<td></td>
<td>-</td>
</tr>
<tr>
<td>CHP</td>
<td></td>
<td></td>
<td></td>
<td>12.87</td>
<td></td>
<td>Suppression of solvate formation</td>
</tr>
<tr>
<td>NOP</td>
<td></td>
<td></td>
<td></td>
<td>2.79</td>
<td></td>
<td>Lewis acid-base interaction</td>
</tr>
<tr>
<td>DMI</td>
<td>FTO/compact-TiO$_2$/CH$_3$NH$_3$PbI$_3$/Spiro-OMeTAD/Au</td>
<td>10.72</td>
<td>10 vol% in 1 ml precursor</td>
<td>N/A</td>
<td>N/A</td>
<td>Pb-O bond formation due to Lewis adduct</td>
</tr>
<tr>
<td>1-(4-ethenylbenzyl)-3- (3,3,4,4,5,5,6,7,7,8,8,8-tridecafluoroctylimidazolium iodide (ETI)</td>
<td>FTO/C-TiO2/mp-TiO2/CH3NH3PbI3/Spiro/Au</td>
<td>19.2</td>
<td>(a) Retained 49% PCE from initial 700 h (b) Retained 60% PCE from initial 700 h</td>
<td>19.5</td>
<td>1 mol%</td>
<td>(a) Retained 85% PCE from initial 700 h (b) Retained 80% PCE from initial 700 h</td>
</tr>
<tr>
<td>1-methyl-3-propylimidazolium bromide (MPIB)</td>
<td>ITO/PEDOT:PSS/CH3NH3PbI3/PC61BM/BCP/Ag</td>
<td>15.9</td>
<td>Retain ~50% of its original PCE after 150 h</td>
<td>18.2</td>
<td>0.5 mg in 1 ml</td>
<td>Retain 78% of its original PCE after 150 h</td>
</tr>
<tr>
<td>BMIMBF4 1-butyl-3-tetrafluoroborate</td>
<td>ITO/NiOx/CH3NH3PbI3/C60/Ag</td>
<td>18.15</td>
<td>Retaining 30% of their initial PCE after thermal ageing of 400 h at 85 °C</td>
<td>18.07</td>
<td>0.4 mol%</td>
<td>Retaining 80% of their initial PCE after thermal ageing of 400 h at 85 °C</td>
</tr>
<tr>
<td>Material Type</td>
<td>Device Configuration</td>
<td>PCE Retention</td>
<td>Weight Ratio</td>
<td>Molar Ratios</td>
<td>Other Properties</td>
<td></td>
</tr>
<tr>
<td>-------------------------------</td>
<td>------------------------------------------------</td>
<td>---------------</td>
<td>--------------</td>
<td>--------------</td>
<td>----------------------------------------------------------------------------------</td>
<td></td>
</tr>
<tr>
<td>triazine-graphdiyne (Tra-GD)</td>
<td>ITO/P3CT-K/CH3NH3PbI3/PC61BM/ZnO/Al</td>
<td>17.90</td>
<td>20.33</td>
<td>2 mg/ml</td>
<td>Died in 1100 h, Retain above 90% after 1100 h, un-encapsulated, interacts with Pb2+ at grain boundaries and passivates grain boundaries and inhibits ion migration</td>
<td></td>
</tr>
<tr>
<td>graphitic carbon nitride (g-C3N4)</td>
<td>FTO/compact TiO2/CH3NH3PbI3/Spiro-MeOTAD/Au</td>
<td>18</td>
<td>Retained 46% PCE after 300 h</td>
<td>21.6</td>
<td>0.1 wt% Retained 90% PCE from initial after 500 h, Encapsulated, Improves grain size and crystallinity, passivates grain boundaries. C=N to interact with Pb2+, decreases the conductivity and carrier mobility</td>
<td></td>
</tr>
<tr>
<td>graphitic carbon nitride (g-C3N4)</td>
<td>FTO/compact TiO2/CH3NH3PbI3/Spiro-OMeTAD/MoO3/Ag</td>
<td>16.22 ± 0.83</td>
<td>N/A</td>
<td>0.4 mg mL</td>
<td>Passivation, enhanced crystallinity, C=N to interact with Pb2+, increases the conductivity and carrier mobility</td>
<td></td>
</tr>
<tr>
<td>1,8-Diazabicyclo[5.4.0]undec-7-ene (DBU)</td>
<td>Glass/ITO/NiOx/CH3NH3PbI3/PCBM/PEI/Ag</td>
<td>15.98</td>
<td>Retained 50% PCE from initial after 10 days</td>
<td>18.13</td>
<td>3% weight ratio Retained 80% PCE from initial after 10 days, un-encapsulated, inert (N2), mpp tracking, Iodine quencher, adduct with PbI2 (C=N interaction with Pb2+), reduced defects, high-quality perovskite film</td>
<td></td>
</tr>
<tr>
<td>acetamidine salt (AcHc)</td>
<td>ITO/TiO2/CH3NH3PbI3/Spiro-OMeTAD/Au</td>
<td>15.45</td>
<td>N/A</td>
<td>Molar ratios of MAI and</td>
<td>N/A</td>
<td>N/A Passivation, smooth film, full and uniform coverage, large</td>
</tr>
<tr>
<td>Material</td>
<td>Structure</td>
<td>Grain size, improve carrier lifetime.</td>
<td>AaHec = 1 : 0.08</td>
<td>wt %</td>
<td>Molar ratio of ACN: PbI₂ is 0.5</td>
<td>Remaining</td>
</tr>
<tr>
<td>--------------</td>
<td>---------------------------------------------------------------------------</td>
<td>---------------------------------------</td>
<td>-----------------</td>
<td>------</td>
<td>-------------------------------</td>
<td>-----------</td>
</tr>
<tr>
<td>Spiro-OMeTAD</td>
<td>FTO/ Den TiO₂/mp-TiO₂/CH₃NH₃PbI₃/spiro-OMeTAD/Au</td>
<td>15.52</td>
<td>N/A</td>
<td>17.77</td>
<td>0.01</td>
<td>~20 % of initial PCE after 150 h</td>
</tr>
<tr>
<td>ACN</td>
<td>ITO/TiO₂/ CH₃NH₃PbI₃ /Spiro-OMeTAD/Au</td>
<td>15.04±0.48</td>
<td>Remained ~20 % of initial PCE after 150 h</td>
<td>19.7</td>
<td>Remained ~60 % PCE after 150 h</td>
<td>100 mW·cm⁻² RH= 60%-90% , in air without encapsulation</td>
</tr>
</tbody>
</table>
2.1.2 O donor atom-based additives

Additives containing O atom as Lewis base may consist of various functional groups such as carbonyls, carboxyl, carboxylates, ester, ethers, alcohols.

2.1.2.1 Carbonyl and amide additives

One of the systematically investigated additives is urea. Urea is an eco-friendly compound consisting of a carbonyl group known to interact with PbI₂. It has been illustrated that PbI₂ and urea forms an intermediate PbI₂.O=C(NH₂)₂ when added to the PbI₂ precursor solution in the double-step spin coating process. The oxygen atoms act as Lewis base. Whereas Pb²⁺ acts as Lewis acid, resulting in the formation of Lewis acid-base adduct. This adduct formation further results in large, flat grains. Similar results were observed for the single-step spin coating process, resulting in grain boundary passivation, improved crystalline film and suppressed non-radiative recombination losses, further improving the efficiency of solar cells.

Moreover, it was shown that incorporating amides in MAPbI₃ reduces the Fermi level by interacting I⁻ defect vacancy, reducing the trap sites and increasing the work function of MAPbI₃ perovskite. At the same time, the carbonyl group transfers electrons to perovskite, reducing the Fermi level, which in turn helps to achieve better charge transport properties.

Recently, a variant of urea, biuret incorporation in MAPbI₃ precursor attributed the intermediate formation with PbI₂ to the electron delocalization in the N-C=O-N system in the presence of carbonyl group and explained this is why the peak shift for C=O vibration is noticed in FTIR spectra. In the case of biuret-modified MAPbI₃ film from 1722 to 1713 cm⁻¹. Some other additives such as benzoquinone (BQ), triazine perylene diimide (TPDI), 3,4-dihydroxybenzhydrazide (DOBD), benzamidine hydrochloride (BMCl) containing the carbonyl group have shown similar properties. Similarly, it was also shown that if a hydrophobic ring is attached within the additive framework in combination with the carbonyl group (Isatin-Cl additive), it also acts as a shield against humidity in ambient conditions, helping to maintain the PCE nearly to 95 % of the initial state. Besides, the usage of the carbonyl group can also be expanded to improve the flexibility of flexible, printable solar cells (FPSC). Polycaprolactone (PCL) additive in MAPbI₃ has shown desirable improvement in PCE as well as mechanical strength. This improvement in mechanical stability was ascribed to a two-fold increase in grain size (from 200 nm to 400 nm) and homogenous grain distribution,
leading to improved mechanical stability that maintained PCE more than 90% of the initial state after 300 cycles for the radius from 20 mm to 4 mm and stability under illumination for 350 h.

2.1.2.2 Sulphonyl additives

Furthermore, carbonyl-based additives are often compared with the sulphonyl-based group, where the O atom is connected to different species, (i.e. S atom instead of C atom). Fang and co-workers have done one such study in which the strength of Pb coordination of sulphonyl group containing additive was compared with carbonyl-based additive. To do so, two novel fused ring non-fullerene acceptor materials IDIS-Th and IDIC-Th were introduced into MAPbI$_3$. IDIC-Th had the Lewis base functional group carbonyl (C=O), and IDIS-Th had a sulfonyl group (O=S=O). Since the sulfonyl group (O=S=O) is a stronger electron-withdrawing group compared with carbonyl (C=O), the sulfonyl group was predicted to have a stronger interaction with Pb ions than carbonyl (C=O) because the two sulphur-oxygen double bonds can chelate Pb$^{2+}$ with stronger interaction. Besides, it was noticed that replacing carbonyl with sulfonyl group can effectively downshift the lowest unoccupied molecular orbital (LUMO) level of IDIS-Th, which indicated the sulfonyl group is a stronger electron-withdrawing group. Thus, the interaction with Pb would reduce the defect traps density. Further, to confirm the defect passivation effect of IDIC-Th and IDIS-Th, the trap densities ($n_{\text{trap}}$) in bulk MAPbI$_3$ films were calculated and found to be $8.85 \times 10^{15}$ cm$^{-3}$ and $4.20 \times 10^{15}$ cm$^{-3}$, respectively. Undoubtedly, the sulphonyl group reduced the defect states. This further reflected improvements in the contact angles of the film (so that the hydrophobicity of the films). The improvement in hydrophobicity indicated that the additive molecules at the GBs and surface could inhibit the raid of moisture to MAPbI$_3$ films. However, both IDIC-Th and IDIS-Th are known for their hydrophobic nature. Nevertheless, these changes reflect further improvement in hydrophobic nature. Besides, the influence of the two molecules on photovoltaic performance was also examined. The PSC with IDIS-Th molecule showed significant improvement in PCE and reached up to 20.01%. To add on, due to the strong passivation effect of IDIS-Th, PSC with IDIS-Th demonstrated superior stability over PSC with IDIC-Th in ambient conditions under solar radiation and in the dark at high temperature. Likewise, a comparison of solvent additives hexamethyl phosphoric triamide (HMPA) and dimethyl sulphoxide (DMSO) were made, which was further compared to solvent additive NMethyl-2-
pyrrolidone (NMP). Here, Lewis basicity, donor number ($D_N$), and boiling point of solvents were utilised as comparison parameters to correlate the role of solvents in regulating morphology. This investigation done by Cao and Wei co-workers highlighted that the larger the donor number, the stronger is the Lewis basicity of the solvent additive. The donor number of DMF, N-Methyl-2-pyrrolidone (NMP), dimethyl sulfoxide (DMSO), and hexamethyl phosphoric triamide (HMPA) are 26.6, 27.3, 29.8, and 38.8, respectively. Therefore, it was suggested that Pb-O bond strength would increase with an increase in the donor number of additive $^{77,78}$. Hence, NMP, DMSO and HMPA have been expected to form stronger intermediates over pure DMF. In addition, it is also observed that the strong Lewis base additives exhibit higher boiling points. (The boiling point of the DMF, NMP, DMSO, and HMPA are 152, 202, 189, 235 °C, respectively) $^{79,80}$. This, in turn, reduces the evaporation rate of the solvent during the spin-coating process, resulting in a good film morphology. As a result, DMSO followed by NMP cosolvents displayed excellent PCE of 14.66% and 16.17% over pristine (DMF) (12.25%). As no residue of PbI$_2$ remained and complete conversion into perovskite resulted in less resistance $^{81}$. Further, other solvent additives based on O donor atoms, such as tetramethylene sulfone (TMS) $^{82}$ and tetrahydrothiophene oxide (THTO), also utilized a similar mechanism of forming Pb-O bond and improved performance and stability $^{83}$. The influence of amides/carbonyl and sulphonyl group based additives on the stability of the MAPbI$_3$ layer have been presented in Table 2.
Table 2 A summary of additives containing Amides/carbonyls/sulphonyl functional group in MAPbI₃ active layer.⁵⁷

<table>
<thead>
<tr>
<th>Additive in active layer</th>
<th>architecture</th>
<th>PCE, % (Pristine)</th>
<th>Stability (Pristine)</th>
<th>PCE, % (with additive)</th>
<th>amount of additive</th>
<th>Stability with additive</th>
<th>Stability conditions</th>
<th>Role of additive</th>
<th>Ref</th>
</tr>
</thead>
<tbody>
<tr>
<td>Urea</td>
<td>Glass/ITO/PEDOT:PSS/CH₃NH₃PbI₃/PCMB/BCP/Al</td>
<td>15.1</td>
<td>Retained ~35% from original PCE after 2 h</td>
<td>17</td>
<td>molar ratio of the urea: lead acetate = 0.5</td>
<td>Retained ~60% from original PCE after 2 h</td>
<td>Light, 100mW/cm², 50-60°C, inert, unencapsulated</td>
<td>interaction of carbonyl group of urea with PbI₂ results in crystalline film, resulting passivation and improvement in stability</td>
<td>⁶⁴</td>
</tr>
<tr>
<td>Urea</td>
<td>ITO/PEDOT:PSS/PbI₃/MAI/P CBM/BPhen/Ag</td>
<td>12.75</td>
<td>N/A</td>
<td>18.01</td>
<td>5 wt %, wt % of PbI₂</td>
<td>N/A</td>
<td>N/A</td>
<td>double step spin coating, Urea and PbI₂ together form PbI₂O=C(NH₂)₂ complex/intermediate, resulting big flat grains</td>
<td>⁶⁵</td>
</tr>
<tr>
<td>Urea</td>
<td>ITO/SnO₂/CH₃NH₃PbI₃/Spiro/Ag</td>
<td>16.80</td>
<td>a) Retained 10 % PCE as of final PCE after ~27 days b) retained nearly 90 % PCE from initial after 60 mins</td>
<td>18.5</td>
<td>4 mol%</td>
<td>a) Remained 12 % PCE as of final PCE after ~27 days b) retained nearly 100 % PCE from initial after 60 mins</td>
<td>mppt tracking a) dark, ambient, b) 1 sun, in-situ</td>
<td>adduct formation, high crystallinity, good film, suppress non-radiative recombination and passivates grain boundaries.</td>
<td>⁶⁶</td>
</tr>
<tr>
<td>formamide</td>
<td>FTO/ (c-TiO₂/ (mp-TiO₂)/mesoporous / CH₃NH₃PbI₃/ZrO₂) /ZrO₂ / carbon electrode</td>
<td>14.26</td>
<td>N/A</td>
<td>15.21</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>The amide additives shifted the Fermi level of the MAPbI₃ perovskite from ~4.36 eV to ~4.63, ~4.65, and ~4.61 eV, respectively for 1.formamide, 2. Acetamide, and 3. urea and suppressed non-radiative recombination. Reduced iodide defects vacancy</td>
<td>⁶⁷</td>
</tr>
<tr>
<td>acetamide</td>
<td></td>
<td>15.57</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td></td>
<td></td>
</tr>
<tr>
<td>thiourea</td>
<td></td>
<td>15.07</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Biuret</td>
<td>FTO/TiO₂/CH₃NH₃PbI₃/PCBM/Ag</td>
<td>18.26</td>
<td>maintains ~50%PCE after 12 days</td>
<td>21.16</td>
<td>2 mol%</td>
<td>preserves 94% of its initial efficiency after 12 day</td>
<td>85°C, N₂, inert, non-encapsulated</td>
<td>Increased grain size, reduced trap state, additive acts as Lewis base and interacted with uncoordinated Pb²⁺,</td>
<td>⁶⁸</td>
</tr>
<tr>
<td>Compound</td>
<td>Layer Configuration</td>
<td>PCE Retained</td>
<td>Notes/Conditions</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>--------------------------------</td>
<td>---------------------</td>
<td>--------------</td>
<td>-------------------------------------------------------------------</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>benzoquinone (BQ)</td>
<td>ITO /PEDOT:PSS /CH3NH3PbI3 / C60 /BCP/Au</td>
<td>10.7</td>
<td>Remained ~50% PCE from initial after 900 h</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>15.6</td>
<td>0.5 mol% PCE from initial after 1000 h</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>unencapsulated, 1 sun, open circuit, without uv-filter</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>improves the thermal stability</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>reduces trap density</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>benzoquinone (BQ)</td>
<td>FTO/TiO2/ CH3NH3PbI3 /SpiroOMeTAD/Au</td>
<td>17.37</td>
<td>(a) Dead in 1200 h (b) Dead in ~800 h</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>18.01</td>
<td>0.25% PCE from initial after 2400 h</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>(a) Retained 75 % PCE from initial after 2400 h</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>(b) Retained ~30 % PCE from initial after 1200 h</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>un-encapsulated, without uv-filter</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>(a) RH (~20%, RT)</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>(b) ambient air, RH (40%-70%, RT)</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>Improves crystal quality, passivate grain boundary, reduce trap states, suppress PbI2 formation at GB</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>triazine perylene diimide (TPDI)</td>
<td>ITO/PEDOT:PSS/ CH3NH3PbI3/PC61BM /Ag</td>
<td>8.32</td>
<td>Retained 30% from initial PCE after 400h</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>10.84</td>
<td>1.2 mg/mL</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>Retained 60% PCE from initial PCE after 400h</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>Non-encapsulated, ambient, minimize grain boundary defects and enhance the coverage and crystal grain sizes</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>3,4-Dihydroxybenzhydrazide (DOBD)</td>
<td>ITO/PEDOT:PSS/ CH3NH3PbI3/C60 /BCP/Al</td>
<td>14.47</td>
<td>Retained 70% PCE from initial after 35 days</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>17.58</td>
<td>3 mg/mL</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>Retained 85% PCE from initial after 35 days</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>Non-encapsulated, inert, dark, increases grain size and decrease of grain boundaries, both of which facilitate charge transportation and suppress charge recombination, due to Lewis acid-base interaction between Pb2+ and CaO</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>BMCl, benzamidine hydrochloride</td>
<td>(ITO/TiO2/PC61BM/ CH3NH3PbI3/PTAA/MoO3/Ag</td>
<td>17.8</td>
<td>N/A</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>18.4</td>
<td>N/A</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>N/A</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>N/A</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>enhance work function of perovskite film improving efficiency</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Isatin-Cl</td>
<td>ITO/PTAA:F4TCNQ/ CH3NH3PbI3/ PCBM/ Al</td>
<td>18.13</td>
<td>a) Retained 60% PCE from initial after 350 h. b) Retained 30% PCE from initial after 24 h</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>20.18</td>
<td>0.0001 wt%</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>a) Retained 95% PCE from initial after 350 h. b) Retained 75% PCE from initial after 24 h</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>un-encapsulated, a) in ambient air, RH=45%, room temperature, b) in nitrogen atmosphere at 85 °C temperature, The carbonyl groups and hydrogen-bond structures on Isatin-Cl passivate the defect states in the perovskite grain boundaries and improve charge transport, suppress charge recombination, hydrophobic ring attached to Isatin-Cl improves stability against humidity.</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Material</td>
<td>Description</td>
<td>Retained % of initial PCE</td>
<td>Molar Ratio</td>
<td>Temperature</td>
<td>Stability</td>
<td>Notes</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>----------</td>
<td>-------------</td>
<td>---------------------------</td>
<td>-------------</td>
<td>-------------</td>
<td>-----------</td>
<td>-------</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>polycaprolactone (PCL)</td>
<td>glass or PET/ITO/PEDOT:PSS/CH3NH3PbI3/PC61BM/BCP/Ag</td>
<td>Retained 32% of initial PCE (10.12%) after 300 bending cycles</td>
<td>14.49</td>
<td>0.025 wt%</td>
<td>Retained 90% of initial PCE (10.12%) after 300 bending cycle</td>
<td>mechanical bending stability</td>
<td>carbonyl (C=O) and Pb2+ bond helps the uniform coverage of perovskite, which avoids the defects and achieve the grain boundary regulation on flexible PSC</td>
<td></td>
<td></td>
</tr>
<tr>
<td>IDIS-Th</td>
<td>ITO/P3CT-N/CH3NH3PbI3/PC61BM/Bphen/Ag</td>
<td>Retained 50% from initial PCE after 300h</td>
<td>20.1</td>
<td>0.05mg mL-1</td>
<td>Retained 80% from initial PCE after 300h</td>
<td>(a)100 mW cm-2, ambient, RH=30%, non-encapsulated, (b) 85C, inert, dark,</td>
<td>Passivate grain boundary, reduce charge recombination, adduct between additive and under coordinated Pb ions can effectively inhibit ion migration and moisture diffusion to enhance the stability of PSC devices</td>
<td></td>
<td></td>
</tr>
<tr>
<td>IDIC-Th</td>
<td>ITO/TiO2/PbI2/MAI/Spiro-OMeTAD/Au</td>
<td>Died after 14 days</td>
<td>14.66</td>
<td>30% NMP in 1ml precursor</td>
<td>Retained 66% from initial PCE after 14 days</td>
<td>in air</td>
<td>morphology control based on Lewis basicity based, Donor number and boiling point</td>
<td></td>
<td></td>
</tr>
<tr>
<td>NMP</td>
<td>FTO/TiO2/PbI2/MAI/Spiro-OMeTAD/Au</td>
<td>Retained 30% from initial PCE after 14 days</td>
<td>16.17</td>
<td>20% DMSO in 1ml precursor</td>
<td>Retained 80% from initial PCE after 300h</td>
<td>in air</td>
<td>morphology control based on Lewis basicity based, Donor number and boiling point</td>
<td></td>
<td></td>
</tr>
<tr>
<td>DMSO</td>
<td>FTO/TiO2/PbI2/MAI/Spiro-OMeTAD/Au</td>
<td>Retained ~70% from initial PCE after 30 days</td>
<td>16.2</td>
<td>Molar ratio =PbI2 :MAI :TMS (2:2:1)</td>
<td>Retained 80% from initial PCE after 30 days</td>
<td>RT, RH=10-40%, un encapsulated, dark</td>
<td>Intermediate phase via cross-linking. PbI2 act as Lewis acid TMS with S=O group acts as Lewis base.</td>
<td></td>
<td></td>
</tr>
<tr>
<td>HMPA</td>
<td>FTO/TiO2/mp-TiO2/CH3NH3PbI3/Spiro/Au</td>
<td>Retained 70% from initial PCE after 30 days</td>
<td>8.7</td>
<td>Molar ratio =PbI2 :MAI :TMS (2:2:1)</td>
<td>Retained 80% from initial PCE after 30 days</td>
<td>RT, RH=10-40%, un encapsulated, dark</td>
<td>Intermediate phase via cross-linking. PbI2 act as Lewis acid TMS with S=O group acts as Lewis base.</td>
<td></td>
<td></td>
</tr>
<tr>
<td>tetrahydrothiophene oxide (THTO)</td>
<td>ITO/PEDOT:PSS/CH3NH3PbI3/PCBM/A</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>additive alters the nucleation and growth processes, lowered the free energy of the precursor by incorporating a sulfoxide (S=O), which strongly interacts with MAPbI3 precursors, allowing an unprecedented degree of control over the nucleation density and growth rate.</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>
2.1.2.3 Carboxylic / acid additives

Besides, acids additives have also been incorporated in the MAPbI$_3$ precursor. The most commonly reported acid additive is 5-amino valeric acid (5-AVA). Dauskardt and co-workers showed that the introduction of 5-AVA into MAPbI$_3$ precursor could be helpful to increase the mechanical robustness of the perovskite film. To test the mechanical reliability double cantilever beam method was used, and the cohesion energy (Gc) was calculated from the critical load at which the film created cracks. It was observed that the incorporation of 5% concentration of 5-AVA into MAPbI$_3$ precursor increased cohesion energy (Gc) from 0.61 ± 0.27 J/m$^2$ (pristine) to 6.04 ± 2.04 J/m$^2$ (with AVA additive) almost by 12-fold. This improvement in Gc with 5-AVA was attributed to enhanced interaction forces due to the longer alkyl chains present in the 5-AVA. Additionally, a further increase in plasticity and crack deflection around the additive-containing perovskite grain boundaries was observed. Later, the elastic moduli of MAPbI$_3$ perovskite films with 5-AVA showed a slight decrease in the elastic modulus from 20.5 GPa (pristine) to 18.9 GPa (5-AVA) (using the Nanoindentation method). This decrease in stiffness of the planar perovskite structure made it more mechanically robust and less brittle. Also, it was confirmed that adding 5 AVA in MAPbI$_3$ precursor does not change MAPbI$_3$ lattice parameters. Simultaneously, another study done by Durrant and the group reported enhanced photostability of MAPbI$_3$ solar cells due to surface defect passivation in screen printed, HTM free, carbon electrode based PSC consisting of 5 AVA in MAPbI$_3$. They found a 40-fold increase in device lifetime measured under full sun illumination in ambient air (RH± 15%). Further, it was proposed that AVA is located at grain boundaries and thus able to passivate surface defect sites, resulting in enhanced resistivity to oxygen-induced degradation. The impressive improvement in the stability due to AVA additive is attributed to the interaction of halides with –COOH and NH$_3^+$ group, through hydrogen bonding [(O-H---I) and (N-H---I)] and also been further verified in the large area cell with an area of 0.25 cm$^2$ that demonstrated the efficiency of 6.6% with a decent shelf life of 75 days, maintaining more than 90% of initial efficiency. Later, using polyacrylic acid (PAA), Cao and workers also demonstrated that acid additives could be useful for large area (1 cm$^2$) films using the doctor blade method. Using the carboxyl functional groups of PAA, iodide ion vacancies at the perovskite crystal surface could be cross-linked. Thus the interaction of the PAA molecule with MAPbI$_3$ passivates defects and improves PCE and stability.
that bifacial passivation could also be obtained by the interaction of a functional group of -COOH, combined with -C= S (of thiocetic acid (TA)). Lewis acid-base reaction between under-coordinated Pb$^{2+}$ and S atom in MAPbI$_3$ can passivate one side, and at the same time, TiO$_2$ can interact with COOH through hydrogen bonding, resulting in double-sided passivation. Likewise, various studies reported that if multiple –COOH groups are attached with hydrophobic phenyl ring – it can chelate with Pb$^{2+}$ atom and act as a shield against moisture and humidity under ambient conditions, maintaining the overall crystallinity of film. Terephthalic acid (TPA) and trimesic acid (TMA) are examples. The proposed mechanism of stability in such a case is given as follows: negatively charged groups ($-$COO$^-$) strongly attract Pb$^{2+}$ ions in the precursor solution via electrostatic interactions. At the same time, the hydrogen atom from carboxylic acid can bond covalently with the halide anion in the solution due to the strong electronegativity of halide ions. Thus, it overall suppresses the loss of iodine molecules and, in turn, slows down the decomposition of MAPbI$_3$ light absorbing layer. Simultaneously, benzene ring with rigidity and $\pi$-$\pi$ bond effect does not allow to interact with water and protects against thermal stress and UV-illumination in ambient conditions. Similar effects were observed when 3,30,5,50-azobenzene-tetracarboxylic acid (H$_4$abtc) containing two benzene rings connected via azo bonding is introduced in PbI$_2$ precursor in optimum amount (2 mass %). Although the purpose of using the azo group was to reduce the stiffness of the perovskite film. However, due to the hydrophobic nature of attached cation in the acid-containing additive, most of them increase ambient stability. Further details of acid-based additives in MAPbI$_3$ are provided in Table 3 below.
<table>
<thead>
<tr>
<th>Additive in active layer</th>
<th>architecture</th>
<th>PCE, % (Pristine)</th>
<th>Stability (Pristine)</th>
<th>PCE, % (with additive)</th>
<th>amount of additive</th>
<th>Stability with additive</th>
<th>Stability conditions</th>
<th>Role of additive</th>
<th>Ref</th>
</tr>
</thead>
<tbody>
<tr>
<td>5-aminovaleric acid (5-AVA)</td>
<td>FTO/ C60/ CH3NH3PbI3 /PTAA/Au</td>
<td>15.4</td>
<td>N/A</td>
<td>13.7</td>
<td>5% wt</td>
<td>N/A</td>
<td>N/A</td>
<td>Larger grain size, improved crystallinity, improved mechanical robustness</td>
<td>84</td>
</tr>
<tr>
<td>amino valeric acid AVA</td>
<td>FTO/compact TiO2/mesoporous TiO2/mesoporous ZrO2/mesoporous carbon</td>
<td>11.1</td>
<td>Died in 110 h</td>
<td>9.1</td>
<td>3% molar ratio of AVA: MAI</td>
<td>Retained 50% PCE from initial after 110 h</td>
<td>RH =15%, 1 Sun, non-encapsulated, AVA located at grain boundaries is able to passivate surface defect sites, resulting in enhanced resistivity to oxygen-induced degradation.</td>
<td>85</td>
<td></td>
</tr>
<tr>
<td>5-ammonium valeric acid iodide (5-AVAl)</td>
<td>FTO/TiO2/ CH3NH3PbI3/ ZrO2/Carbon</td>
<td>N/A</td>
<td>N/A</td>
<td>6.68</td>
<td>0.072M of AVAI</td>
<td>5.62% PCE as of final PCE after 75 days</td>
<td>Ambient, Big area 0.25cm², lower charge transport resistance</td>
<td>86</td>
<td></td>
</tr>
<tr>
<td>aminovaleric acid iodide (AVA)</td>
<td>TiO2 /ZrO2/ CH3NH3PbI3/Spiro/Au</td>
<td>~7</td>
<td>14.9</td>
<td>5 mg/mL</td>
<td>Retained 80% from initial PCE after 24 days</td>
<td>RT, air, ambient,RH~30±5%, non-encapsulated, Using the doctor blade method, a smooth, uniform, and pin-hole free film of high electronic quality, passivate defects, large area devices (1cm²)</td>
<td>Controls ion migration-</td>
<td>92</td>
<td></td>
</tr>
<tr>
<td>Poly(acrylic acid) PAA</td>
<td>FTO/ NiOx:Zn/ CH3NH3PbI3/ (PC61BM)/bathocuproine (BCP)/Ag</td>
<td>10.3</td>
<td>Retained 60% from initial PCE after 24 days</td>
<td>6% as of PCE after 90 days</td>
<td>19.23</td>
<td>weight ratio of MAI:APPA= 0.56</td>
<td>Un-encapsulated, RH-10%, Smaller grain size, smooth surface, suppress non-radiative charge recombination, resulting in enhanced Jsc and Voc</td>
<td>97</td>
<td></td>
</tr>
<tr>
<td>aminopropanoi c acid (APPA)</td>
<td>ITO/PTAA/CH3NH3PbI3/ PC61BM/BCP/Ag,</td>
<td>17.51</td>
<td>6% as of PCE after 90 days</td>
<td>20.4</td>
<td>20 mg/ml</td>
<td>a) retains 98% of its original PCE after 450 min b) 97% PCE after 2100 h c) retained 92% PCE from initial after 600 h</td>
<td>carboxylic acid moieties Binds TiO2 surface Then five-membered ring-containing the dynamic covalent disulfide is bonded to the other end of the molecule through the thermal-initiated ring-opening and interacts with Pb, forming high-quality perovskite film due to the Lewis acid-base reaction between S and Pb2+. Extra passivation on TiO2 helps for efficient charge extraction and stability under UV illumination and ambient conditions</td>
<td>98</td>
<td></td>
</tr>
<tr>
<td>thioctic acid (TA)</td>
<td>FTO/compact TiO2 (c-TiO2)/TiO2-Poly(TA)/ CH3NH3PbI3/Spiro-OMeTAD/Au</td>
<td>17.4</td>
<td>a) Died after 180 mins b) a) Died after 400 h c) n/a</td>
<td>20.4</td>
<td>a) under UV irradiation time (35.8 mW cm⁻²). b) air (50 ± 10 RH%), light/dark-n/a, temp-n/a, c)mppt-yes, inert.1.5 AMG</td>
<td>a)</td>
<td>88</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Compound</td>
<td>FTO/ TiO2/CH3NH3PbI3 /Spiro-OMeTAD /Ag</td>
<td>Initial TPA precursors</td>
<td>Initial PbI2 precursor solution</td>
<td>a) Unencapsulated, air, RH= 35%, 25°C, ambient, dark. b) 60°C. c) 365 nm UV illumination with an intensity of 250 mW cm–2 (equivalent to 56 suns equivalent of UV light below 400 nm in wavelength).</td>
<td>a) Retained 94% PCE from initial PCE after 21 days. b) 10.7 % PCE as of final PCE after 700 h. c) Retained 77% PCE from initial PCE after 40 mins.</td>
<td>a) Retained 94% PCE from initial PCE after 21 days. b) 10.7 % PCE as of final PCE after 700 h. c) Retained 77% PCE from initial PCE after 40 mins.</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>--------------------------------</td>
<td>----------------------------------------</td>
<td>------------------------</td>
<td>---------------------------------</td>
<td>-------------------------------------------------------------------------------</td>
<td>---------------------------------------------------------------------------------------------------------------------------------</td>
<td>----------------------------------------------------------------------------------------------------------------------------------</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>terephthalic acid (TPA)</td>
<td>FTO/compact-TiO2/CH3NH3PbI3 /Carbon layer</td>
<td>11.5 ±0.67</td>
<td>8 mg/mL</td>
<td>14. 29 ± 0.8 mg/mL</td>
<td>a) Retained 81% PCE from initial PCE after 21 days. b) ~6% PCE as of final PCE after 700 h. c) Retained 79% PCE from initial PCE after 40 mins.</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>trimesic acid (TMA)</td>
<td>FTO/TiO2/CH3NH3PbI3 /Spiro-OMeTAD /Ag</td>
<td>14.27</td>
<td>1.0 mol L−1 PbI2 precursor solution</td>
<td>17.21</td>
<td>a) Retained 49% PCE from initial PCE after 10h. b) Retained 46% from initial PCE after 20 days.</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>3,3’,5,5’-azobenzene-tetracarboxylic acid (H(4)abc)</td>
<td>FTO/TiO2/CH3NH3PbI3 /Spiro/Au</td>
<td>14.25</td>
<td>2.0% (mass ratio with respect to PbI2)</td>
<td>17.67</td>
<td>a) Remained nd 25% after 20h. b) Retained 66% of its initial PCE after 30 d.</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>4-methylbenzene sulfonic acid (4-MSA)</td>
<td>FTO/bi-TiO2/mp-TiO2/CH3NH3PbI3 /Spiro-OMeTAD/Au.</td>
<td>14.05</td>
<td>N/A</td>
<td>17.58</td>
<td>N/A</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>N/A</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

---

The strong hydrogen bond between the hydroxyl group and iodide to suppress the loss of iodide ion, preventing the perovskite from decomposing. Moreover, the benzene ring with rigidity and the π–π bond effect, and the hydrophobic alkyl chains further protects the perovskite from reacting with water. High-quality perovskite films, H4abc can passivate grain boundaries by reacting with the lead cation, therefore leading to good thermal stability and anti-moisture of perovskite films due to rigidity of the benzene ring and azo bond. Improved performance, reduced hysteresis, improve J-V characteristics, the sulfonic group is chemically bonded to mp-TiO2 and phenyl backbone has p-conjugated structure. Jsc and Voc of 4-MSA doped PSC are enhanced.
In a similar fashion, the acetates in the form of additives also show improvement in crystallinity and grain size, passivating the grain boundaries. One of the examples is formamidine acetate salt (FAAc). It was reported that FAAc controls the film morphology and improved fill-factor over 80%, improving PCE to 16.59%. The improved photovoltaic parameter was further associated with incorporating FAAc that eliminated the defect and trap density in the MAPbI₃ film and thus improved the charge transport efficiency and reduced the hysteresis. On the contrary, methyl ammonium acetate (MAAc) resulted in lower crystallinity and a smaller grain size ~200 nm. However, it was suggested to use MAAc together with thiourea (TSC) salt in the precursor to overcome lower crystallinity. This combination of additives (10–15% MAAc (molar ratio) and a tiny amount of TSC (3–5% molar ratio)) gave a certified PCE of 19.19% for an aperture area of 1.025 cm², and the high-performing devices were able to sustain over 80% of the initial PCE after 500 h of thermal ageing at 85°C. Besides, acetate additives were also reported to be used as complementary to halogens. For instance, ammonium acetate (NH₄Ac) was found to produce full film coverage with higher crystallinity. It was speculated that NH₄Ac resulted in the formation of methylamine acetate salt by forming NH₄PbI₃ as an intermediate phase with a volatile by-product NH₃ resulting in a higher nucleation density of grains and full coverage of the surface. This, in turn, resulted in higher efficiency of 13.9% in carbon-based solar cells (FTO/TiO₂/perovskite/Carbon) and 17.02% in the two-step spin coating in FTO/TiO₂/CH₃NH₃PbI₃/spiro-OMeTAD/Au configuration. Further, the influence of NH₄Ac addition was compared with NaAc and ZnAc₂. The incorporation of sodium acetate (NaAc) into MAPbI₃ precursor reported no improvement in photovoltaic performance. However, the PCEs were comparable. While compared to Zinc-acetate (ZnAc₂) additive, devices with ZnAc₂ demonstrated improved fill factor and short circuit current density over reference cells, resulting in improved PCE from 11.1% to 12.30%. Furthermore, against the speculation that Zn²⁺ might partially replace Pb²⁺ due to the smaller ionic radius, the small quantity of ZnAc₂ (MAI/PbI₂/ZnAc₂ (1:1-x:x, x= 7%) was reported to assimilate well within MAPbI₃ framework and maintained ~89% of initial PCE after 1900 h when stored in Rh=40%, dark. However, NH₄Ac incorporated devices exhibited ~96% PCE of the initial stage after 1900 h with the same conditions. Later on, lead acetate (PbAc₂) has been employed as an additive and demonstrated an excellent PCE improvement from 17.25%
to 19.07%. It was further demonstrated that incorporation of PbAc\textsubscript{2} in precursor creates an intermediate phase by forming hydrogen bonding due to interaction with MA\textsuperscript{+} and O from acetate. Thus, this hydrogen bonding acts as a crossing linking agent for the intermediate phase, which later causes to improve intrinsic stability of devices that maintained almost 95% of initial PCE till 20 days\textsuperscript{100}. A similar mechanism was utilized in another study where the addition of barium acetate (BaAc\textsubscript{2}) has been explored in MAPbI\textsubscript{3} perovskite with a lower concentration of (0-2mg /mL), which suppressed ion migration and improved thermal stability. The devices could sustain ~90% PCE of the initial stage after exposure to thermal stress at 90°C in the dark in inert conditions without any encapsulation up to 400 h\textsuperscript{101}. Thus, by employing acetate-based additives, improved stability can be obtained both in ambient and inert conditions. Further, the acetate-based additives are summarized in Table 4, as shown below.
<table>
<thead>
<tr>
<th>Additive in active layer</th>
<th>architecture</th>
<th>PCE, % (Pristine)</th>
<th>Stability (Pristine)</th>
<th>amount of additive</th>
<th>Stability with additive</th>
<th>Stability conditions</th>
<th>Role of additive</th>
<th>Ref</th>
</tr>
</thead>
<tbody>
<tr>
<td>Formamidine acetate salt (FAAc)</td>
<td>ITO/PEDOT:PSS/CH₃NH₃PbI₃/PCBM/Al</td>
<td>12.13</td>
<td>(a)n/a</td>
<td>16.59</td>
<td>5 mol%</td>
<td>(a) Retained 90 % PCE from initial after 30 days (b)16.10 as of final PCE after 320 s @ (0.87 V)</td>
<td>inert, un-encapsulated, control film morphology and crystallinity, improves optical and electrical properties reduces hysteresis</td>
<td>95</td>
</tr>
<tr>
<td>Methylammonium acetate (MAAc) and thiosemicarbazide (TSC), combined</td>
<td>FTO/NiO/CH₃NH₃PbI₃/PCBM/Ag</td>
<td>N/A</td>
<td>N/A</td>
<td>19.19</td>
<td>10–15% MAAc (molar ratio) 3–5% TSC (molar ratio)</td>
<td>a) Retained 90% PCE from initial after 1000 h b) Retained 80% PCE from initial after 500 h</td>
<td>a) AM 1.5 light soaking (short-circuit, temperature of ≈25 °C and RH &lt; 25%), b)dark, 85°C, RH &lt; 25%</td>
<td>large-area (aperture area of 1.025 cm² using one step solution process, high crystalline quality of film</td>
</tr>
<tr>
<td>Ammonium acetate (NH₄Ac,)</td>
<td>FTO/TiO₂/CH₃NH₃PbI₃/spiro-OMeTAD/Au</td>
<td>13.82</td>
<td>N/A</td>
<td>17.02</td>
<td>10 wt%</td>
<td>N/A</td>
<td>N/A</td>
<td>Improved film morphology and increased surface coverage</td>
</tr>
<tr>
<td>Ammonium acetate CH₃COONH₄ (NH₄Ac)</td>
<td>FTO/TiO₂/CH₃NH₃PbI₃/carbon devices</td>
<td>11.11</td>
<td>Remained 60% from initial PCE after 1900h</td>
<td>13.9</td>
<td>MAI/PbI₂/NH₄Ac (1:1:x=0.08%)</td>
<td>Remained 96% from initial PCE after 1900h</td>
<td>Dark, RH=40%, Carbon electrode-based device, improved crystallinity</td>
<td>Carbon electrode-based device, improved crystallinity</td>
</tr>
<tr>
<td>Zn(CH₃COO)₂ (ZnAc₂)</td>
<td>FTO/TiO₂/CH₃NH₃PbI₃/PCBM/Ag</td>
<td>12.30</td>
<td>MAI/PbI₂/ZnAc₂ (1:1-x:x= 7%,)</td>
<td>12.30</td>
<td>MAI/PbI₂/ZnAc₂ (1:1-x:x= 7%,)</td>
<td>Remained 89% from initial PCE after 1900h</td>
<td>Dark, RH=40%, Carbon electrode-based device, improved crystallinity</td>
<td>Carbon electrode-based device, improved crystallinity</td>
</tr>
<tr>
<td>Lead acetate (PbAc₂)</td>
<td>Glass/ITO/PTAA/CH₃NH₃PbI₃/PCBM/BCP/Ag</td>
<td>17.25</td>
<td>Retained 80% PCE from initial after 20 days</td>
<td>19.07</td>
<td>3% PbAc₂ (molar ratio with respect to PbI₂)</td>
<td>Retained 95% PCE from initial after 20 days</td>
<td>un-encapsulated, inert. PbAc₂ additive aids cross-linking to form a strong hydrogen bond with MAI, leading to a more stable perovskite intermediate phase, retards crystallization process, resulting, perovskite thin films with better morphology and larger grains</td>
<td>PbAc2 additive aids cross-linking to form a strong hydrogen bond with MAI, leading to a more stable perovskite intermediate phase, retards crystallization process, resulting, perovskite thin films with better morphology and larger grains</td>
</tr>
<tr>
<td>barium acetate (BaAc₂)</td>
<td>ITO/P3CTN/CH₃NH₃PbI₃/PC₆₀BM/C₆₀/BCP/Ag</td>
<td>18.99</td>
<td>Retained only 20% from initial PCE after 400 h</td>
<td>19.82</td>
<td>2 mg/mL</td>
<td>Retained 90% from initial PCE after 400 hours</td>
<td>Non-encapsulated, inert, 90 °C, dark, suppression of ions migration, high quality perovskite film, grain boundary passivation</td>
<td>101</td>
</tr>
</tbody>
</table>

| Retained 90% from initial PCE after 400 hours | 2 mg/mL | Retained only 20% from initial PCE after 400 h | 18.99 | barium acetate (BaAc₂) | ITO/P3CTN/CH₃NH₃PbI₃/PC₆₀BM/C₆₀/BCP/Ag | 18.99 | Retained only 20% from initial PCE after 400 h | 19.82 | 2 mg/mL | Retained 90% from initial PCE after 400 hours | Non-encapsulated, inert, 90 °C, dark, suppression of ions migration, high quality perovskite film, grain boundary passivation | 101 |
2.1.2.5 Ester and ether based additives

Interestingly, phenyl-C61-butyric acid methyl ester (PCBM), which is commonly employed as a charge transport layer in organic-inorganic hybrid solar cells, has also been examined as an additive in the perovskite layer to achieve hole transport material (HTM) free fully printable MPSC (mesoporous perovskite solar cell). It was shown that when the concentration of PCBM increased in the active layer from 0 to 0.25 mg/mL, the PCE significantly improved from 8.58% to 12.36%, achieving a PCE enhancement of more than 44%. This enhancement of PCE was further ascribed to increased $J_{sc}$ from 14.56 mA cm$^{-2}$ to 20.26 mA cm$^{-2}$ due to higher photo-generated charge separation and suppressed the charge recombination process. Later, it was illustrated that the PCBM-perovskite intermediate phase is facilitated due to the formation of an intermediate adduct with PbI$_2$ and carbonyl groups in PCBM. Afterwards, Hu et al. compared PCBM incorporation with only C$_{60}$ unit and C$_{60}$-Taurine unit in single-step spinning coating method in p-i-n configuration. It was reported that C$_{60}$ (16.59%), PCBM (15.94%), C$_{60}$-Ta (16.59%) all improved PCE over pristine (14.87%), which was consistent with the previously published report. Further, it was found that the addition of C$_{60}$ and its derivatives decrease the trap densities and exhibited higher stability when exposed to ambient conditions RH=25-50% without encapsulation.

Likewise, investigations have shown that ethers can help passivate grain boundaries on the perovskite surface boundary. Poly (propylene glycol) bis (2-aminopropyl ether) (PEA) and Jeffamine are some of the examples that showed interaction with Pb ions due to lone pair of electron on the oxygen-containing ether part of the additives. Simultaneously, the MA$^+$ cation from perovskite forms hydrogen bonding with the counter ion of additive. Thus the polymer works as a cross-linking agent that decreases trap densities and hysteresis, improving the device performance and stability. To add on, the cross-linking properties can also improve the ductility of perovskite film while stretching when fabricated on a flexible substrate (such as D2000, Jeffamine variation). Furthermore, using the mechanism above, ethyl cellulose (EC), a low cost, environmentally friendly, thermally stable and water-insoluble compound, also demonstrated chemical passivation of defect traps. Thus, because of the passivation effect of EC additive, the MAPbI$_3$ crystal structure remained stable against moisture and air, maintaining 80% of PCE when exposed un-encapsulated to ambient air at RH=45% in the dark for 30 days. Later on, tetraorthosilicate (TEOS) additive in MAPbI$_3$ was also reported to
lower the cost of processing by making the fabrication process feasible in the air instead of the glove box, which was found to be valid both for single and double step. This achievement was due to the fact that when TEOS is introduced to MAPbI$_3$ in air, SiO$_2$ precipitates at the surface, acting as a passivation for the perovskite surface and shielding it from moisture and air. This improved the overall stability in ambient conditions$^{107-109}$. Further, cyclic ether compound THF (Tetrahydrofuran) also reported improving stability in ambient air, which the pioneer of PSCs Miyasaka group investigated. The study demonstrated that THF and PbI$_2$ in DMF interact and form complex, resulting in dense, homogenous and pinhole-free film due to complex formation between Pb and O donor from THF because of the Lewis acid nature of Pb and Lewis basicity of THF. This, in turn, avoids a direct interaction of PbI$_2$ with water, improving T80 (T80 is the time after which PSC remain 80% of initial efficiency) for 20 days in the ambient environment with 50% RH when devices were exposed un-encapsulated$^{110}$. Further, a table describing ester and ether containing additives and their role in the MAPbI$_3$ layer is presented in Table 5.
### Table 5: Ester and Ether based additives for MAPbI₃ and their role.

<table>
<thead>
<tr>
<th>Additive in active layer</th>
<th>architecture</th>
<th>PCE, % (Pristine)</th>
<th>Stability (Pristine)</th>
<th>PCE, % (with additive)</th>
<th>amount of additive</th>
<th>Stability with additive</th>
<th>Stability conditions</th>
<th>Role of additive</th>
</tr>
</thead>
<tbody>
<tr>
<td>(6,6)-phenyl-C₆₁-butyric acid methyl ester</td>
<td>FTO/ TiO₂/m- TiO₂/mZrO₂/ CH₃NH₃PbI₃/m-carbon</td>
<td>8.58</td>
<td>N/A</td>
<td>12.36</td>
<td>0.25 mg mL⁻¹</td>
<td>N/A</td>
<td>N/A</td>
<td>Improved morphology, intermediate formation between C=O of PCBM and PbI₂</td>
</tr>
<tr>
<td>PCBM</td>
<td>Glass/ITO/ CH₃NH₃PbI₃/PCBM/BPhen/Ag</td>
<td>13.94</td>
<td>Retained ~9% (absolute value) as of final PCE after 10 days</td>
<td>15.94</td>
<td>3.5 mg/mL</td>
<td>Retained ~12% (absolute value) as of final PCE after 10 days</td>
<td>without encapsulation, ambient RH= 25-50%</td>
<td>Improves crystallinity, passivates defects, suppress non radiative recombination</td>
</tr>
<tr>
<td>C₆₀-Ta</td>
<td></td>
<td>16.46</td>
<td>1.5 mg/mL</td>
<td>Retained ~12% (absolute value) as of final PCE after 10 days</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>C₆₀</td>
<td></td>
<td>16.59</td>
<td>0.1 mg/mL</td>
<td>Retained ~11% (absolute value) as of final PCE after 10 days</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Poly(propylene glycol) bis(2-amino propyl ether) (PEA)</td>
<td>FTO/c-TiO₂/mp-TiO₂/ CH₃NH₂PbI₃/Spiro/Au</td>
<td>17.18</td>
<td>Maintains ~55% of its original PCE after 30 days</td>
<td>18.87</td>
<td>1 wt%</td>
<td>Maintains 95% of its original PCE after 30 days</td>
<td>Dark, ambient air with 30±5% relative humidity,</td>
<td>Grain boundary passivation, the oxygen atom from ether in PEA, acts as a crosslinking agent, reduces trap density and hysteresis</td>
</tr>
<tr>
<td>Jeffamine</td>
<td>ITO/NiO₂/CH₃NH₂PbI₃/PCBM/BCP/Ag</td>
<td>14.5</td>
<td>Showed major cracks</td>
<td>16.8</td>
<td>0.05 wt%</td>
<td>Retained original morphology</td>
<td>10 cycles of stretching at 30% strain</td>
<td>Defect passivation through lewis acid-base reaction of N atom and O atom with Pb²⁺ / or interaction of MA⁺ and hydrogen bond of jeffamine decrease trap density, enhances the ductility of the perovskite film to prevent cracking during stretching</td>
</tr>
<tr>
<td>ethyl cellulose (EC)</td>
<td>FTO/c-TiO₂/ CH₃NH₂PbI₃/Spiro-OMeTAD/ MoO₃/Ag</td>
<td>17.11</td>
<td>Completely died in 30 days</td>
<td>19.27</td>
<td>0.1 mg/mL</td>
<td>Retained 80% PCE from initial after 30 days</td>
<td>Non encapsulated, dark, Ambient, air, RH=45%</td>
<td>Hydrogen bonding between EC and MAI passivates defects at the grain boundary, reduces hysteresis and improves stability</td>
</tr>
<tr>
<td>Material</td>
<td>Layer Configuration</td>
<td>ורה</td>
<td>Retention of PCE after 28 days</td>
<td>Additional Information</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>--------------------------</td>
<td>----------------------------------------------</td>
<td>-----</td>
<td>-------------------------------</td>
<td>----------------------------------------------------------------------------------------</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Tetraethyl orthosilicate (TEOS)</td>
<td>TiO$_2$/CH$_3$NH$_3$PbI$_3$/Spiro-OMeTAD/Ag</td>
<td>15.96</td>
<td>Retained 73% of its initial PCE after 28 days</td>
<td>18.38</td>
<td>0.3 mol% Retained 77% of its initial PCE after 28 days</td>
<td>Ambient, 25°C, RH=30%, non-encapsulated. Reduce trap density, improves carrier lifetime</td>
<td></td>
<td></td>
</tr>
<tr>
<td>THF</td>
<td>FTO/TiO$_2$/CH$_3$NH$_3$PbI$_3$/Spiro-OMeTAD/Au</td>
<td>11.3</td>
<td>Retained 35% PCE from initial after 20 days</td>
<td>15.1</td>
<td>THF: DMF(1:10) v/v Retained 80% from initial PCE after 20 days</td>
<td>RH 50%, un-encapsulated, Complex formation due to lewis acid-base reaction</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Diethyl ether</td>
<td>Glass/ITO/NiO$_x$/CH$_3$NH$_3$PbI$_3$/PCBM/BCP/Ag</td>
<td>13.28</td>
<td>N/A</td>
<td>15.09</td>
<td>the molar ratio of 4% with matrix solvent</td>
<td>N/A N/A Grain size improvement</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

107, 109, 111
2.1.2.6 Hydroxyl/alcohol

The Hydroxyl group can also play a vital part in interacting with perovskite through hydrogen bonding, further improving crystallinity and performance. For example, enhanced PCE and stability was observed when dibutyl hydroxyl toluene (BHT) additive containing a phenol group was mixed in MAPbI$_3$ precursor $^{112}$. Furthermore, methanol and isopropanol showed larger grain size, reduced grain boundaries, lessened defect density and demonstrated efficient charge carrier extraction at the interfaces leading to improved PCE stability in ambient conditions without encapsulation. Similarly, improvement in PCE was also noticed due to other hydroxyl based additives such as 2-methoxy ethanol (ME), 2-ethoxyethanol (EE), and 2-propoxy ethanol (PE) and n butanol $^{113-115}$. A summary of alcohol-based additives and their influence on the PCE and role with the perovskite framework is described in Table 6.
<table>
<thead>
<tr>
<th>Additive in active layer</th>
<th>architecture</th>
<th>PCE, % (Pristine)</th>
<th>Stability (Pristine)</th>
<th>PCE, % (with additive)</th>
<th>Stability with additive</th>
<th>Stability conditions</th>
<th>Role of additive</th>
<th>Ref</th>
</tr>
</thead>
<tbody>
<tr>
<td>dibutylhydroxytoluene (BHT)</td>
<td>ITO/ PEDOT: PSS/ CH$_3$NH$_3$PbI$_3$/ PC$_6$BM/ZnO/Al</td>
<td>17.1</td>
<td>Retained 85% from initial PCE after 180 min</td>
<td>18.1</td>
<td>0.02 M</td>
<td>Retained 93% of initial PCE after 180 min</td>
<td>100 mW cm$^{-2}$, RT, non-encapsulated, RH&lt;5%</td>
<td>intermolecular hydrogen bonds between the MA$^+$ and –OH groups of the BHT</td>
</tr>
<tr>
<td>methanol</td>
<td>FTO/TiO$_2$/ CH$_3$NH$_3$PbI$_3$/ Spiro-OMeTAD/Au</td>
<td>16.53</td>
<td>Retained 40% from initial PCE after 30 days</td>
<td>19.51</td>
<td>5 vol%</td>
<td>Retained 90% from initial PCE after 30 days</td>
<td>Dark, ambient, nonencapsulated, morphology control/enhancement</td>
<td>113</td>
</tr>
<tr>
<td>2-methoxyethanol ME</td>
<td>ITO/ZnO/ CH$_3$NH$_3$PbI$_3$/ Spiro-OMeTAD/MoO$_x$/Ag</td>
<td>14.2</td>
<td>N/A</td>
<td>16.7</td>
<td>30µl to 1 ml MAI solution</td>
<td>N/A</td>
<td>N/A</td>
<td>two-step interdiffusion protocol to prepare pin-hole free perovskite films, glycol ethers changes the lead iodide to perovskite conversion dynamics and enhances PCE resulting in more compact polycrystalline films, and it creates micrometer-sized perovskite crystals vertically-aligned across the photoactive layer</td>
</tr>
<tr>
<td>2-ethoxyethanol (EE), 2-propanoyl ethanol (PE)</td>
<td>FTO/compact-TiO$_2$/ CH$_3$NH$_3$PbI$_3$/ Spiro-OMeTAD/Au</td>
<td>16.02</td>
<td>Retained 40% PCE from initial after 40 days</td>
<td>19.70</td>
<td>precursor: IPA volume ratio = 4:1</td>
<td>Retained 85% PCE from initial after 40 days</td>
<td>un-encapsulated, air, ambient , RT, dark/light-n/a, mppt-n/a, uv-filter-n/a, morphology enhancement/control</td>
<td>114</td>
</tr>
<tr>
<td>n-butanol</td>
<td>FTO/CT-IO2/mp-TiO2/CH3NH3PbI2/Spiro-OMeTAD/Ag</td>
<td>13.8</td>
<td>N/A</td>
<td>15.5</td>
<td>5.0 v% for 1 ml precursor</td>
<td>N/A</td>
<td>N/A</td>
<td>morphology enhancement</td>
</tr>
<tr>
<td>------------</td>
<td>-----------------------------------------------</td>
<td>------</td>
<td>-------</td>
<td>------</td>
<td>----------------------------</td>
<td>-----</td>
<td>-----</td>
<td>-------------------------</td>
</tr>
</tbody>
</table>
2.1.2.7 Oxygen based multifunctional group containing additives

Other than these additives, other oxygen atom-based additives with multiple functional groups consisting of C=O, COOH and OH are also employed in the MAPbI₃ precursor. One example is reduced graphene oxide (rGO), which was used to achieve fast electron transport rates toward the anode, including the growth of large, uniform, smooth and crystalline perovskite film, resulting in a massive improvement in device performance from 13.6% to 20% ⁱ¹⁷. Another example includes Poly (amic acid) (PAA) and polyimide (PI) additive. However, the PAA and PI additives also consisted of N atom, other than C=O, COOH and OH functional group. The O atoms in PAA and PI form hydrogen bonds with H atoms in CH₃NH₃⁺. The lone pair of electrons of N atoms interact with Pb ions, which stabilized the PVSK framework. Furthermore, these interactions improved the optoelectronic properties of the perovskite layer. As a result, an increment in the grain size was observed when 0.0497 mg/mL PAA-derived perovskite was employed, illustrating the Lewis acid–base interaction between C=O and Pb²⁺ that controls the crystallization process and defects passivation of PVSK. Besides, both PAA and PI are hydrophobic and highly heat-resistant polymers and further contribute to the stability of PSC when operated in a humid and high-temperature environment ⁱ¹⁸. Table 7 presents the details of these additives.

An overall comparison of stabilizing effect of additives of different functional groups associated with O donor atom has been shown in Figure A0.2, Appendix 0.
<table>
<thead>
<tr>
<th>Additive in active layer</th>
<th>architecture</th>
<th>PCE, % (Pristine)</th>
<th>Stability (Pristine)</th>
<th>PCE, % (with additive)</th>
<th>amount of additive</th>
<th>Stability with additive</th>
<th>Stability conditions</th>
<th>Role of additive</th>
<th>Ref</th>
</tr>
</thead>
<tbody>
<tr>
<td>Reduced graphene oxide (rGO)</td>
<td>FTO/TiO$_2$/CH$_3$NH$_3$PbI$_3$/Spiro/Ag</td>
<td>13.8</td>
<td>retained 20% of their initial PCE after 50 days</td>
<td>16.5</td>
<td>9 μg mL$^{-1}$</td>
<td>retained 40% of their initial PCE after 50 days</td>
<td>dark, RH=10%, un-encapsulated,</td>
<td>defect-free perovskite films of enhanced crystallinity, larger and evenly distributed grains, enhanced light harvesting potential, increasing the photocurrent density and the resulting improved PCE</td>
<td>117</td>
</tr>
<tr>
<td>Poly(amic acid) (PAA)</td>
<td>ITO/NiO$_x$/CH$_3$NH$_3$PbI$_3$/PC$_61$BM/BCP/Ag</td>
<td>14.16</td>
<td>(a)Remained 13% as of final PCE after 500 h (b) Retained 50% from initial PCE after 70h</td>
<td>17.85</td>
<td>0.0497 mg/ml</td>
<td>(a)Remained 16.57% as of final PCE after 500 h (b) Retained 88% from initial PCE after 70h</td>
<td>Inert, dark, non-encapsulated, (b) 85°C, RH=45% without encapsulation, dark, in the glovebox</td>
<td>The O atoms in PAA and PI form hydrogen bonds with H atoms in CH$_3$NH$_3^+$ and lone pair of electrons of N atoms interact with Pb ions, which stabilized the PVSK framework. Furthermore, these interactions improve the optoelectronic properties of the perovskites resulting in improved PCE</td>
<td>118</td>
</tr>
<tr>
<td>polyimide (PI)</td>
<td></td>
<td>16.49</td>
<td></td>
<td>16.49</td>
<td>0.0990 mg/ml</td>
<td>N/A</td>
<td>N/A</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

Table 7 Other oxygen atom-based additives with multifunctional group.57
2.1.3 S donor atom-based additives

2.1.3.1 Sulphide and organosulphur additives

Further, sulphur-based donor atoms have also improved crystallinity and device performance. For instance, Yang and co-workers used dimethyl sulphide (DS) additive in MAPbI₃ precursor solution (based on DMSO precursor) and demonstrated a record high PCE of~ 18.4% for a flexible perovskite solar cell. Also, the formation of a stable intermediate complex between PbI₂ and DS molecule was observed that further enhanced stability. The enhancement of stability due to DS solvent additive was ascribed to the smaller electronegativity of the sulphur atom (2.5) in DS molecule compared to an oxygen atom (3.5) in DMSO molecule, which allowed sulphur molecules to provide electronins to empty 5d Pb orbitals, ultimately resulting in a hexa-coordinated complex formation. Therefore, with better crystallization and stable intermediate formation, 86% of initial PCE remained for 60 days when un-encapsulated devices were exposed to moisture RH~35% in the dark at room temperature. Thiourea is another example of such an organosulphur compound, the addition of which into the photo-active layer results in improved performance and stability due to intermediate formation because of Lewis acid-base reaction. However, the addition of thiourea in the active layer is often compared to similar compound urea where O atom from carbonyl group (in urea) is replaced with S atom for thiourea. (the carbon atom is connected to different species). Both thiourea and urea have been found to show similar effects of increasing grain size, crystallinity, grain boundary passivation and coordination with PbI₂ in the MAPbI₃ framework. Besides, many other organosulphur derivatives have been reported to form an adduct with PbI₂ as the Pb atom acts as Lewis acid. One such example is a volatile Lewis base, thioacetamide (CH₃CSNH₂), abbreviated as TAA. Another example is 2-pyridylthiourea, which has a S donor from thiourea, with a better ability to coordinate with PbI₂, and N donor from pyridine, which can co-ordinate with PbI₂ as a Lewis acid-base and regulate the co-ordination strength with PbI₂. This, further results in an improvement in crystallinity, which in turn resulted in better light-harvesting ability, charge transport, the reduction of defect and recombination loss leading to PCE of 18.2%. In addition, this allowed retaining the stability of PSC more than 90% when exposed to ambient conditions, at room temperature or at higher temperature in the dark. Recently, Zhang and his co-worker combined thiourea with water and Iodine (ITU) ions to reduce iodine defect vacancy produced during the film fabrication process. Afterwards,
the grain size was found to be increased with ITU (3.4 um) compared to when thiourea is added (800- 2000 nm), reducing the defects at grain boundaries. Besides, PSCs with ITU additives displayed a higher \( V_{\text{oc}} \), longer decay time and longer carrier lifetime with a lower charge recombination rate. Thus overall, the addition of ITU resulted in improvement in PCE from 17.75% to 20.3%. In addition, the trap densities of the perovskite film significantly reduced as the ITU additive was incorporated into PSC, allowing PSC to stabilize and maintain \( \sim 80 \) of initial PCE after 100 h of exposure to 1.5AMG solar irradiation and 30 days in the ambient atmosphere \cite{122}.

2.1.3.2 Thiocyanates

Above and beyond, thiocyanates (SCN\(^-\) containing anions) additives are another subcategory for S atom-based additives. It should be noted here that thiocyanates are also considered pseudo halides. However, the role of thiocyanates in the perovskite film is very controversial. For example, Yanfa Yan and group demonstrated that a small amount (5%) of Pb(SCN)\(_2\) addition in the precursor can significantly increase the grain size and crystalline quality of perovskite thin films using a one-step solution process method. This increased the average PCE from 15.57 to 17.80%. It was proposed that SCN\(^-\) anions do not incorporate in the perovskite film. SCN\(^-\) react with CH\(_3\)NH\(_3^+\) and form volatile products HSCN and CH\(_3\)NH\(_2\). This allows excess Pb\(^{2+}\) and I\(^-\) to form PbI\(_2\) at grain boundaries that sources passivation effect \cite{123}. On the contrary, Kim et al. demonstrated that Pb(SCN)\(_2\) in CH\(_3\)NH\(_3\)PbI\(_3\) partially substitute I anions and forms CH\(_3\)NH\(_3\)Pb(SCN)\(_x\)I\(_{3-x}\) at lower temperatures. This phenomenon was observed not dependent on the concentration of Pb(SCN)\(_2\). However, similar reports of enhancement of crystal size were found. Thus, it was concluded that the influence of processing temperature could affect the purity of the final perovskite film when Pb(SCN)\(_2\) additive is used with MAPbI\(_3\) \cite{124}. Whereas, the addition of potassium thiocyanate (KSCN) also reported to form volatile products HSCN and CH\(_3\)NH\(_2\), consistent with earlier mentioned results, with no traces of SCN\(^-\) found in the final perovskite film \cite{123}. In the case of the KSCN additive, however, the residue was KI instead of PbI\(_2\). Nevertheless, the authors illustrated that the final product upon KSCN incorporation was MAPbI\(_3\), not KPbI\(_3\), due to the smaller radius of K cation. In addition, KI residue improves the crystal quality of perovskite film, resulting in enhancement of charge transport, reduced carrier recombination and eliminating hysteresis \cite{125}. 

71
Conversely, when NH$_4$SCN is incorporated in MAPbI$_3$, it was reported to form an unstable intermediate phase NH$_4$PbI$_{3-x}$SCN$_x$ due to lower formation enthalpy ($\Delta$Hf) of the NH$_4$PbI$_3$ over MAPbI$_3$, which later resulted in CH$_3$NH$_3$PbI$_{3-x}$SCN$_x$ a mixed halide perovskite after annealing of the films $^{126}$. Therefore, when methylammonium thiocyanate (MASCN) was introduced as an additive to the precursor, a rapid vacuum-based drying approach was used to extract volatile intermediate product. So that, MAPbI$_3$ is formed as the final product with no traces of SCN$^-$. The films fabricated using this fabrication technique was reported to gain grain size of more than one micrometres with uniform surface morphology, resulting in high crystallinity and significantly large carrier lifetimes ($\tau1 = 931.94 \pm 89.43$ ns; $\tau2 = 320.41 \pm 43.69$ ns), Improving the ambient stability up to 1000 h $^{127}$. However, when a larger cation Guadinium (Gu), is directly added in MAPbI$_3$ as GuSCN, GuPbI$_3$ was formed as an intermediate phase present with MAPbI$_3$ phase. It was contradictory to the earlier belief and reports, which showed that Gu single-handedly could not form three dimensional perovskite materials due to a larger ionic size (278 pm) over MA cation (217 pm). As a result, improved crystallinity, grain size and reduced trap density were noticed further, resulting in improved PCE (from 15.57% to 16.70%) that maintained stability ~90 % of the initial value after being stored for 15 days without encapsulation $^{128}$. On the other hand, when guanidinium isothiocyanate is added in PbI$_2$ precursor, with dual step fabrication method; mixed cation perovskite was formed (GU)$_x$(MA)$_{1-x}$PbI$_3$ $^{129}$. Nevertheless, most S donor atom-based additives are found to influence ambient stability. See Figure A0.3, Appendix 0. At a glance summary of additives containing S atom and their role in the MAPbI$_3$ framework has been presented in Table 8.
<table>
<thead>
<tr>
<th>Additive in active layer</th>
<th>architecture</th>
<th>PCE, % (Pristine)</th>
<th>Stability (Pristine)</th>
<th>PCE, % (with additive)</th>
<th>Stability with additive</th>
<th>Stability conditions</th>
<th>Stability conditions</th>
<th>Role of additive</th>
<th>Ref</th>
</tr>
</thead>
<tbody>
<tr>
<td>DS</td>
<td>MgF₂/PET/ITO/Nb₂O₅/CH₃NH₃PbI₃/Spiro-OMeTAD /Au</td>
<td>17.03</td>
<td>(a) Retained 50% PCE from initial after 60 days (b) n/a</td>
<td>18.40</td>
<td>(a) Retained 86% PCE from initial after 60 days (b) 15.24 (83% of initial) as of final PCE after 5000 cycles</td>
<td>(a) Un-encapsulated, RH=35%, dark, RT (b) bending stability- bending radius of 4 mm</td>
<td>Intermediate between Pb²⁺ and S atom</td>
<td>119</td>
<td></td>
</tr>
<tr>
<td>Thiourea</td>
<td>ITO/ PEDOT:PSS/CH₃NH₃PbI₃/PCBM/Ag</td>
<td>13.4</td>
<td>N/A</td>
<td>16.2</td>
<td>0.5 vol%</td>
<td>N/A</td>
<td>N/A</td>
<td>Urea and thiourea both promote grain growth, reduce trap states, passivate grain boundaries.</td>
<td>120</td>
</tr>
<tr>
<td>Thioacetamide (TAA),</td>
<td>ITO/SnO₂/CH₃NH₃PbI₃/Spiro-OMeTAD/Au</td>
<td>17</td>
<td>retains ~75.1% of its initial performance after aging 816 h</td>
<td>18.9</td>
<td>1.0% (molar ratio to PbI₂)</td>
<td>retains 88.9% of its initial performance after aging 816 h</td>
<td>RH=25-35%, unsealed, air,</td>
<td>Interaction of of TAA with Pb²⁺, improved grain size</td>
<td>121</td>
</tr>
<tr>
<td>2-pyridylthiourea</td>
<td>FTO/C-TiO₂/mp-TiO₂/CH₃NH₃PbI₃/Spiro-OMeTAD Spiro/Au</td>
<td>15.5</td>
<td>a) Retained only <del>10% PCE from initial after 30 days b) Retained</del>55% PCE from initial after 30 days</td>
<td>18.2</td>
<td>0.5 mg mL⁻¹</td>
<td>a) Retained<del>95% PCE from initial after 30 days b) Retained</del>92% PCE from initial after 30 days</td>
<td>ambient, air, dark a) RH=55±5%, dark, RT b) 65 °C, RH=30%, dark,</td>
<td>N-donor and S-donor coordinate with PbI₂ and slow down the formation of PbI₂, improved morphology, larger crystalline size, smooth compact, homogeneous film</td>
<td>60</td>
</tr>
<tr>
<td>ITU for I⁻ and thiourea</td>
<td>ITO/SnO₂/CH₃NH₃PbI₃/Spiro-OMeTAD/Au</td>
<td>17.75</td>
<td>retain 30% of the initial PCE after 100 h</td>
<td>20.3</td>
<td>0.003 mM</td>
<td>retain 80% of the initial PCE after 100 h</td>
<td>AM 1.5 light soaking, in ambient atmosphere</td>
<td>Reduction of iodine ions and reduces defect state concentration, and defect passivation of grain boundaries crystalline quality, improve charge transport,</td>
<td>122</td>
</tr>
<tr>
<td>Additive</td>
<td>Cell Structure</td>
<td>Jsc (mA cm⁻²)</td>
<td>Voc (V)</td>
<td>PCE (%)</td>
<td>Molar Ratio</td>
<td>Retained (%)</td>
<td>Notes</td>
<td></td>
<td></td>
</tr>
<tr>
<td>----------</td>
<td>----------------</td>
<td>---------------</td>
<td>--------</td>
<td>---------</td>
<td>-------------</td>
<td>--------------</td>
<td>-------</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Pb(SCN)₂</td>
<td>FTO/STO/CH₃NH₃PbI₃/Spiro-OMeTAD/Au</td>
<td>15.57</td>
<td>N/A</td>
<td>17.80</td>
<td>N/A</td>
<td>N/A</td>
<td>forms volatile products HSCN and CH₃NH₂, resulting in formation of excess PbI₂ that passivates GB</td>
<td></td>
<td></td>
</tr>
<tr>
<td>K(SCN)₂</td>
<td>FTO/c-TiO₂/m-TiO₂/CH₃NH₃PbI₃/Spiro-OMeTAD/Au</td>
<td>19.38</td>
<td>N/A</td>
<td>19.6</td>
<td>1 mol%</td>
<td>N/A</td>
<td>N/A</td>
<td>Grain size and crystallinity improvement reduced recombination density, rapid vacuum-based drying approach, high crystallinity, large carrier lifetimes</td>
<td></td>
</tr>
<tr>
<td>(MASCN)</td>
<td>Glass/FTO/TiO₂/CH₃NH₃PbI₃/Spiro-OMeTAD/Au</td>
<td>15.81</td>
<td>Died in 150 h.</td>
<td>18.71</td>
<td>40 mol%</td>
<td>Retained 16.34 % as of final PCE after 1000 h ~89.7 % from initial, air, RH= ~20-25%, without encapsulation, rapid vacuum-based drying approach, high crystallinity, large carrier lifetimes</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Gu(SCN)₂</td>
<td>FTO/TiO₂/CH₃NH₃PbI₃/PCBM/Ag</td>
<td>15.57</td>
<td>Retained 60% PCE from initial PCE after 15 days</td>
<td>16.70</td>
<td>10% mmol</td>
<td>Retained 90% PCE from initial PCE after 15 days, Un-encapsulated, dark, RH=30-40%, enhance the crystallinity, enlarge the crystal size, and reduce the trap density of the perovskite film</td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>
2.1.4 Alkane additives

Furthermore, alkane based additives can be another class of additives that has been briefly investigated within the MAPbI$_3$ framework. Additives like poly(vinylidene fluoride-co-hexafluoropropylene) (PVDF-HFP) have shown interaction with MA cation via hydrogen bonding with fluorine atoms in the additive. Such an additive is quite useful for indoor photovoltaic applications as the additive is reported to control the nucleation and growth rate on a very thin (~150 nm) active layer of MAPbI$_3$ through a one-step solution processing method. Thinner light absorber perovskite is usually full of voids and results in low fill factor, lower internal quantum efficiency due to poor perovskite film quality. However, increasing the thickness is not suitable to obtain semi-transparent films. To solve this problem, poly(vinylidene fluoride-co-hexafluoropropylene) (PVDF-HFP) additive had illustrated less rough morphology when ~150 nm thick perovskite layer was obtained. Also, it was found that perovskite solar cells with PVDF-HFP film have a higher charge transfer rate and lower carrier recombination rate. Similar observations were seen when another derivative of PVDF polyvinylidene fluoride-trifluoroethylene polymer P(VDF-TrFE) was employed in a two-step fabrication process instead. Other than these additives, some other haloalkane additives like diiodomethane (CH$_2$I$_2$) and diiodoctane (C$_8$H$_{16}$I$_2$) have also been reported to reduce the trap states resulting in improved morphology and enhanced PCE. Further, Table 9 represents the alkane additives and discuss their role in the MAPbI$_3$ framework.
Table 9 Alkane based additives and their role within MAPbI$_3$ framework.\textsuperscript{57}

<table>
<thead>
<tr>
<th>Additive in active layer</th>
<th>architecture</th>
<th>PCE, % (Pristine)</th>
<th>Stability (Pristine)</th>
<th>PCE, % (with additive)</th>
<th>amount of additive</th>
<th>Stability with additive</th>
<th>Stability conditions</th>
<th>Role of additive</th>
<th>Ref</th>
</tr>
</thead>
<tbody>
<tr>
<td>poly(vinylidene efluoride-co-hexafluoropropylene) (PVDF-HFP)</td>
<td>FTO/cTiO$_2$/CH$_3$NH$_3$PbI$_3$/spiro-MeOTAD/Au</td>
<td>7.2</td>
<td>N/A</td>
<td>10.6</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>Interact with uncoordinated MAI molecule through hydrogen bonds between fluorine atoms. This can improve the carrier lifetimes and reduce the charge transfer resistance, which contributes to enhancing PCE.</td>
<td>131</td>
</tr>
<tr>
<td>polyvinylidene fluoride-trifluoroethylen polymer (P(VDF-TrFE))</td>
<td>FTO/c-TiO$_2$/mesoporous-TiO$_2$/CH$_3$NH$_3$PbI$_3$/spiro-MeOTAD/Ag</td>
<td>9.57±0.2 5%</td>
<td>N/A</td>
<td>12.54±0.40</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>Two-step deposition, improved crystallinity and morphology, reduced carrier recombination of charge carrier, increased carrier lifetime</td>
<td>132</td>
</tr>
<tr>
<td>diiodomethane CH$_2$I$_2$</td>
<td>Glass/FTO/TiO$_2$/MAPbI$_3$/Spiro-OMeTAD /Au</td>
<td>10.0</td>
<td>N/A</td>
<td>16.5</td>
<td>0.25 ml in 1 ml precursor</td>
<td>N/A</td>
<td>N/A</td>
<td>Iodine liberation, morphology enhancement</td>
<td>134</td>
</tr>
<tr>
<td>Diiodooctane DIO</td>
<td>Glass/ITO/PEDOT:PSS/MAPbI$_3$/PCBM/Ag</td>
<td>10.61</td>
<td>N/A</td>
<td>17.74</td>
<td>1 vol% in 1 ml precursor</td>
<td>N/A</td>
<td>N/A</td>
<td>Intermediate formation and morphology enhancement</td>
<td>133</td>
</tr>
</tbody>
</table>
2.1.5 Quantum dot-based additives

Recently, a new area of additive engineering emerged based on quantum dots containing different functional groups introduced in the precursor. This allows the functional group to chelate with under coordinated Pb vacancy or iodine defect sites at the surface of the perovskite layer. At the same time, quantum dot improves the crystallinity of film due to the quantum confinement effect and reduces non-radiative recombination centres, thus passivating defects at grain boundaries\textsuperscript{135–140}. In some cases, quantum dots can even promote charge transfer from the oxide surface to the perovskite layer, further reducing the charge trap density, boosting fill factor as high as 84\% and efficiency as 21.04\%.\textsuperscript{139,141} A summary of such additives based on Quantum dots (QDs) is presented in Table 10.
### Table 10 Quantum dots based additives for MAPbI₃

<table>
<thead>
<tr>
<th>Additive in active layer</th>
<th>architecture</th>
<th>PCE, % (Pristine)</th>
<th>Stability (Pristine)</th>
<th>PCE, % (with additive)</th>
<th>amount of additive</th>
<th>Stability with additive</th>
<th>Stability conditions</th>
<th>Role of additive</th>
<th>Ref</th>
</tr>
</thead>
<tbody>
<tr>
<td>carbon quantum dot (CQD)</td>
<td>ITO/NiOₓ/CHₓNHₓPbI₃/PCBM/Ag</td>
<td>15.25</td>
<td>Remained ~ 10% PCE from initial after 48 h</td>
<td>18.24</td>
<td>0.15 mg/mL</td>
<td>Remained ~ 73.4% PCE from initial after 48 h</td>
<td>Un-encapsulated, dark, RT, RH=80%,</td>
<td>Reduce non-radiative recombination loss, improves the crystallinity of film. Thus passivates grain boundaries and improves stability</td>
<td>135</td>
</tr>
<tr>
<td>carbon nanodots (CNDs)</td>
<td>ITO/NiOₓ/CHₓNHₓPbI₃/PC61BM/BCP/Ag</td>
<td>14.48% ± 0.39%</td>
<td>N/A</td>
<td>16.47% ± 0.26%</td>
<td>10 mg/mL</td>
<td>Remained ~18% as of an absolute value of PCE after 500 h</td>
<td>dark, 25 °C, RH=40%, air, un-encapsulated,</td>
<td>increase in the crystal size and a lower content of grain boundary defects and, longer carrier lifetimes.</td>
<td>138</td>
</tr>
<tr>
<td>carbon quantum dots (CQDs)</td>
<td>FTO/TiO₂/CHₓNHₓPbI₃/Spiro-OMeTAD/Ag</td>
<td>17.59</td>
<td>(a) Retained 74% from initial PCE after 1500 h (b) Retained 17% from initial PCE after 216 h</td>
<td>18.81</td>
<td>0.05 mg/mL</td>
<td>(a) Retained 90% from initial PCE after 1500 h (b) Retained 70% from initial PCE after 216 h</td>
<td>(a) un-encapsulated, inert, (b) un-encapsulated, RH=50-60%,</td>
<td>passivate the grain boundaries and decrease the trap-state density. The bonding between CQDs and MAPbI₃ leads to a stable absorption of CQDs on the MAPbI₃ surface, forming a protective layer to prevent the perovskite from coming in contact with water, thereby enhancing the stability of PSCs.</td>
<td>137</td>
</tr>
<tr>
<td>nitrogen doped CQDs (N-CQDs)</td>
<td>ITO/PEDOT:PSS/CHₓNHₓPbI₃/PCBM/Al</td>
<td>8.34</td>
<td>N/A</td>
<td>13.936</td>
<td>3 vol%</td>
<td>N/A</td>
<td>N/A</td>
<td>N-CQDs act like an intermediate and help to form dense and smooth perovskite, passivates the trap states and decreased the non-radiative charge recombination</td>
<td>136</td>
</tr>
<tr>
<td>Nitrogen-doped carbon dots (NCDs)</td>
<td>FTO/bTiO₂/ml-TiO₂/CHₓNHₓPbI₃/Spiro-OMeTAD/Ag</td>
<td>12.12 ± 0.28%</td>
<td>N/A</td>
<td>15.93 ± 0.15%</td>
<td>0.05 mg/mL</td>
<td>N/A</td>
<td>N/A</td>
<td>coordinate with the iodide ions and lead cations on the surface of perovskite, which effectively passivates the surface traps and help reduce non-radiative charge carrier recombination, the</td>
<td>140</td>
</tr>
</tbody>
</table>
nitrogen dopants with lone electron pairs in NCDs optimise the interfacial energy level to enhance the charge carrier extraction efficiency at photoactive layer/TiO₂ interface.

<table>
<thead>
<tr>
<th>Potassium cation (K⁺) functionalized carbon nanodots (CNDs@K)</th>
<th>ITO/PTAA:F4TCNQ/CH₃NH₃PbI₃/PCBM/BPhen/Ag</th>
<th>18.25</th>
<th>N/A</th>
<th>21.04</th>
<th>N/A</th>
<th>N/A</th>
<th>defects passivation and crystallisation control of the perovskite film. K⁺ in the grain boundary and prevents excessive cations from occupying interstitial sites, thereby reducing microstrain of polycrystalline film. The synergistic effect of tailored crystal size and suppressed grain boundary defects could reduce charge trap density, facilitate charge generation, and lengthen carrier lifetime.</th>
</tr>
</thead>
<tbody>
<tr>
<td>Graphene quantum dots (GQDs)</td>
<td>FTO/c-TiO₂/mp-TiO₂/CH₃NH₃PbI₃/Spiro-OMeTAD/Au</td>
<td>16.83</td>
<td>Remained ~15.6% as of final PCE after 30 days</td>
<td>18.34</td>
<td>1.5 mg/mL</td>
<td>Remained ~17.4% as of final PCE after 30 days</td>
<td>Encapsulation-n/a, RH=36%, atm, promote charge transfer from the perovskite layer to TiO₂ film. Faster electron extraction and a slower recombination rate, passivate hanging bonds at the perovskite GBs.</td>
</tr>
</tbody>
</table>
2.2 Inorganic additives

Inorganic salts can be further explained as per the category in the periodic table, i.e. based on alkali metals, alkaline earth metals, transition metals, other metals and other non-metals. These additives may exist in the form of inorganic halide salts or inorganic acids.\textsuperscript{142}

2.2.1 Alkali metals additives

Hydro halides are at the top, as hydrogen is the first element in group one of the periodic table. Soe et al. studied the incorporation of hydrohalic acids (HX, X=I, Br, Cl) in MAPbI\textsubscript{3} precursor prepared using DMF. It was found that HX incorporation in the perovskite layer alters the bandgap and unit cell parameters. The HI addition compressed bandgap, whereas HBr widens the bandgap at high concentrations (20-25 vol %). Further, these changes were found to be correlated with the types of defects present in polycrystalline perovskite thin films combined with the structural strain induced in very small crystallites. Thus, it was concluded that these acids could influence crystallization rate, surface coverage and improve morphology. However, HCl incorporation showed no influence on bandgap.\textsuperscript{143,144} The same was verified by Yan and co-workers who investigated HI (Hydriodic acid) as an iodine quencher in MAPbI\textsubscript{3} precursor solution (prepared with isopropyl alcohol (IPA)), that further lead to chemically passivate grain boundaries and increase in PCE from 16.13\% (pristine) to 18.21\% (with HI additive).\textsuperscript{145} Likewise, alkali metals such as Li, Na, and K combined with halogen counterparts have been inspected as additives for the MAPbI\textsubscript{3} light absorber layer. Grätzel and Friend co-workers demonstrated the influence of NaI (sodium iodide) on the optical, excitonic and electrical properties of CH\textsubscript{3}NH\textsubscript{3}PbI\textsubscript{3} perovskite prepared by a two-step sequential deposition technique. It was revealed that the NaI additive helps in the complete conversion of PbI\textsubscript{2} into CH\textsubscript{3}NH\textsubscript{3}PbI\textsubscript{3}, leaving no unreacted PbI\textsubscript{2} and enhancing the crystallinity. Furthermore, KPFM measurements showed a reduction in work function (towards Au metal) for contact-potential difference (CPD) and proved the chemical passivation of perovskite surface due to additive incorporation in the precursor. Additionally, the hypothesis of partial substitution of Pb\textsuperscript{2+} with monovalent cations Na was discarded because replacing Pb\textsuperscript{2+} with the Na cations requires high energy, which cannot be obtained at room temperature since additives and films were processed at room temperature.\textsuperscript{146} Similar reports were published from Chu and co-workers who investigated alkali metal chloride additives (LiCl, NaCl and KCl) in MAPbI\textsubscript{3} and suggested that mixed halide formation does not occur as Cl atoms easily evaporate due to the annealing
process, improving the crystallinity and carrier charge transport \textsuperscript{147}. However, as the size of nuclei increases, the perovskite shows partial replacement and forms a perovskite with a double cation. (i.e. in the case of RbX and CsX, where X represents halide) \textsuperscript{148} The partial substitution of cation was also observed when alkaline earth metals were employed as additives in the precursor. Hence, they are not the centre of attraction here and suggested that alkaline earth metals are best suited to replace Pb due to their divalent nature \textsuperscript{149,150}. Further, the role of alkali metal additives in the MAPbI\textsubscript{3} framework is summarized in Table 11.
Table 11 Alkali metal additives and their role in MAPbI₃ perovskite.⁵⁷

<table>
<thead>
<tr>
<th>Additive in active layer</th>
<th>Architecture</th>
<th>PCE, % (Pristine)</th>
<th>Stability (Pristine)</th>
<th>PCE, % (with additive)</th>
<th>amount of additive</th>
<th>Stability with additive</th>
<th>Stability conditions</th>
<th>Role of additive</th>
<th>Ref</th>
</tr>
</thead>
<tbody>
<tr>
<td>HI</td>
<td>ITO/PTAA/CH₃NH₃PbI₃/PCBM/Ti/Au</td>
<td>16.1</td>
<td>N/A</td>
<td>18.21</td>
<td>0.004 vol%</td>
<td>N/A</td>
<td>N/A</td>
<td>Grain size improvement</td>
<td>145</td>
</tr>
<tr>
<td>HCl</td>
<td>Glass/TiO₂/CH₃NH₃PbI₃/Spiro-OMeTAD/Au</td>
<td>9.96</td>
<td>N/A</td>
<td>14.49</td>
<td>volume ratio 8%</td>
<td>N/A</td>
<td>N/A</td>
<td>Grain size improvement and morphology enhancement</td>
<td>151</td>
</tr>
<tr>
<td>HBr</td>
<td>Glass/TiO₂/CH₃NH₃PbI₃/Spiro-OMeTAD/Au</td>
<td>13.53</td>
<td>N/A</td>
<td>15.21</td>
<td>volume ratio 8%</td>
<td>N/A</td>
<td>N/A</td>
<td>Grain size improvement and morphology enhancement</td>
<td>151</td>
</tr>
<tr>
<td>LiI</td>
<td>FTO/TiO₂/CH₃NH₃PbI₃/electrode</td>
<td>11.3</td>
<td>Remained ~1% PCE as of final value after 25 days</td>
<td>17.01</td>
<td>12mg/mL</td>
<td>Retained ~6% PCE as of final value after 70 days</td>
<td>un-encapsulated, ambient, air, RH=40%,</td>
<td>larger grain size and higher crystallinity and reduced PbI₂ residue</td>
<td>152</td>
</tr>
<tr>
<td>NaI</td>
<td>FTO/compact TiO₂/CH₃NH₃PbI₃/SpiroMeOTAD/Au</td>
<td>14.01</td>
<td>N/A</td>
<td>15.14</td>
<td>0.02 mol/L</td>
<td>N/A</td>
<td>N/A</td>
<td>Improved crystallinity and grain boundary passivation</td>
<td>146</td>
</tr>
<tr>
<td>LiCl</td>
<td>Glass/ITO/PEDOT:PSS/CH₃NH₃PbI₃/PC₆1BM/C₆0/BCP/Al</td>
<td>11.40</td>
<td>Died in 50 days</td>
<td>9.98</td>
<td>0.25%, wt%</td>
<td>N/A</td>
<td>N/A</td>
<td>Improved crystallinity and homogenous nucleation, and crystallisation</td>
<td>147</td>
</tr>
<tr>
<td>NaCl</td>
<td>Glass/ITO/PEDOT:PSS/CH₃NH₃PbI₃/PC₆1BM/C₆0/BCP/Al</td>
<td>12.77</td>
<td>1.0%, wt%</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
</tr>
<tr>
<td>KCl</td>
<td>Glass/ITO/PEDOT:PSS/CH₃NH₃PbI₃/PC₆1BM/C₆0/BCP/Al</td>
<td>15.08</td>
<td>0.75%, wt%</td>
<td>Remained ~85% after 50 days</td>
<td>unencapsulated, inert (glove box) dark</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
</tr>
</tbody>
</table>


2.2.2 Transition metals additives

Additionally, some transition metals have also been reported as additives in MAPbI\textsubscript{3} precursor. One such example is n-type goethite (FeOOH) quantum dots that act as multifunctional additives. The addition of FeOOH QDs into precursor solution improves not only the performance but also stability. The investigation done by Wang and the group showed that FeOOH QDs could produce heterogeneous nucleation, passivate the trap states, and obstruct the ion migration. The investigation demonstrated that the oxygen (in FeOOH) as a Lewis base could coordinate with Lewis acid Pb\textsuperscript{2+}. The –OH group (in FeOOH) can coordinate with hydrogen atoms of MA\textsuperscript{+}. Thus, this interaction results in the delay of crystal growth kinetics, resulting in good quality of perovskite films that result in high PCE. Further, the iron in FeOOH QDs as a Lewis acid interact with Lewis base I\textsuperscript{–}. Thus, ion migration of I\textsuperscript{–} and MA\textsuperscript{+} is controlled, resulting in enhanced intrinsic stability of solar cells\textsuperscript{153}. Further, the transitional metal halides, either with monovalent cations (i.e. AgI, CuI, CuBr), divalent cation (NiCl\textsubscript{2}, CuCl\textsubscript{2}, ZnCl\textsubscript{2}, CdCl\textsubscript{2})\textsuperscript{154–157} or trivalent cation (RhI\textsubscript{3})\textsuperscript{158}, frequently pointed out the improvement in crystallinity and grain boundary passivation.

Interestingly, in all these reports, Chlorine-based additive salts were reported to form the MAPbI\textsubscript{3} phase without mixed iodide and chloride as it was proposed that Cl atoms evaporate while annealing the films. Similarly, trivalent cation like Rh\textsuperscript{3+} was also noticed not replacing lead atoms when used in small quantities like 1 mol\%. However, the addition to 5\% could result in partial replacement of the Pb atom. Further, Table 12 summarizes the details associated with transitional metal additives.

83
<table>
<thead>
<tr>
<th>Additive in active layer</th>
<th>Architecture</th>
<th>PCE, % (Pristine)</th>
<th>Stability (Pristine)</th>
<th>PCE, % (with additive)</th>
<th>amount of additive</th>
<th>Stability with additive</th>
<th>Stability conditions</th>
<th>Role of additive</th>
<th>Ref</th>
</tr>
</thead>
<tbody>
<tr>
<td>n-type goethite (FeOOH)</td>
<td>FTO/cTiO₂/mp-TiO₂/CH₃NH₃PbI₃/Spiro-OMeTAD/Au</td>
<td>15.4</td>
<td>(a) Remained only 5.7 % as of final PCE after 360h. (b) Retained 61% from initial PCE after 60 days (c) Retained only 42% from initial PCE after 480h</td>
<td>19.7</td>
<td>0.1 mg/ml</td>
<td>(a) Retained 94 % after 360h. i.e. 17.9% (b) Retained 97% from initial PCE after 60 days (c) Retained 92% from initial PCE after 480h</td>
<td>(a) inert, 85°C, dark, non-encapsulated, (b) 10± 5% RH, (c) 100 mW cm⁻², inert, RT, mpp tracking.</td>
<td>Improved quality of perovskite and inhibition of iodine and methylamine ion migration</td>
<td>153</td>
</tr>
<tr>
<td>AgI</td>
<td>FTO/compact TiO₂ /mesoporous TiO₂ /CH₃NH₃PbI₃/SpiroMeOTAD/Au</td>
<td>14.01</td>
<td>N/A</td>
<td>14.18</td>
<td>0.02 mol/L</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>Improved crystallinity and grain boundary passivation</td>
</tr>
<tr>
<td>CuI</td>
<td>FTO/compact TiO₂ /mesoporous TiO₂ /CH₃NH₃PbI₃/SpiroMeOTAD/Au</td>
<td>15.25</td>
<td>N/A</td>
<td>15.61</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td></td>
</tr>
<tr>
<td>CuBr</td>
<td>FTO/compact TiO₂ /mesoporous TiO₂ /CH₃NH₃PbI₃/SpiroMeOTAD/Au</td>
<td>17.25</td>
<td>Retained ~70% PCE after 100 h</td>
<td>20.61</td>
<td>0.03 mM</td>
<td>Retained ~70% PCE after 100 h</td>
<td>En-capssulated, air, 65 mW cm⁻², ~25 °C , RH&lt;45%, without ultraviolet filter</td>
<td>High crystallinity, GB passivation,</td>
<td></td>
</tr>
<tr>
<td>NiCl₂</td>
<td>FTO/SnO₂ /CH₃NH₃PbI₃/SpiroMeOTAD/Au</td>
<td>9.73</td>
<td>N/A</td>
<td>15.22</td>
<td>2.5 mol%</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>Improves morphology</td>
</tr>
<tr>
<td>CuCl₂</td>
<td>FTO/NiO₂ /CH₃NH₃PbI₃/PCBM/BCP/Ag</td>
<td>11.7</td>
<td>N/A</td>
<td>13.2</td>
<td>1 % molar ratio</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>Enhance grain size and crystallinity</td>
</tr>
<tr>
<td>CdCl₂</td>
<td>FTO/compact TiO₂ /mesoporous TiO₂ /CH₃NH₃PbI₃/SpiroMeOTAD/Au</td>
<td>13.76</td>
<td>0.1 % molar ratio</td>
<td>0.1 % molar ratio</td>
<td>19.09</td>
<td>Retained 75% of efficiency after 500 h</td>
<td>N/A</td>
<td>N/A</td>
<td>Improved crystallinity and grain boundary passivation</td>
</tr>
</tbody>
</table>

Table 12 Transition metal additives and their role in MAPbI₃ perovskite.²⁷
2.2.3 Other metals additives

The most widely reported metal additive is PbI₂. Several groups have suggested using excess PbI₂ as an additive and studied the effect of the stoichiometric and non-stoichiometric composition of PbI₂ in MAPbI₃ perovskite. Reports suggest that the addition of excess PbI₂ in perovskite increases power conversion efficiency (PCE). However, the influence of excess PbI₂ on photochemical stability is debatable. Some research groups claim that excess PbI₂ passivates grain boundary, thus creates extra passivation, enhancing performance and stability overall. On the contrary, some reports showed that excess PbI₂ could increase PCE but decreases PSC stability. To resolve the issue, Stevenson and the group demonstrated that the stability associated with excess PbI₂ is affected by solvent coordination capacity with Pb atom and suggested that excess PbI₂ can work as a stabilizer to improve intrinsic stability if correct solvent (NMP) is chosen over commonly-used solvent DMF. Later, other than PbI₂, adding PbCl₂ also reported to result in an equally good perovskite film quality with improved performance, but the outcome was reported as a mixed halide. Hence, it is not focused here. Interestingly, Ngo and the group demonstrated a different approach by using PbS quantum dots as capping ligands in the precursor solution to control nucleation and morphology. This approach allowed to improve crystallinity and enhanced grain size, resulting in improved solar cell performance. Further, a relevant summary is presented in Table 13.
Table 13 Other metal additive for MAPbI₃

<table>
<thead>
<tr>
<th>Additive in active layer</th>
<th>architecture</th>
<th>PCE, % (Pristine)</th>
<th>Stability (Pristine)</th>
<th>PCE, % (with additive)</th>
<th>amount of additive</th>
<th>Stability with additive</th>
<th>Stability conditions</th>
<th>Role of additive</th>
<th>Ref</th>
</tr>
</thead>
<tbody>
<tr>
<td>PbI₂</td>
<td>FTO/c-TiO₂/m-TiO₂/CH₃NH₃PbI₃/Spiro-OMeTAD/Au</td>
<td>15.95</td>
<td>N/A</td>
<td>18.42</td>
<td>10 % excess PbI₂</td>
<td>N/A</td>
<td>N/A</td>
<td>improves the crystallinity</td>
<td>159</td>
</tr>
<tr>
<td>PbI₂</td>
<td>Glass/FTO/CH₃NH₃PbI₃/Spiro-OMeTAD/Electrode/Encapsulation(UV-epoxy)</td>
<td>16.2</td>
<td>Retained 80% PCE till 12 h</td>
<td>16.5</td>
<td>10 mg/mL</td>
<td>Retained 80% PCE till 10 days</td>
<td>ambient air, 85°C and 60% RH, 1sun</td>
<td>N/A</td>
<td>167</td>
</tr>
<tr>
<td>PbI₂</td>
<td>Glass/ITO/SnO₂/CH₃NH₃PbI₃/PTAA/MoO₃/Al</td>
<td>~8.9%</td>
<td>Remained ~40% PCE after 1500 h</td>
<td>~15.6%</td>
<td>15% excess</td>
<td>Remained ~95% PCE after 1500 h</td>
<td>30 mW cm⁻² at 40 °C, inert</td>
<td>Excess PbI₂ forms adduct with the cosolvent (NMP), improving PCE and stability.</td>
<td>168 (Our work)</td>
</tr>
<tr>
<td>PbI₂</td>
<td>FTO/TiO₂/CH₃NH₃PbI₃/Spiro-OMeTAD/Ag</td>
<td>7.23 ± 0.10</td>
<td>N/A</td>
<td>14.32±0.28%</td>
<td>concentration N/A, by annealing @130 °C</td>
<td>N/A</td>
<td>N/A</td>
<td>grain boundary passivation</td>
<td>172</td>
</tr>
<tr>
<td>PbS QDs</td>
<td>FTO/SnO₂/CH₃NH₃PbI₃/Spiro-OMeTAD/Au</td>
<td>15.2</td>
<td>N/A</td>
<td>15.7</td>
<td>12.5mg/mL</td>
<td>N/A</td>
<td>N/A</td>
<td>Capping ligand for surface functionalization to improve crystallinity</td>
<td>171</td>
</tr>
</tbody>
</table>

86
2.2.4 Non-metal inorganic salts

Furthermore, the controlled nucleation, improved morphology, enhanced crystalline size and grain size with lower trap density were also noticed with additives based on other non-metals salts. During the two-step method, which is one of the commonly used fabrication approaches to fabricate planar heterojunction complex lead halide perovskite solar cells, the complete conversion of PbI₂ into CH₃NH₃PbI₃ is often observed to be restricted by the inadequate diffusion of CH₃NH₃I into PbI₂ film, which affects the short circuit current density. To overcome this problem, Pathipati and co-worker used ammonium iodide (NH₄I) in small quantity (5 wt%) in the PbI₂ solution and found this approach increases the porosity of PbI₂ film, allowing to improve film morphology and increasing grain size up to 500 nm. This, in turn, improves the fill factor and short circuit current density, improving the PCE compared to pristine solar cell 173. Similarly, a drastic improvement in fill factor (from 27.53 without additive to 80.11 with NH₄Cl additive) was noticed when NH₄Cl was added in MAPbI₃ precursor. Moreover, as reported earlier, due to the quick evaporation of chlorine atoms, mixed halide formation did not take place 174. Furthermore, improved performance and higher stability were observed with different ammonium halide salts (NH₄X, where X can be I, Cl, Br) even when using the single-step solution process method. Although, NH₄I showed the highest performance amongst all 173–175. Another ammonium-based additive, NH₄H₂PO₂ (ammonium hypophosphite-AHP), was reported to show similar behaviour. Surprisingly, one of the by-product (H₃PO₂) from CH₃NH₃I synthesis was found suppressing the formation of molecular iodine (i.e. the oxidation of I⁻ to I₂) 176,177. This led to the idea of using NH₄H₂PO₂ (ammonium hypophosphite-AHP) as an additive in the PbI₂/CH₃NH₃I precursor. Huang and co-workers found that AHP forms a complex with PbI₂, which leads to improvement in crystallinity and grain size. In turn, this improves PV performance due to crystalline grain boundaries 178. Besides, in a recent report, it was illustrated that N₂H₅I, an iodine quencher in the MAPbI₃ active layer, can form an intermediate complex with PbI₂ and enhanced crystallinity and grain size ~1100 nm, causing grain boundary passivation. Which, in turn, reduced hysteresis in solar cells, improved efficiency and intrinsic stability of solar cells up to 4400 h 179. Similar reports were received from Huang and the group who reported N₂H₅Cl incorporation in MAPbI₃ 180. Whereas hypophosphorous acid (HPA) was used to assist crystallization dynamics for large area substrates 181. A summary of these additives is presented in Table 14.
Table 14 Non-metal additives and their role in MAPbI₃ active layer.⁷⁷

<table>
<thead>
<tr>
<th>Additive in active layer</th>
<th>Architecture</th>
<th>PCE, % (Pristine)</th>
<th>Stability (Pristine)</th>
<th>PCE, % (with additive)</th>
<th>amount of additive</th>
<th>Stability with additive</th>
<th>Stability conditions</th>
<th>Role of additive</th>
<th>Ref</th>
</tr>
</thead>
<tbody>
<tr>
<td>NH₄I</td>
<td>Glass/ITO/PTAA/CH₃NH₃PbI3/PCBM/Ag</td>
<td>15.2</td>
<td>Retained ~70% PCE after 20 days</td>
<td>17.4</td>
<td>5 wt%</td>
<td>Retained ~80% PCE after 20 days</td>
<td>RH=50 ± 5%, un-encapsulate d, ambient air,</td>
<td>Improved morphology, increased crystalline size and grain size, lower trap density</td>
<td>173</td>
</tr>
<tr>
<td>NH₄Cl</td>
<td>ITO/PEDOT-PSS/CH₃NH₃PbI3/PC₆0BM/Al</td>
<td>7.97</td>
<td>N/A</td>
<td>9.93</td>
<td>17.5mg/mL</td>
<td>N/A</td>
<td>N/A</td>
<td>Improved morphology, increased crystalline size and grain size, lower trap density</td>
<td>174</td>
</tr>
<tr>
<td>NH₄F</td>
<td>ITO/PEDOT-PSS/CH₃NH₃PbI3/PC₆0BM/LiF/Al</td>
<td>13.74</td>
<td>Retained 70 % PCE after 5 weeks</td>
<td>15.15</td>
<td>10 mol%</td>
<td>Retained 82 % PCE after 5 weeks</td>
<td>Encapsulated, air</td>
<td>Improved morphology, increased crystalline size and grain size, lower trap density</td>
<td>175</td>
</tr>
<tr>
<td>NH₄Br</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>NH₄I</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>NH₄H₂PO₂</td>
<td>ITO/PTAA:F4-TCNQ/CH₃NH₃PbI3/PC₆0BM/TrNBr/Ag</td>
<td>9.4 ± 1.0%</td>
<td>N/A</td>
<td>16.5 ± 0.7%</td>
<td>2.5mg/ml</td>
<td>N/A</td>
<td>N/A</td>
<td>Intermediate with Pb and improved crystallinity grain size</td>
<td>178</td>
</tr>
<tr>
<td>N₂H₅I</td>
<td>Glass/ITO/SnO2/CH₃NH₃PbI3/PTAA/MoO/Cr/Al</td>
<td>14.98</td>
<td>Retained ~60 % PCE after 4400 h</td>
<td>17.03</td>
<td>0.5%, % by wt</td>
<td>Retained ~80 % PCE after 4400 h</td>
<td>Inert, light 50-60 mWcm², 50-60 °C.</td>
<td>Intermediate between PbI₂ and N₂H₅I, improved crystallinity, grain size</td>
<td>179 <em>(Our work)</em></td>
</tr>
<tr>
<td>N₂H₅Cl</td>
<td>ITO/PEDOT-PSS/CH₃NH₃PbI3/PCBM/C₆0/BCP/Ag</td>
<td>7.14</td>
<td>N/A</td>
<td>12.66</td>
<td>PbI/MAI/N₂H₅Cl molar ratio = 1:1:0.2</td>
<td>N/A</td>
<td>N/A</td>
<td>Intermediate between PbI₂ and N₂H₅Cl, improved crystallinity, grain size</td>
<td>180</td>
</tr>
<tr>
<td>hypophosphorous acid (HPA)</td>
<td>Glass/FTO/TiO₂/CH₃NH₃PbI3/ETL/electrode</td>
<td>5.1</td>
<td>N/A</td>
<td>8</td>
<td>0.75 ul/mg solution in 1 ml of MAI</td>
<td>N/A</td>
<td>N/A</td>
<td>larger grains with a smoother surface, Additive acts as a reducing agent for iodine</td>
<td>181</td>
</tr>
</tbody>
</table>
2.3 Summary of literature review:

To summarize, upon the literature review analysis, it was found that amines, heterocyclic amines, and their derivatives, followed by carbonyl and acetate functional groups, can improve intrinsic stability. On the other hand, acid, esters, ether and alcohol, and S atom-based additives can be mainly valuable to boost ambient stability. For a comparison, see Figure A0.1-A0.3, Appendix 0. Similarly, the comparison for inorganic additives is presented in Figure A0.4, Appendix 0.

Furthermore, it has been observed that additives showing stabilization effect typically resulted in improved nucleation growth, film morphology, crystallinity, grain size leading to passivate grain boundary via complex/intermediate formation. Similar characteristics were observed in our studies and presented under the section “Results and discussion.”
3. Experimental section

This section describes the methodology to conduct experiments, materials used and techniques majorly performed to characterise thin films and solar cells in the scope of this thesis.

3.1 Methodology

The scheme of the methodology implemented during the thesis work is shown in Figure 8. The motivation behind this methodology is to screen additives that enhance the intrinsic stability of the perovskite photoactive layer. That is why a thin film study is opted before investigating solar cell performance with additives.

![Figure 8: Methodology of the experiment. (a) solution preparation (b) Spin coating process for device optimization (c) conditions for stability tests (d) completed device upon stability tests.](image)

The methodology of the experiment can be described in the following parts:

i) Prepare the precursor solution with an additive.

ii) Next, prepare thin films of perovskite precursor with additives on glass substrates, using the one-step spin-coating method. This allows understanding the impact of additive on the photostability absorber layer. Because glass substrate is considered inert material, hence it will not influence degradation dynamics.
iii) Test photo-thermal stability of perovskite film with the additive by exposing the film to the given light intensity at a certain temperature in an inert environment. Therefore, the experiments are performed in a glovebox to minimise the effect of external factors such as moisture, water, air.

iv) Further, improvement in intrinsic stability is characterised using UV-Vis and XRD measurements (primarily), performed with a certain time interval.

v) Thus, the most stable additive is screened and further adopted to check the device performance of the solar cell with the selected additive.

vi) If device performance is higher than pristine perovskite, prepare solar cell devices with this additive and check device stability. This is because the PCE of PSCs is going higher, but stability is still to be achieved. Hence here, the aim is to screen the additive that enhances stability and shows decent performance.

3.2 Materials

The chemical structures of investigated additives are shown in Figure 9 below.
**Figure 9 Investigated additives and their chemical structures**
Following the classification in the literature review, the functional groups present in the investigated additives are shown in Table 15.

**Table 15 Investigated additives with their respective functional group**

<table>
<thead>
<tr>
<th>S.No</th>
<th>Name of Additive</th>
<th>Functional groups in additive</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td></td>
<td>amines and derivatives</td>
</tr>
<tr>
<td>1.</td>
<td>Hydrazinium Iodide</td>
<td>✔</td>
</tr>
<tr>
<td>2.</td>
<td>Lead Iodide with NMP - (functional group shown here is for NMP)</td>
<td>✔</td>
</tr>
<tr>
<td>3.</td>
<td>Acetylcysteine</td>
<td>✔</td>
</tr>
<tr>
<td>4.</td>
<td>Lipoic Acid</td>
<td></td>
</tr>
<tr>
<td>5.</td>
<td>Mercaptoundeconic acid</td>
<td></td>
</tr>
<tr>
<td>6.</td>
<td>Mercapto succinic acid</td>
<td></td>
</tr>
<tr>
<td>7.</td>
<td>SHS35</td>
<td></td>
</tr>
<tr>
<td>8.</td>
<td>Phenyl-C61-butyric acid (PCBA)</td>
<td></td>
</tr>
<tr>
<td>9.</td>
<td>Poly[bis(4-phenyl)(4 - trimethyl[phenyl]amin e] - PTA</td>
<td>✔</td>
</tr>
<tr>
<td>10.</td>
<td>Urea</td>
<td>✔</td>
</tr>
<tr>
<td></td>
<td>additive</td>
<td>1</td>
</tr>
<tr>
<td>---</td>
<td>----------------------------------------------</td>
<td>-----</td>
</tr>
<tr>
<td>11.</td>
<td>Thiourea</td>
<td>✔</td>
</tr>
<tr>
<td>12.</td>
<td>Lactose</td>
<td></td>
</tr>
<tr>
<td>13.</td>
<td>Tetraethyl orthosilicate(Si-(O-C2H5)4)</td>
<td></td>
</tr>
<tr>
<td>14.</td>
<td>Gamma bipyridyl</td>
<td>✔</td>
</tr>
<tr>
<td>15.</td>
<td>8 Oxyquinoline</td>
<td>✔</td>
</tr>
<tr>
<td>16.</td>
<td>4-hydroxy-phenanthroline</td>
<td>✔</td>
</tr>
<tr>
<td>17.</td>
<td>1,10 Phenanthroline</td>
<td>✔</td>
</tr>
<tr>
<td>18.</td>
<td>Bathoocuproine</td>
<td>✔</td>
</tr>
<tr>
<td>19.</td>
<td>Bathophenanthroline</td>
<td>✔</td>
</tr>
<tr>
<td>20.</td>
<td>Pentaerythritol tetrakis(2-mercaptoacetate)</td>
<td></td>
</tr>
<tr>
<td>21.</td>
<td>Tetrathiafulvalene</td>
<td></td>
</tr>
<tr>
<td>22.</td>
<td>AK1882</td>
<td>✔</td>
</tr>
<tr>
<td>23.</td>
<td>Delo (commercial product - functional group not known)</td>
<td></td>
</tr>
</tbody>
</table>

The highlighted additives (green coloured) in Table 15 showed improved intrinsic stability over pristine MAPbI3 films (Figure A1.1, Appendix A1). While unhighlighted represents additives, those did not improve the photostability of thin-film (Figure A1.2, Appendix A1). However,
only the best results will be the focus of this thesis. Therefore, the best additives improving stability will be described under the section “4. Results and discussion”.

Besides the above-studied additives, other typically used materials and chemicals involved are N,N-dimethylformamide (DMF, anhydrous, 99.99%), and N-methyl-2-pyrrolidone (NMP), aqueous tin oxide (15% concentration), PCBM, toluene, chlorobenzene and ethyl acetate; those were purchased from Sigma-Aldrich and used as received. PCBA, PTA, PTAA, MAI, PbI₂ were home-grown and used as 99.999% pure. Glass substrates were used for thin-film experiments. ITO coated substrates were used as required for device performance and device stability experiments.

3.2.1 Preparation of Precursor Solutions:

0.3M solution of MAPbI₃ combined with additives was used to prepare thin films. Additives were added by 5%, percentage by weight unless specified. Further, 1.4M solution of MAPbI₃ was used to prepare devices unless specified. Filtered solutions were used for film and device fabrication and characterisation. Precursor solutions were filtered with 0.45um PTFE filters. The precursor solutions usually contained MAI and PbI₂ dissolved in either pure DMF or the mixture of DMF/NMP (4:1 v/v) and annealed at 70 °C overnight. The absorber layer for thin films and PSCs are made using this solution-processed precursor with a one-step spin coating method. For which, toluene is used as an antisolvent.

3.2.2 Thin Film Preparation:

Glass substrates were cut into 25 mm* 25 mm size and cleaned. Deionized water, acetone and isopropanol were used to give an ultra-sonication bath for 15 minutes in this particular sequence for cleaning substrates. Upon cleaning, substrates were plasma treated for 5 minutes. Then, transferred into Argon filled glovebox. 0.3M solution of MAPbI₃ is used to prepare perovskite film on the glass substrate. (with the respective additive added by 5 wt% in 1 ml precursor). The absorber layer was spun at 3000 rpm and annealed at 100°C for a minute.
3.2.3. Device Preparation:

Devices are prepared in n-i-p configuration. Typically architecture of the device consists of Glass/TCO/ETL/Passivation layer/MAPbI₃(with or without additive)/HTL/metal electrode. ITO is used as TCO. To prepare PSCs, glass substrates coated with Indium Tin Oxide(ITO) were cut into 25 mm* 25 mm size and cleaned. Deionized water, acetone and isopropanol were used to give an ultra-sonication bath for 15 minutes to clean the ITO substrates in this particular sequence. Upon cleaning, substrates were plasma treated for 5 minutes. Usually, SnO₂ is used as ETL followed by a passivation layer of either PCBA or PCBM. Incase of PCBA concentration used is 0.4mg/ml in toluene and in case of PCBM concentration used is 30mg/ml in CB. ZnO is occasionally used as specified. The ETL layer of SnO₂ is spun at 4000 rpm and annealed at 170°C for 15 minutes. This SnO₂ solution was made by adding deionized water to dilute tin oxide concentration from 15 % to 10 %. Water was added in the ratio of 2:1. Further, this solution was ultra-sonicated for 5 minutes and filtered using a 0.45um PES filter. The filtered solution was used to spin coat on cleaned substrates. In the case of ZnO, ZnO is spun at 6000 RPM and further annealed at 200°C for 1 hour. The ZnO solution was made by mixing 0.100 g zinc acetate dihydrate with 28.0 ml monoethanolamine in 1 ml of 2-methoxyethanol and stirring it overnight at room temperature. Thus obtained ZnO was filtered using 0.45 um filters before spinning coating onto the substrates.

All the subsequent layers after SnO₂ is spin-coated in Ar filled glovebox. In the glovebox, these substrates were heated at 150 °C for 10 minutes. Inside the glove box, first, PCBM /PCBA layer was spun at 3000 rpm and annealed for 5 minutes at 80°C/100°C respectively. Further perovskite layers were spun at 4000 rpm. For the perovskite layer, the one-step spin coating was used, toluene was used as antisolvent. These films were further annealed at 85 °C for 10 minutes. Either PTA (6 mg /ml in toluene) or PTAA (6mg/ml in toluene) was used as HTL and was spun on the perovskite layer at 3000 rpm. Polystyrene (0.4mg /ml in ethyl acetate) is spun on the perovskite layer before evaporating electrodes. Then, MoO₃ (10nm) and Silver (100nm) electrodes were used.

To test the device stability, devices were fabricated as Glass/ITO/SnO₂/MAPbI₃/PTAA/V₂O₅/Al. This is to investigate that stability of the absorber
layer is not affected by the instability of the passivation layer. Here $V_2O_5$ and Al were thermally electrodes.

3.3 Characterisation Techniques:

3.3.1 UV-visible spectroscopy

The absorbance feature of the perovskite layer can be monitored using UV-Vis spectra. The evolution of the absorbance feature further indicates the stability or instability of film for additive incorporation with respect to time. The UV-Vis spectra were measured using AvaSpec-2048-2 UV–Vis fibre spectrometer integrated inside the glove box.

3.3.2 XRD measurements

Additionally, X-ray diffraction patterns are used to verify the phase and crystallinity of the perovskite films. Besides, XRD can help to investigate adduct formation, degradation byproduct. XRD patterns were measured using a Bruker D8 Advance powder diffractometer (Cu-$K\alpha$ radiation, 5–60° 2 theta range, 0.0219° increment step). Measurements were carried out in fixed illumination mode with no sample rotation. The time interval of 0.2 seconds, voltage 40kV, filament current 40 mA was used for all the measurements.

3.3.3 FTIR spectroscopy

FTIR spectroscopy can reveal the changes in vibrations corresponding to the functional groups associated with additive in MAPbI$_3$. Thus, it can help to understand the additive interaction with the MAPbI$_3$ framework. The FTIR spectra were obtained using Bruker Alpha II with an ATR module (diamond crystal).

3.3.4 Photoluminescence

Photoluminescence measurements can reveal the changes in photoemission upon additive incorporation. That can further lead to correlate charge transport properties. The PL measurements were carried out using Automatic Research GmbH LBIC+PL+EL microscopy setup with Horiba spectrometer. All samples were measured with 532 nm laser wavelength at 0.05s integration time, 0.5 slit-width. For PL vs Power dependency, laser power variation was from 18.5 μW (10%) to 185 μW (100%).
3.3.5 Atomic Force Microscopy

AFM topography is a useful tool to reveal changes on the surface of perovskite film upon additive incorporation and photostability experiments. AFM topography images were obtained in a semicontact mode using Cypher ES atomic force microscope installed in an Ar-filled glovebox. Single crystal diamond probes (HA_NC/FD) were used to reduce sticking of material from the photodegraded samples to the tip and avoid imaging artefacts.

While in-situ measurements can reveal the detailed mechanism of adduct formation, AFM Insitu photo-degradation was performed using a laser beam of 405 nm wavelength, with a light intensity of 10 kW m\(^{-2}\).

3.3.6 Scanning Electron Microscopy & Energy Dispersive Xray.

Similar to AFM topography, SEM topography is very useful, especially in measuring grain size and change in morphology upon additive incorporation in MAPbI\(_3\) film. Additionally, EDX allows to compare the quantity of lead before and after photostability test and thus additive binding with Pb site can be understood.

For excess PbI\(_2\) investigation, EDX analysis was performed on an Oxford Instruments Inco Energy unit integrated with the Zeiss SUPRA 25 microscope. For HAI related studies, SEM and EDX measurements were performed using the Helios G4 Plasma FIB Uxe double-beam scanning electron microscope. A top view imaging was performed in secondary electron (SE) mode at 5-10 kV. The energy-dispersive X-ray spectroscopy (EDX) was implemented at 10kV. The Octane Elite Super detector by EDAX and Team Software by EDAX was used within the FEI Helios system. The EDX signal was averaged along the sample surface in order to determine the I:Pb ratio.

3.3.7 X-ray photoelectron spectroscopy

XPS was used to measure core level and VB spectra with the assistance of a PHI XPS 5000 VersaProbe spectrometer (ULVAC-Physical Electronics, USA) equipped with a spherical quartz monochromator and an energy analyzer working in the range of binding energies from 0 to 1500 eV. The energy resolution was ΔE ≤ 0.5 eV. The samples were kept in the vacuum chamber for 24 h prior to the experiments and were measured at a pressure of 10\(^{-7}\) Pa.
3.3.8 J-V characterisation

Device performance characterisation was done by measuring Current-Voltage (J-V) behaviour under AM 1.5G (100 mW cm\(^{-2}\)) solar illumination simulator inside the glovebox. This instrument is provided by a Newport Verasol AAA class solar simulator. The illumination intensity was checked before each measurement using a calibrated silicon diode with known spectral responses. The J-V curves of all devices were measured while applying a metal mask with a 0.041 cm\(^2\) window (unless specified) using the Advantest 6240A Source measurement units.
4. Results and Discussion

4.1 Impact of solution formulation on the excess of PbI$_2$ additive in MAPbI$_3$ thin films and solar cells

PbI$_2$ as an additive is one of the controversial additive investigated in the MAPbI$_3$ light-absorbing layer. Many groups most widely investigate the non-stoichiometric usage of PbI$_2$. The majority of researchers have reported that excess PbI$_2$ improves PCE. But its impact on photostability was debatable $^{182,183}$. Some reports showed that excess PbI$_2$ passivates grain boundary $^{163,184}$, generating passivation effect $^{164,185}$, improving performance and stability overall $^{165,185,186}$. Contrariwise, some reports showed, employing an excess of PbI$_2$ in precursor solution reduced the stability of PSC $^{187}$, even in inert environment $^{167,188}$.

However, these reports lack the focus on the aspect of solvent engineering while reporting excess PbI$_2$ and its impact on photostability. Since the choice of solvents affects perovskite film quality, morphology, device performance and stability due to the difference in coordination between perovskite material and various solvent $^{189-198}$, we chose to study the impact of excess PbI$_2$ in MAPbI$_3$ perovskite with respect to different solution formulation. For this purpose, DMF was chosen, a commonly used solvent to prepare perovskite ink $^{194,199}$. Although reports have shown that DMF exhibits poor coordination ability with PbI$_2$ due to lower boiling point (152°C) and higher evaporation rate, which may cause instability. Next, NMP was chosen, which exhibits a higher boiling point (203°C) and low evaporation rates $^{200,201}$, producing a relatively stable intermediate phase with PbI$_2$ $^{193,202,203}$, due to the strong intercalation properties $^{191,204}$, further leading to rapid nucleation and growth of perovskite crystals with a uniform and good film morphology $^{201,205}$. Further, reports have shown that 20 % addition of NMP gives the best results; we used 20 % NMP with 80% DMF to yield 1 ml of DMF/NMP mixture solution $^{195}$. An overview of the chemical structures of these two solvent DMF and NMP is further shown in Figure A2.1 in Appendix 2.
Next, I prepared films with these two solution formulations—pure DMF and DMF/NMP mixture. The films were prepared in the following configuration: ITO/ZnO/MAPbI$_3$ (with and without excess PbI$_2$)/PTA. Then, films were placed into a photodegradation chamber in N$_2$ filled glovebox under white light with power 50 mW cm$^{-2}$ at 60$^\circ$C for 200 h. Fresh and photoaged films were characterized using UV-Vis Spectra, X-ray diffraction (XRD) primarily.

Here, the reference MAPbI$_3$ film from pure DMF is represented as MAPbI$_3$. DMF and MAPbI$_3$ film with 15% excess PbI$_2$ from pure DMF is represented as MAPbI$_3$+PbI$_2$.DMF. Likewise, the reference MAPbI$_3$ film from DMF/NMP mixture is represented as MAPbI$_3$.NMP and 15% excess of PbI$_2$ in DMF/NMP is denoted as MAPbI$_3$+PbI$_2$.NMP.

4.1.1 Photostability of thin-films

UV-Vis tests revealed that all fresh films (independent of solvent formulation or excess PbI$_2$ content) had an absorbance characteristic at 750 nm, indicating that perovskite production had occurred. However, at 500 nm, a shoulder corresponding to PbI$_2$ emerged for fresh MAPbI$_3$.DMF and MAPbI$_3$+PbI$_2$.DMF films. Whereas for fresh MAPbI$_3$.NMP and MAPbI$_3$+PbI$_2$.NMP films, this shoulder was observed to be prolonged (from 450 nm to 540 nm), possibly due to the presence of an intermediary phase/adduct between PbI$_2$ and NMP.

Following the photoaging, the absorbance characteristic at 750 nm for MAPbI$_3$+PbI$_2$.DMF vanished utterly. Only a peak matching to PbI$_2$ remained near 500 nm, demonstrating that extra PbI$_2$ speeds the disintegration of perovskite film when made with pure DMF. The absorbance characteristic at 750 nm for MAPbI$_3$+PbI$_2$.NMP, on the other hand, remained stable, implying that the destabilising effect of over stoichiometric PbI$_2$ was inhibited due to the presence of co-solvent NMP. Further, comparing absorbance spectra with and
without excess PbI₂, before and after photoaging is displayed below (Figure 10a and 10b).

Figure 10 Absorbance spectra of fresh and photoaged MAPbI₃ films with 0% and 15% excess PbI₂
(a) from pure DMF (b) from DMF/NMP cosolvents.¹⁶⁸

XRD measurements demonstrated similar observations. The fresh MAPbI₃.DMF exhibited XRD patterns of perovskite at 14.14°, 20.03°, 23.52°, 24.54°, 28.45°, 31.93°, 40.65°, and 43.21°.¹⁸⁸,²⁰⁷ However, peaks matching to PbI₂ were observed at 12.70° and 25.68°. These peaks were visible even after photoaging. However, photoaging resulted in a small peak at 31.32° that was linked to Pb. MAPbI₃+PbI₂.DMF exhibited the same position of XRD peaks as MAPbI₃.DMF. But, more PbI₂ peaks were located at 12.68°, 25.69°, 38.65°, 39.60°, 41.73°. To add on, the intensity of the PbI₂ peak at 12.68° was found to increase due to increased PbI₂ content for MAPbI₃+PbI₂.DMF film. Sadly, MAPbI₃+PbI₂.DMF was totally degraded after photoaging, leaving PbI₂ as a minor by-product and Pb as the predominant by-product, with strong peaks at 12.68° and 31.27°, respectively (Figure 11a).²⁰⁸ Fresh MAPbI₃.NMP revealed peaks of perovskite at 14.14°, 20.06°, 23.53°, 24.57°, 28.51°, 31.94°, 40.80°, and 43.31°. Further, PbI₂ signals were found to be displaced at 12.78° and 25.69°, accompanied by the additions peaks at 8.3° and 11.10°, belonging to NMP-PbI₂ adduct.¹⁹⁵,¹⁹⁶ When PbI₂ concentration is increased (MAPbI₃+PbI₂.NMP), the low-
intensity peak of NMP-PbI₂ adduct developed a stronger peak intensity (combined with PbI₂ peak at 12.78°), and the signal at 11.10° disappeared. Later, after photoaging, the adduct formed by NMP and over stoichiometric PbI₂ remained stable but displaced slightly from its initial position to 8.18°. Furthermore, the PbI₂ peak was observed to be slightly displaced to 12.76°, with only a minimal peak corresponding to Pb at 31.31°, implying that when formulated from DMF/NMP combination, conversion of PbI₂ into Pb is slowed, resulting in visible, stable peaks corresponding to perovskite (Figure 11b).

Figure 11 XRD pattern of fresh and photoaged MAPbI₃ films with 0% and 15% PbI₂ (a) from pure DMF (b) from DMF/NMP mixture.¹⁶⁸
4.1.2. Proposed mechanism of improved stability with MAPbI₃+PbI₂.NMP

Further, the effect on the binding of lead iodide to yield MAPbI₃ with these two solvent compositions – pure DMF and DMF/NMP was investigated using the XPS technique. The XPS spectra of Pb 4f7/2 fresh films (Figure A2.2a and A2.2b, Appendix 2) demonstrated that the chemical state of lead atoms was found to be similar to that of the MAPbI₃, regardless of the type of formulation or the amount of excess PbI₂. Conversely, XPS Pb 4f7/2-spectra of photoaged MAPbI₃+PbI₂.DMF film revealed a high-energy shift with the excess of PbI₂ for full coincidence with the spectrum of reference PbI₂, proposing full degradation of perovskite (Figure A2.2c, Appendix 2). On the other hand, MAPbI₃+PbI₂.NMP film did not show any shift in XPS spectra of Pb 4f7/2 spectra (Figure A2.2d, Appendix 2). This implies that when over-stoichiometric PbI₂ is present in the system, NMP as a co-solvent forms a stable and robust adduct with Pb. This was further supported with EDX measurements of the atomic ratio of iodine to lead atoms. (Figure A2.2e, Appendix 2)

AFM in-situ photodegradation experiments further verified this. The MAPbI₃+PbI₂.NMP film illustrated the appearance of needle-like structures in film morphology upon illumination, which can be considered the result of the adduct formation during in situ AFM photodegradation. (Movie 4, Appendix 2 and Figure 12h). MAPbI₃+PbI₂.DMF film, on the other hand, had lost volatile species, which resulted in defects and accelerated photodegradation (For the comparison, see Movie 1-4, Appendix 2 and Figure 12a-h)¹⁶⁸.

Alternatively, Movies 1-4 can be accessed using the link: https://drive.google.com/file/d/1FAkhj8R3xI4QzzZ7FBvCn5Eyn85Cydc/view?usp=sharing
Figure 12 AFM images of MAPbI$_3$ thin films acquired as a result of in situ photo-degradation. (laser beam of 405 nm wavelength, with the light intensity of 10 kW m$^{-2}$ was used). (a) fresh, 0% excess PbI$_2$, from pure DMF. (b) fresh, 10% excess PbI$_2$ from pure DMF (c) fresh, 0% excess PbI$_2$ from
Further investigation revealed that adducts between NMP and PbI$_2$ are favoured by the uniform distribution of valence states (Figure A2.3a and A2.3b, Appendix 2) in the accumulation with NMP’s great coordination capacity with PbI$_2$. Furthermore, investigations have demonstrated that NMP sits near Pb sites in the PbI$_2$ lattice due to its ring-like structure and binds with lead atoms$^{193,200,206}$. As a result of the strong intercalation of NMP with PbI$_2$, the adduct is more photodegradation resistant due to low evaporation rates and good morphology$^{192,197,202}$.

### 4.1.3 Device performance and Device stability

Later, solar cells with excess PbI$_2$ addition were prepared by using co-solvent DMF/NMP. Perovskite solar cells were fabricated in n-i-p configuration Glass/ITO/ZnO/PCBM/MAPbI$_3$(with and without excess PbI$_2$)/PTA/MoO$_x$/Ag architecture. The PbI$_2$ concentration was varied from 5% to 15% by weight. The relevant fabrication steps are described in “3.2.3 Device preparation”. A decent efficiency of 14.4% was obtained by 10% excess PbI$_2$ in the solution. This was almost double that of without excess PbI$_2$. In addition, excess PbI$_2$ improved open-circuit voltage, short circuit current densities and fill factor, thus increased overall solar cell performance. This improvement in photovoltaic parameters was associated with good morphology$^{201}$ (Figure A2.4, Appendix 2).

Since the objective of this work was to check the influence on the photostability of solar cells, the operational stability of solar cells was also investigated. Solar cell devices based on MAPbI$_3$ using following configuration was fabricated: Glass / ITO / SnO$_2$/MAPbI$_3$/PTAA/MoO$_x$/Al. Here, the passivation layers are not used to avoid their impact on degradation dynamics. This will further allow monitoring the influence on photostability due to the excess PbI$_2$ and DMF/NMP cosolvent. Although skipping passivation layers
often result in loss of performance\textsuperscript{168}. Solar cell devices were made with 0% and 15% excess PbI\textsubscript{2} from pure DMF and the same from DMF/NMP mixture. These devices were kept at 50°C and exposed to light having power 50 mW/cm\textsuperscript{2} inside a glovebox for 1500 h. (Figure A2.5, Appendix 2)

As shown in Figure 13, the solar cells with MAPbI\textsubscript{3}+PbI\textsubscript{2}.DMF are unstable and consistent with thin-film results. While solar cells with MAPbI\textsubscript{3}+PbI\textsubscript{2}.NMP remained fully functional. Thus, the presence of NMP co-solvent contributes to the improved photostability of PSC, while over stoichiometric PbI\textsubscript{2} is present in the MAPbI\textsubscript{3} frame.
4.2 Enhanced intrinsic photostability of MAPbI$_3$ thin films and solar cells with hydrazinium iodide

Hydrazinium iodide ($N_2H_5I$) is an inorganic salt additive. It has been reported that it can also act as an iodine quencher, reducing molecular iodine to iodide. Hence, the salt should be added in the perovskite framework$^{209-212}$. Earlier reports showed that partial or full substitution of MA$^+$ cation using hydrazinium cation improved the efficiency and stability of solar cells, forming mixed cation perovskite$^{209}$. However, exploring hydrazinium based salts as additives is another aspect. Hydrazinium halides are majorly investigated in the context of FASnI$_3$ based perovskite solar cells. For instance, a tiny amount of $N_2H_5Br$ has been demonstrated to inhibit tin oxidation in FASnI$_3$ based perovskite solar cells and reduce defects and trap states in perovskites$^{213}$. In the same way, adding $N_2H_5Cl$ to FASnI$_3$ improved perovskite film morphology and crystallinity, yielding excellent power conversion efficiency$^{214}$. Likewise, the addition of $N_2H_5Cl$ to MAPbI$_3$ also improved PCE, coverage, quality and crystallinity of perovskite film due to intermediate formation with PbI$_2$$^{180,215}$. Following the idea, hydrazinium iodide (HAI) additive in MAPbI$_3$ is investigated. Further, its impact on the morphology, crystallinity, intrinsic photostability of thin-film, device performance and operational stability of solar cells was also studied$^{179}$.

4.2.1 Photostability of thin-films with HAI additive

The pristine MAPbI$_3$ film is defined as a reference MAPbI$_3$ film with 0% HAI. Similarly, MAPbI$_3$ film with 15% HAI is referred to as MAPbI$_3$+HAI. The photostability test was conducted inside a glovebox by illuminating perovskite films to 30 mW cm$^{-2}$ using white LED light at 40 °C up to 1200 h. The white LED lamps had a similar spectrum to the solar AM1.5G spectrum. Further, UV-Vis and XRD were performed in regular intervals to check the intrinsic stability of films.
UV-vis test results revealed that the fresh, pristine MAPbI₃ film exhibits absorbance characteristics of perovskite ~750 nm. However, this absorbance feature of perovskite vanished after photoaging. Additionally, a shoulder matching to PbI₂ is visible ~500 nm (Figure 14a), implying that pristine perovskite is unstable and degrades as suspected. In comparison, the absorbance characteristics of perovskite in fresh MAPbI₃+HAI film is observed ~750 nm, which remains very much visible even after 1200 h of photoaging. This indicates that adding HAI to the MAPbI₃ precursor improves its intrinsic photostability. Although a shoulder matching to PbI₂ was noticeable ~500 nm (Figure 14b).

Simultaneously, the XRD patterns for fresh, pristine MAPbI₃ revealed less crystalline nature of the film with peaks located at 14.34°, 28.67°, 32.09°, 40.83°, 43.39° 216,217. Further, these peaks related to the perovskite structure vanished with photoaging. Instead, at 12.80° and 31.40°, new peaks corresponding to PbI₂ and Pb emerged 216, showing perovskite deterioration. The fresh MAPbI₃+HAI film, on the other hand, displays a small shift in the peaks that correspond to the perovskite structure with shifted peaks noticeable at 14.11°, 28.37°, 43.10°, and 58.61° 215,218. Moreover, the fresh MAPbI₃+HAI film exhibits a more crystalline nature than the pristine film. Additionally, the peak intensity at
14.11° gets immensely intense (which becomes almost 100 times more than pristine) (Figure A2.6 a, Appendix 2). Furthermore, a peak at 7.60° is observed due to an intermediate phase with PbI₂ that have peaks at 12.74°, 24.18°, and 25.58°. Upon photoaging, the intermediate phase vanishes, while the PbI₂ peak becomes evident, with perovskite peaks slightly shifted to 14.14°, 28.42°, 43.19° and 58.71° after light soaking and perovskite film exhibits the crystalline nature even after photoaging (Figure 15).

Figure 15 XRD patterns of fresh and aged MAPbI₃ and MAPbI₃+HAI films. * represents perovskite peaks.

Thus, The UV-Vis and XRD results confirm that the addition of HAI salt in MAPbI₃ do not destroy perovskite and improves intrinsic stability.

4.2.2. Proposed mechanism of improved stability with HAI salt

The crystalline nature of a film is typically linked to a decrease in FWHM with an increase in peak intensity. FWHM and crystallite size for pristine MAPbI₃ and MAPbI₃+HAI films were calculated following this concept. For the fresh state, the FWHM of pristine
MAPbI$_3$ was 0.18° and dropped to 0.09° for MAPbI$_3$+HAI. After the photostability test, the FWHM of MAPbI$_3$+HAI showed less deviation with FWHM values as 0.10°. It should be noted here that the pristine MAPbI$_3$ degrades with photoaging. As a result, no perovskite phase was available; therefore, the FWHM value of photoaged MAPbI$_3$ is not comparable to photoaged MAPbI$_3$+HAI. The crystallite size is calculated using Scherer’s equation $^{223}$ given as:

$$D=\frac{0.89\lambda}{(\beta.\cos\theta)}$$  \hspace{1cm} (11)

Where D represents average crystallite size, $\lambda$ is the wavelength of X-ray (1.54 A°), $\theta$ is diffraction angle, and $\beta$ is FWHM of the peak in XRD. The average crystallite size of the fresh, pristine MAPbI$_3$ film was observed 36 nm, which increased to 60 nm for MAPbI$_3$+HAI. After photoaging, the pristine perovskite defragmented into lead iodide and lead. Therefore the average crystallite size for the photoaged pristine film reduced to 23 nm compared to the fresh condition, which was determined using PbI$_2$ and Pb peaks as perovskite was defragmented. While the MAPbI$_3$+HAI film did not show any significant variation in the average crystallite size (50 nm). This indicates that HAI addition improves the crystallinity of perovskite film (Figure A2.6 a and b, Appendix 2).

The improvement in crystallinity is connected to an improvement in grain size. Therefore SEM measurements were performed. The grain size of MAPbI$_3$+HAI was grown from 50-150 nm (pristine MAPbI$_3$) to 400-1100 nm. The morphological changes showed that HAI addition resulted in a homogeneous film with flat and big grains passivating the grain boundaries, which can be caused by an intermediate phase between HAI and PbI$_2$ (Figure 16 a and b) $^{215}$. The atomic ratio of I:Pb obtained using EDX measurements further validated this due to a higher value for MAPbI$_3$+HAI film over the pristine film (Figure A2.7, Appendix 2).
Figure 16 SEM images of (a) pristine MAPbI$_3$ film (b) MAPbI$_3$ + HAI film.

As a result, photoluminescence peak intensities for MAPbI$_3$+HAI film exhibited a stronger peak intensity, implying that the HAI additive lowered non-radiative recombination losses at grain boundaries $^{211}$. Furthermore, PL spectra indicated a peak shift from 767 to 753 nm (Figure A2.8a, Appendix 2), implying that the addition of HAI altered the bandgap of the perovskite layer, potentially increasing open-circuit voltages $^{213,180}$. Additionally, the charge carrier recombination dynamics of MAPbI$_3$ film also changes with the $\kappa$ factor of 0.6 for pristine MAPbI$_3$ to $\kappa$ factor of 1.16 for MAPbI$_3$+HAI film; suggesting that HAI addition in MAPbI$_3$ influenced the recombination process that changed from free to bound for pristine to exciton-like recombinations for MAPbI$_3$+HAI film (Figure A2.8b and c, Appendix 2). This is linked with the reports suggesting that smaller grain size and non-radiative recombination losses lower the $\kappa$ factor due to the disordered phase. On the other hand, larger grains size result in an exciton-like transition at grain boundaries, implying an ordered phase and homogeneous perovskite layer $^{179,224,225}$.

Later, FTIR measurements/investigations confirmed the formation of an intermediate in the MAPbI$_3$+HAI film, which was believed to be the reason for the increased grain size. Peaks belonging to pristine perovskite are identified as C-H bend at 1380 cm$^{-1}$ and 1470 cm$^{-1}$, weak N-H bend at 1582 cm$^{-1}$, C-H stretch at 3030 cm$^{-1}$ and N-H stretch 3133 cm$^{-1}$ and 3180 cm$^{-1}$ in pure MAPbI$_3$, which are consistent with the literature $^{215}$. In the case of
MAPbI₃+HAI, an additional N-H bend emerged at 1418 cm⁻¹ in addition to the prominent N-H bend seen at 1565 cm⁻¹. A tiny peak showing N₂H₅⁺ deformation was also be seen at 1384 cm⁻¹. Peaks of PbI₂ were found at 2360 cm⁻¹, 2924 cm⁻¹. In addition, the N-H stretch got concentrated at 3136 cm⁻¹, while the NH₂ stretch related to N₂H₅⁻ was observed at 3282 cm⁻¹. These additional peaks point to the presence of an intermediate phase /complex formation of hydrazinium with lead iodide (Figure 5), which exhibited peaks of cubic MAPbI₃ at 1384 cm⁻¹, 1418 cm⁻¹, 1575 cm⁻¹, 1650 cm⁻¹, 3135 cm⁻¹, and 3178 cm⁻¹ upon photoaging; enhancing the intrinsic photostability of thin films. Further, these results are consistent with XRD and UV-Vis test outcome. See Figure 17.

Figure 17 FTIR spectra of pristine and MAPbI₃+HAI films before and after photoaging test.


4.2.3 Device performance and Device stability

To investigate the device performance of MAPbI₃ solar cell devices with HAI additive solar cells were fabricated in the n-i-p configuration in the following architecture Glass/ITO/SnO₂/PCBA/MAPbI₃/PTA/Polystyrene/MoOₓ/Ag. Different HAI concentrations were employed in precursor as 0% (pristine), 0.5%, 1%, 2.5% and 5%, % by weight. Amongst which, 0.5% HAI addition showed the best PCE of 17.03% over pristine perovskite with 14.98%. Furthermore, V_{oc}, J_{sc}, and fill factor began to fall as HAI concentration rose above the optimum level (0.5%). Although the addition of 1% and 2.5 % HAI yielded in functional devices, the performance had reduced. The addition of 5% HAI, on the other hand, ruined the performance of solar cells completely (Figure A2.9 a and b, Appendix 2). The solar cell performance with respect to change in HAI concentration is shown in Table 16. According to reports, high current and open-circuit voltage are linked to increased crystallinity and grain size, resulting in improved charge transport characteristics. As a result of the grain boundary passivation, the PCE was boosted up. On the other hand, excessive passivation might obstruct charge carrier transport and reduced device performance, as shown in the case of 5% and higher.

Further, the J-V characteristics of the best solar cell (with 0.5 HAI) exhibited reduced hysteresis over the pristine solar cell (Figure A2.10, Appendix 2). Reports suggest that in perovskite solar cells, the short circuit current hysteresis is induced by trap states present at the active layer interface that acts as a recombination centre. Hence, reduced

<table>
<thead>
<tr>
<th>HAI Content, %</th>
<th>V_{oc}, mV</th>
<th>J_{sc}, mA cm⁻²</th>
<th>Fill Factor</th>
<th>PCE, %</th>
</tr>
</thead>
<tbody>
<tr>
<td>0</td>
<td>1040.67</td>
<td>18.19</td>
<td>79.06</td>
<td>14.98</td>
</tr>
<tr>
<td>0.5</td>
<td>1058.13</td>
<td>20.02</td>
<td>80.39</td>
<td>17.03</td>
</tr>
<tr>
<td>1</td>
<td>940.82</td>
<td>18.07</td>
<td>51.50</td>
<td>8.75</td>
</tr>
<tr>
<td>2.5</td>
<td>921.50</td>
<td>16.82</td>
<td>57.71</td>
<td>9.95</td>
</tr>
<tr>
<td>5</td>
<td>387.99</td>
<td>2.90</td>
<td>36.54</td>
<td>0.41</td>
</tr>
</tbody>
</table>

Further, the J-V characteristics of the best solar cell (with 0.5 HAI) exhibited reduced hysteresis over the pristine solar cell (Figure A2.10, Appendix 2). Reports suggest that in perovskite solar cells, the short circuit current hysteresis is induced by trap states present at the active layer interface that acts as a recombination centre. Hence, reduced
Hysteresis is attributed to reduced recombination centres at the grain borders due to the high quality of the MAPbI₃+HAI film with enhanced crystallinity and larger grains, further resulting in improved fill factor.¹⁷⁹,¹⁸⁰,²⁰⁹,²¹⁵

Later, the operational stability of solar cells containing HAI additive was investigated. To do so, solar cells were fabricated in Glass/ITO/SnO₂/ MAPbI₃+HAI / PTAA/ V₂O₅/ Al configuration. For the operational stability test of solar cells, passivation layers like PCBA and polystyrene were not used to minimise the influence on degradation dynamics. Unfortunately, without the passivation layers, the solar cell performance was reduced (Figure A2.11, Appendix 2). However, it allowed the photostability to be monitored associated with the active layer containing the HAI additive.²⁳⁰–²³³ An optimum concentration of 0.5% was investigated for the photostability test. Solar cells were illuminated with white light with an intensity of 30 mW cm⁻² at 40°C for 1400 h. Afterwards, the entire set of devices was exposed to white light of the higher intensity of 60-70 mW cm⁻² at 50 °C, from 1400 h till 4400 h. This experiment was performed inside the glovebox in an inert environment. After 4400 hours of constant illumination, the operational stability test revealed that reference solar cells containing pristine MAPbI₃ retained 60% of their initial efficiency. Solar cell devices containing 0.5% HAI maintained 80% of their initial efficiency, demonstrating that adding HAI improves the operational stability of MAPbI₃-based solar cells under light and heat. See Figure 18.
Figure 18 Normalised IV parameters with HAI additive.

Thus, enhanced/improved stability of MAPbI$_3$ film was achieved due to HAI incorporation MAPbI$_3$ in precursor solution $^{179}$. 
4.3 Photostability of MAPbI₃ thin films with pyridine-based ligands

Pyridine based compounds are heterocyclic N atom-based compounds which are considered electron-deficient by nature. Furthermore, The N atom in pyridine derivatives has been demonstrated to be capable of interacting with Pb²⁺ defect sites in studies as lewis base ²⁶. Whereas Pb²⁺ defects sites that act as Lewis acid ²³⁴. Because the N atom can undergo protonation and passivate defect sites as a chelating ligand, nitrogen-based chelating compounds are often used as passivation agents, which promote charge carrier transport ²³⁵–²³⁷. Therefore, particularly, the main interest has been in studying the effects of pyridine derivatives as additives for the MAPbI₃ light-absorbing active layer in this experiment. Following the idea, bathophenanthroline (N1), Υ-bipyridyl (N2), oxiphenanthroline (N3), bathocuproine (N4), oxyquinoline (N5) and 1,10 phenanthroline (N6) were investigated ⁴³. The chemical structures of these additives are shown in Figure 9, under the section “3.2 Materials”.

4.3.1 Photostability of thin-films with pyridine-based ligands

The UV-vis results of fresh MAPbI₃ films illustrated that incorporation of additives in MAPbI₃ precursor resulted in the blue shift of the absorbance edge, altering the bandgap of the perovskite layer ⁸. The pristine MAPbI₃ displayed the absorbance feature of the perovskite phase ~750 nm. Whereas the absorbance feature of perovskite vanished for MAPbI₃+N1 and a small edge/bend appeared ~692 nm. MAPbI₃+N2 depicted the absorbance feature ~745 nm and maintained the perovskite phase. However, MAPbI₃+N3 and MAPbI₃+N4 badly affected the perovskite structure and absorbance feature corresponding to the perovskite phase, similar to N1, was not observed. Whereas MAPbI₃+N5 and MAPbI₃+N6 displayed absorbance features of perovskite formation, those were found ~730 nm and ~736 nm, respectively. Similarly, the blue shift was noticed for PL emission peaks upon the addition of N1-N6, with the reduction in peak intensity compared to pristine (except for N6).
Further, the XRD analysis was done. The XRD of fresh, pristine MAPbI₃ film showed patterns consistent with the cubic structure/phase of MAPbI₃. However, XRD patterns of MAPbI₃+N1 displayed deformation in the peak corresponding to the perovskite phase, and peak intensity was weakened drastically than pristine MAPbI₃, implying the loss of crystalline nature of the film. On the contrary, XRD of MAPbI₃+N2 exhibited peak splitting at 14.02° and 14.2°, peaks matching the perovskite structure, signifying the phase transition of MAPbI₃. Further, smaller and broader XRD peaks reflecting the perovskite structure were observed in the case of MAPbI₃+N3, which was found to be somewhat displaced compared to pristine MAPbI₃. Whereas the addition of N4 showed similar behaviour as the addition of N1, illustrating the deformity of the perovskite structure. MAPbI₃+N5 and MAPbI₃+N6 show similar XRD patterns related to MAPbI₃ perovskite (Figure A2.12, Appendix A2). Table 17 summarises UV-vis, PL, and XRD observations performed on fresh MAPbI₃ samples containing additives N1-N6.
Next, all samples were subjected to a photostability test which was performed in a specially
designed degradation chamber integrated inside the glovebox with an inert atmosphere.
Finally, samples were exposed to the continuous light illumination of intensity 70-80 mW cm\(^{-2}\) around 50-60 °C for 1400 h.

Despite the fact that the perovskite structure had already been damaged by adding N1 to
the MAPbI\(_3\) precursor, the UV-vis evolution of the MAPbI\(_3\)+N1 film showed negligible
modifications after photoaging for 1400 hours. The XRD pattern also supported this
(Figure 20a-b). That is why N1 could not be taken as an ideal additive for MAPbI\(_3\)
stabilisation. While, the UV-vis evolution of MAPbI\(_3\)+N2 films revealed that the
absorbance feature of the perovskite structure was noticeable even after 1400 hours of
photoaging, signifying that adding N2 to the MAPbI\(_3\) precursor maintains the stability of
the MAPbI\(_3\) thin film (Figure 20c). This stability could be mainly as a result of a complex
between PbI\(_2\) and N\(_2\)\(^{243,244}\), which will be expressed later in the section of “4.3.2 Proposed
mechanism of improving stability with N2”. Also, the XRD pattern at 14.02 of the

---

**Table 17 Comparison of UV-vis, PL and XRD observations for the fresh MAPbI\(_3\)+additive (N1-N6)
films\(^{43}\)**

<table>
<thead>
<tr>
<th>Additive in MAPbI(_3)</th>
<th>UV-vis peak position of MAPbI(_3)</th>
<th>PL peak position of MAPbI(_3)</th>
<th>XRD peak position of MAPbI(_3)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Pristine</td>
<td>750 nm</td>
<td>767 nm</td>
<td>14.1°, 28.4°, 31.9°</td>
</tr>
<tr>
<td>N1</td>
<td>692 nm (peak diminished)</td>
<td>734 nm</td>
<td>peak diminished</td>
</tr>
<tr>
<td>N3</td>
<td>710 nm</td>
<td>723 nm</td>
<td>13.9°, 14.3°, 28.6°, 32.0°</td>
</tr>
<tr>
<td>N4</td>
<td>690 nm (peak diminished)</td>
<td>746 nm</td>
<td>peak diminished</td>
</tr>
<tr>
<td>N5</td>
<td>730 nm</td>
<td>766 nm</td>
<td>14.02°, 14.2°, 28.4°, 31.8°</td>
</tr>
<tr>
<td>N6</td>
<td>736 nm</td>
<td>758 nm</td>
<td>14.02°, 14.2°, 28.4°, 31.8°</td>
</tr>
</tbody>
</table>
photoaged film verified the perovskite structure (Figure 20d). Nevertheless, the peak intensity was reduced. Further, N3 and N4 exhibited the same behaviour as N1 (Figure 20e-h). In the case of MAPbI$_3$+N5 film, however, the absorbance feature of the perovskite vanished after photoaging (Figure 20i), the only a shoulder observed ~500 nm, representing the disintegration of perovskite to PbI$_2$. Later, XRD patterns of the photoaged MAPbI$_3$+N5 film displayed peaks at 12.6° and 31.1°, matching PbI$_2$ and Pb, respectively (Figure 20j) \(^{245}\). Similarly, MAPbI$_3$+N6 also showed Pb formation and indicated that N6 addition did not improve MAPbI$_3$ photostability (Figure 20k-l). While pristine MAPbI$_3$ decomposed to PbI$_2$ and Pb as suspected \(^{24}\) (Figure 2m-n).

Thus, the thin film photostability test concluded that Y-bipyridyl (N2) improved the intrinsic photostability of MAPbI$_3$ film and MAPbI$_3$+N2 film was able to sustain illumination for 1400 h while the pristine film died/degraded. In contrast, bathophenanthroline (N1) deformed perovskite features of the active layer. Therefore it was not considered a suitable additive in the context of the photovoltaic application. Likewise, oxiphenanthroline (N3) was omitted too.
Figure 20 Evolution of UV-vis and XRD patterns of MAPbI$_3$+N1 (a,b), MAPbI$_3$+N2 (c,d), MAPbI$_3$+N3 (e,f), MAPbI$_3$+N4 (g,h), MAPbI$_3$+N5 (i,j), MAPbI$_3$+N6 (k,l) and pristine MAPbI$_3$ (m,n) respectively. * presents perovskite, † presents PbI$_2$ and ‡ presents Pb.
4.3.2 Proposed mechanism of improved stability of MAPbI\textsubscript{3} film with \( \Upsilon \)-bipyridyl (N2)

Since it is known that the Pb\textsuperscript{2+} sites in MAPbI\textsubscript{3} act as Lewis acid, electron-deficient nitrogen-based heterocyclic compounds behave as lewis bases and their coordination results in lewis acid-base adduct\textsuperscript{246,247}. Hence, the complex formation between PbI\textsubscript{2} and N2 is expected. Therefore to further, monitor the effect of the additive on the MAPbI\textsubscript{3} surface and morphology, AFM studies were performed.

The AFM images of pristine MAPbI\textsubscript{3} showed an inhomogeneous surface with more significant clusters (Figure 21a). On the contrary, AFM images of MAPbI\textsubscript{3}+N2 resulted in a homogeneous dense compact small granular like structure (Figure 21b). Although there are morphological differences in pristine MAPbI\textsubscript{3} and MAPbI\textsubscript{3}+N2 films, yet the \( \text{RMS} \) roughness is similar. Upon photoaging, the pristine MAPbI\textsubscript{3} film shows pinholes, indicating the photodegradation of the perovskite structure (Figure 21c). On the other hand, MAPbI\textsubscript{3}+N2 shows the growth of needle-like structure, indicating the formation of a new complex that might have taken place and resulted in enhanced photostability of thin-film (Figure 21d).
Further, PL spectra of pristine and MAPbI$_3$+N$_2$ samples were measured. (Figure A2.13, Appendix A2). The PL peak intensity suggests that fresh pristine MAPbI$_3$ had a higher PL peak intensity over MAPbI$_3$+N$_2$, implying that N$_2$ might result in more non-radiative losses that could cause a reduction in open-circuit voltage and fill factor. However, upon photoaging, the PL emission peak for pristine MAPbI$_3$ became extinct, whereas the emission peak intensity for MAPbI$_3$+N$_2$ turned out to be higher than the fresh stage. In addition, the PL emission peak of MAPbI$_3$+N$_2$ displayed a further blue shift upon photoaging which could be attributed to complex formation upon N$_2$ addition in MAPbI$_3$.

Finally, FTIR spectroscopy was performed to investigate the complex formation (Figure 22).
The FTIR spectra of pristine MAPbI$_3$ exhibited peaks analogous to perovskite structure at 1468 cm$^{-1}$ and 1580 cm$^{-1}$ (N-H bend), 2926 cm$^{-1}$ (C-H bend), and 3136 cm$^{-1}$ and 3175 cm$^{-1}$ (N-H stretch), consistent with the literature.$^{239}$ Whereas, for MAPbI$_3$+N$_2$, the N-H bend was found to be shifted at 1466 cm$^{-1}$ and 1573 cm$^{-1}$. Also, many minor peaks emerged at 1573 cm$^{-1}$, suggesting the formation of a new complex which is attributed to the PbI$_2$(N$_2$) complex.$^{248,249}$ In addition, a minor peak of PbI$_2$ appeared at 2965 cm$^{-1}$ in conjunction with C-H stretch at 2925 cm$^{-1}$. The peaks corresponding to the N-H stretch were also noticed to be shifted at 3130 cm$^{-1}$ and 3178 cm$^{-1}$ because of PbI$_2$(N$_2$) complex formation. The peak corresponding to complex formation was attributed to a minor ring stretch at 1436 cm$^{-1}$, 1490 cm$^{-1}$ and 1573 cm$^{-1}$.$^{248}$ The peak at 1557 cm$^{-1}$ was ascribed to N$_2$.$^{248}$, shown in the zoomed version of FTIR spectra (Figure A2.14, Appendix 2). Besides, this complex formation explains the reduction and shift of absorbance edge near 500 nm attributed to
PbI$_2$\textsuperscript{244} (Figure A2.15, Appendix 2). This complex formation later results in improved stability of MAPbI$_3$+N$_2$ thin film (Figure A2.16, Appendix 2).

4.3.3 Device performance with additive Y-bipyridyl (N$_2$)

Since MAPbI$_3$+N$_2$ showed enhanced intrinsic photochemical stability, the additive was further investigated in solar cell devices in n-i-p configuration (Figure 23a). Concentration of N$_2$ was varied from 0.0% (pristine), 0.5%, 1%, 2.5%, 5% to 7.5%, % by weight. The IV parameters are shown in Figure 23b. Unfortunately, the addition of N$_2$ reduced PCE slightly (15.4%) compared to pristine (16.9%). The best and average device performance with various concentrations of MAPbI$_3$+N$_2$ is presented in Table A1, Appendix 2. The small drop in PCE was due to lower $V_{oc}$ and fill factor, which could be attributed to more non-radiative losses\textsuperscript{238}. However, using excess PbI$_2$\textsuperscript{183} or facilitation of charge transport
by additional layers can be further applied in combination with N2 to achieve higher PCE and is subject to further investigation and optimisation.

Figure 23 (a) device architecture (b) Impact of the addition of N2 onto photovoltaic parameters.
Further, the hysteresis factor was calculated for the optimum concentration (2.5%) and compared with pristine, presented in Figure 24 and Table A2, Appendix 2. The hysteresis factor (HF) was calculated with the formula reported elsewhere:

\[
\text{Hysteresis factor} = \frac{\text{PCE (reverse)} - \text{PCE (forward)}}{\text{PCE (reverse)}}
\]

Based on J-V and hysteresis parameters, it was observed that the performance of MAPbI\(_3\)+N\(_2\) is comparable to pristine. Hence, MAPbI\(_3\)+N\(_2\) can be utilised in photovoltaic application.

![Figure 24 J-V curves of pristine vs 2.5% (best PCE) of N2 in MAPbI\(_3\)](image)

In a nutshell, the addition of \(\psi\)-bipyridyl (N\(_2\)) improves the photostability of MAPbI\(_3\) thin films and shows a decent comparable performance. However, the device stability test is a further prospect of investigation in this case.
5. Conclusions and Prospects

In the scope of this thesis, selection criteria for choosing additives for the MAPbI₃ active layer have been presented, which was absent otherwise. Following this, earlier reported additives were classified based on organic and inorganic additives. The organic additives were later subcategorised based on N donor atom, O donor atom and S donor atom mainly with the associated functional group. Inorganic additives were subcategorised based on the group in the periodic table. Following the notion, twenty-three additives were primarily investigated during this work. Both inorganic salts and organic additives were chosen to explore their influence on the intrinsic photostability of MAPbI₃. Organic additives were further chosen based on their functional groups as pyridine derivatives, acids, esters, ethers and others. The initial results obtained from the UV-Vis measurements showed that eight of the additives exhibited improved intrinsic stability of thin films. Out of which, three additives were studied in detail. These three additives are (Lead iodide) PbI₂ with NMP, hydrazinium iodide (N₂H₅I/HAI) and Ψ-bipyridyl. For which, the conclusions are:

- The photostability in the presence of over stoichiometric lead iodide is correlated with the choice of the correct solvent formulation. In our case, the addition of NMP co-solvent improved the photostability of MAPbI₃ thin films while excess PbI₂ content is present in the active layer. According to our findings, the NMP cosolvent forms an adduct with Pb atoms, which inhibited destabilisation of the MAPbI₃ layer due to excess PbI₂ content, leading to improved stability against illumination in inert. Later by employing NMP cosolvent with 10% excess PbI₂, an improved PCE of 14.4% was obtained. Moreover, by incorporating NMP as a co-solvent into the precursor and combining it with over stoichiometric PbI₂, we obtained photostable solar cell devices with a lifetime of up to 1500 hours.

- In the case of N₂H₅I additive, the incorporation of N₂H₅I into MAPbI₃ precursor improved the crystallinity of film, showed the grain size growth with homogeneous film morphology, resulting in grain boundary passivation. Further, these
morphological improvements in the film were ascribed to intermediate formation between \( \text{N}_2\text{H}_5\text{I} \) and \( \text{PbI}_2 \). This intermediate formation slowed down the degradation process and thin-film sustained illumination for up to 1200 h, after which the intermediate phase changes to the cubic phase of \( \text{MAPbI}_3 \). To add on, incorporating an optimum amount of \( \text{N}_2\text{H}_5\text{I} \) demonstrated improved power conversion efficiency of 17.03\% and operational stability of \(~80\%\) (of the initial stage) after 4400 h of continuous illumination in an inert environment.

- Similarly, \( \Upsilon\)-bipyridyl in perovskite precursor resulted in improved stability of thin-film, sustaining illumination for 1400 h under an inert atmosphere that was perceived due to the presence of complex formed between \( \Upsilon\)-bipyridyl and \( \text{PbI}_2 \). However, incorporation of \( \Upsilon\)-bipyridyl resulted in comparable performance (15.4\%) to pristine one.

Further, it should be noticed that the typical donor atom in these additives showing the stabilising effect is the N atom. The cosolvent NMP in the case of \( \text{PbI}_2 \) additive, the additives hydrazinium iodide and \( \Upsilon\)-bipyridyl, all of these compounds are amine derivatives. Although NMP does contain the carbonyl group. Thus it can be said that compounds containing amines can play a very crucial role in overcoming the stability challenges associated with \( \text{MAPbI}_3 \).

A future prospect in additive engineering should focus on developing an artificial intelligence-based system/ machine learning/ depository to compare the morphological and optoelectronic properties with the molecular structure of investigated additives and their influence on photostability in given conditions since there was no proper rule to select the correct/suitable material to achieve stabilization effect until now. Therefore it is the need of the hour to design a tool to perform systematic statistical investigation. This, in turn, will help researchers to select materials to design new additives to stabilize \( \text{MAPbI}_3 \).
Additionally, upscaling and green solvents are other aspects of improvement for future applications
6. Bibliography


19 U. Krishnan, M. Kaur, M. Kumar and A. Kumar, J. Photonics Energy, 2019, 9, 1.


133
Nanotechnol., 2019, 10, 2374–2382.


41 Y. Wang, N. Song, L. Feng and X. Deng, ACS Appl. Mater. Interfaces, 2016, 8, 24703–24711.


66 J. W. Lee, S. H. Bae, Y. T. Hsieh, N. De Marco, M. Wang, P. Sun and Y. Yang,


78 X. Cao, L. Zhi, Y. Li, X. Cui, L. Ci, K. Ding and J. Wei, RSC Adv., 2017, 7,


89 C. Zhang, Q. Luo, X. Deng, J. Zheng, W. Ou-Yang, X. Chen and S. Huang, 

90 L. Su, Y. Xiao, G. Han, L. Lu, H. Li and M. Zhu, J. Power Sources, 2019, 426, 
11–15.


Interfaces, 2019, 11, 40163–40171.

94 F. Han, J. Luo, H. A. Malik, B. Zhao, Z. Wan and C. Jia, J. Power Sources, 2017, 
359, 577–584.

95 C. Gao, H. Dong, X. Bao, Y. Zhang, A. Saporbaev, L. Yu, S. Wen, R. Yang and L. 

2018, 6, 15386–15394.

97 Y. Wu, F. Xie, H. Chen, X. Yang, H. Su, M. Cai, Z. Zhou, T. Noda and L. Han, 

Interfaces, 2016, 8, 15333–15340.

100 G. Tang, P. You, Q. Tai, R. Wu and F. Yan, Sol. RRL, 2018, 2, 1–9.


152 S. Mabrouk, B. Bahrami, A. Gurung, K. M. Reza, N. Adhikari, A. Dubey, R.


162 A. S. Yerramilli, Y. Chen, D. Sanni, J. Asare, N. D. Theodore and T. L. Alford,


S. Wang, W. Dong, X. Fang, Q. Zhang, S. Zhou, Z. Deng, R. Tao, J. Shao, R. Xia,


Y. Li, L. Zhi, G. Ge, Z. Zhao, X. Cao, F. Chen, X. Cui, F. Lin, L. Ci, J. Sun, D.


Appendix 0: Literature Review Analysis
Figure A0.1 Influence of additives with N donor atoms (amines and nitriles) on the photostability of MAPbI$_3$ photoactive layer. Here extrinsic represents ambient test conditions while intrinsic represent inert test conditions.\textsuperscript{57}
Figure A0. 2 Influence of additives with O donor atom on the photostability of MAPbI$_3$ photoactive layer. Here extrinsic represents ambient test conditions while intrinsic represent inert test conditions. The additives were subcategorised based on relevant functional groups as carbonyl/sulfonyl, acids, acetates, ester and ether and alcohol and other multifunctional groups.\textsuperscript{57}
Figure A0.3 Influence of additives with S donor atom onto the photostability of MAPbI$_3$ active layer.$^{57}$
Figure A0. 4 Comparison of the influence of inorganic additives belonging to alkali metal salts, transition metal halides, other metal additives and non-metal additives onto photostability of MAPbI$_3$ photoactive layer for PSC.$^{57}$
Appendix 1: UV-Vis Evolution of Investigated Additives
Figure A1. 1 UV-Vis evolution of additives showing stabilization effect in MAPbI₃ films against illumination in the inert environment.
Figure A1. 2 UV-Vis evolution of investigated additives that did not improve intrinsic photostability of MAPbI₃ thin films
Appendix 2: Supplementary Material
Figure A2. 1 Comparision of Chemical structure of solvents (a) DMF (b) NMP
Figure A2. 2 XPS spectra of Pb 4f of MAPbI$_3$ films with 0% and 15% excess lead iodide (a) fresh, from DMF (b) fresh, from DMF/NMP mixture (c) photoaged, from DMF (d) photoaged, from DMF/NMP mixture
Figure A2. 3 XPS valence band spectra of MAPbI$_3$ thin film with excess of PbI$_2$ (a) from pure DMF (b) from mixture of DMF/NMP.

Figure A2. 4 Device performance with overstoichiometric PbI$_2$ prepared from DMF/NMP cosolvent.
Figure A2. 5 Operational stability of solar cells under continuous illumination. Stability of solar cells made of MAPbI$_3$ with 0% and 15% excess PbI$_2$, coated from pure DMF and DMF/NMP mixture.
Figure A2. 6 Diffraction intensity of XRD pattern vs FWHM Vs average crystallite size in thin films with 0% & 15% HAI concentration. (a) for fresh films. (b) for photoaged films.
Figure A2. 7 Atomic ratio of I: Pb for the film with and without hydrazinium iodide, before and after photoaging. 

Figure A2. 8 (a) PL spectra of the MAPbI$_3$ films without (0% HAI)/pristine and 15% HAI. (b) Power dependent PL excitation spectra of MAPbI$_3$ films with 0% HAI and 15% HAI addition. (c) K factor of MAPbI$_3$ films without and with HAI.
Figure A2. 9 (a) Device architecture of investigated solar cells. (b) Device performance of MAPbI$_3$ solar cells with respect to HAI concentration.

Figure A2. 10 J-V curve of best solar cells with and 0.5% HAI content.
Figure A2. 11: (a) Device architecture to check HAI impact on operational-stability of solar cell devices. (b) Device performance during operational stability test of MAPbI₃ solar cells with optimum HAI Addition. 

179
Figure A2. 12 (a) XRD patterns of MAPbI$_3$ films with additives (N1-N6). (b) Zoomed XRD patterns from 5\(^\circ\) to 15\(^\circ\)
Figure A2. 13 PL emission spectra of fresh and photoaged film with and without N2 additive in MAPbI$_3$
Figure A2. Zoomed FTIR spectra showing complex formation upon N2 addition in fresh film.
Figure A2. Reduction and shift in absorbance edge near 500 nm upon addition of N2 in MAPbI3
Figure A2. 16 FTIR spectra of photoaged film of pristine MAPbI$_3$ and MAPbI$_3$+N
Table A 1 IV parameters of MAPbI$_3$+N$_2$, (with respect to concentration)

<table>
<thead>
<tr>
<th>Concentration</th>
<th>V$_{oc}$, mV</th>
<th>J$_{sc}$, mA cm$^{-2}$</th>
<th>Fill factor</th>
<th>PCE, %</th>
</tr>
</thead>
<tbody>
<tr>
<td>0%</td>
<td>Best</td>
<td>981.84</td>
<td>21.13</td>
<td>81.52</td>
</tr>
<tr>
<td></td>
<td>Avg</td>
<td>953.40±13.73</td>
<td>20.20±0.84</td>
<td>76.87±3.78</td>
</tr>
<tr>
<td>0.5%</td>
<td>Best</td>
<td>934.08</td>
<td>20.56</td>
<td>76.62</td>
</tr>
<tr>
<td></td>
<td>Avg</td>
<td>923.32±7.57</td>
<td>19.23±1.10</td>
<td>70.17±6.32</td>
</tr>
<tr>
<td>1%</td>
<td>Best</td>
<td>936.70</td>
<td>20.53</td>
<td>76.53</td>
</tr>
<tr>
<td></td>
<td>Avg</td>
<td>923.89±10.71</td>
<td>18.98±1.79</td>
<td>68.64±7.70</td>
</tr>
<tr>
<td>2.5%</td>
<td>Best</td>
<td>954.34</td>
<td>20.83</td>
<td>77.94</td>
</tr>
<tr>
<td></td>
<td>Avg</td>
<td>940.85±10.63</td>
<td>19.54±1.34</td>
<td>71.98±6.79</td>
</tr>
<tr>
<td>5%</td>
<td>Best</td>
<td>962.52</td>
<td>15.4</td>
<td>63.40</td>
</tr>
<tr>
<td></td>
<td>Avg</td>
<td>916.04±26.49</td>
<td>14±0.75</td>
<td>56.02±3.85</td>
</tr>
<tr>
<td>7.5%</td>
<td>Best</td>
<td>862.17</td>
<td>7.16</td>
<td>57.52</td>
</tr>
<tr>
<td></td>
<td>Avg</td>
<td>802.14±54.38</td>
<td>6.42±0.96</td>
<td>53.71±4.55</td>
</tr>
</tbody>
</table>

Table A 2 J-V characteristics and hysteresis factor of best solar cells made of pristine vs 2.5% MAPbI$_3$+N$_2$

<table>
<thead>
<tr>
<th>concentration</th>
<th>V$_{oc}$, mV</th>
<th>J$_{sc}$, mA cm$^{-2}$</th>
<th>Fill factor</th>
<th>PCE, %</th>
<th>Hysteresis factor (HF)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.0% (FS)</td>
<td>981.84</td>
<td>21.13</td>
<td>81.52</td>
<td>16.91</td>
<td>0.1574</td>
</tr>
<tr>
<td>0.0% (RS)</td>
<td>946.81</td>
<td>20.43</td>
<td>75.78</td>
<td>14.61</td>
<td>0.1574</td>
</tr>
<tr>
<td>2.5% (FS)</td>
<td>954.34</td>
<td>20.83</td>
<td>77.94</td>
<td>15.49</td>
<td>0.1568</td>
</tr>
<tr>
<td>2.5% (RS)</td>
<td>953.36</td>
<td>20.46</td>
<td>68.60</td>
<td>13.39</td>
<td>0.1568</td>
</tr>
</tbody>
</table>